

PRODUCT GUIDE

**MOSFETs**



Toshiba's MOSFET devices meet the needs of a wide range of ultra-high-density applications.

# POWER-MOSFETS CONTENTS

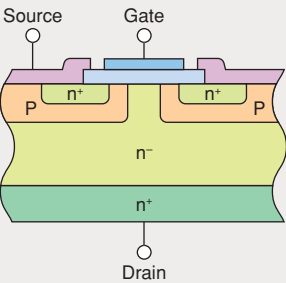
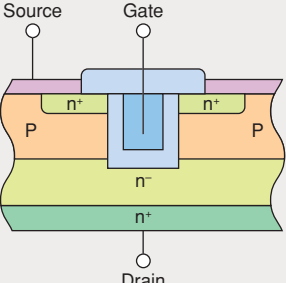
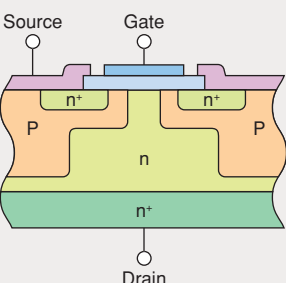
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• STP2 Series ... [Part Number: TPCT4xxx]	
• TSON Advance Series	
• TSSOP-8 Series ... [Part Number: TPCS8xxx]	
• TSSOP Advance Series ... [Part Number: TPCM8xxx]	
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- 1) No carrier storage effect; superior frequency and switching characteristics
- 2) Rugged and no current concentration
- 3) Voltage-controlled device, hence low drive power
- 4) Easy parallel connection

■ Toshiba MOSFETs have the following additional features:

- 1) Guaranteed avalanche capability..... Allows an absorber circuit to be simplified
- 2) Improved functioning of built-in diodes ..... Enhanced circuit design flexibility
- 3) High ruggedness ..... Increased margin for circuit design
- 4) High-speed switching ..... Higher speed in end-product's operation
- 5) Low  $R_{(DS)ON}$  ..... Reduced end-product's power consumption
- 6) Smaller packages ..... Reduced end-product size
- 7) Low drive loss ..... Reduced end product's power

■ Structures of Toshiba MOSFETs

<p>Double-Diffusion Structure</p> 	<p>● <math>\pi</math>-MOS</p> <p>Toshiba Power MOSFETs use a double-diffusion MOS (D-MOS) structure, which produces high-withstand voltage, to form channels. This structure is especially well suited to high-withstand voltage and high-current devices. A high level of integration yields a high-performance Power MOSFET with low ON-resistance and low power loss.</p>
<p>Trench Structure</p> 	<p>● U-MOS</p> <p>Higher channel density is achieved by connecting channels vertically to form a U-groove at the gate region, a structure that yields a lower ON-resistance than other MOSFET structures.</p>
<p>Super-Junction Structure</p> 	<p>● DTMOS</p> <p>The super-junction structure, which has P-type pillar layers as shown left, realizes high withstand voltage and ON-resistance lower than the conventional theoretical limit of silicon.</p>

## 2-1 MOSFET Product Lines

### SSM Series ( $V_{DS} = 12\text{ V to }60\text{ V}$ )

Very compact and thin, the SSM Series is suitable for use in various electronic devices. The SSM Series is available in a wide range of packages and features low voltage drive.

- Applications
- Cell phones ● Notebook PCs
- Portable electronic devices ● Small-signal switching

### VS and PS Series ( $V_{DS} = 12\text{ V to }40\text{ V}$ )

Very compact and thin, the VS and PS Series are suitable for use in various electronic devices.

- Applications
- Cell phones ● Notebook PCs
- Portable electronic devices

### Chip LGA and STP Series ( $V_{DS} = 20\text{ V to }30\text{ V}$ )

The LGA and STP Series are housed in an ultra-small and thin package and are suitable for use in lithium-ion secondary battery protection circuits in various portable electronic devices.

- Applications
- Lithium-ion secondary battery protection circuits

### SOP and TSON Series ( $V_{DS} = 20\text{ V to }60\text{ V}$ )

The SOP and TSON Series are compact and thin, and require only a small mounting area. They are suitable for lithium-ion secondary battery protection circuits and notebook PCs.

- Applications
- Lithium-ion secondary battery protection circuits
- Notebook PCs ● Portable electronic devices
- DC-DC converters

### TO-220SM(W) Series ( $V_{DS} = 40\text{ V to }150\text{ V}$ )

The TO-220SM package, which uses Cu connectors and a wide source terminal, realizes low ON-resistance and a high current-carrying capability.

- Applications
- Motor drivers ● Switching power supplies

### Low- $V_{DS}$ , High- $Q_g$ U-MOS Series ( $V_{DS} = 40\text{ V to }100\text{ V}$ )

High integration is achieved using a trench technology. Low-voltage drive ( $V_{GS} = 4\text{ V}$ ) is possible due to ultra-low ON-resistance.

- Applications
- Motor drivers ● Solenoids and lamp drivers

### U-MOS Series for Synchronous Rectification ( $V_{DS} = 60\text{ V to }150\text{ V}$ )

Fabricated using a trench technology, the U-MOS Series is ideal for synchronous rectification on the secondary side of power supply circuits.

- Applications
- Switching power supplies ● AC adapters
- Motor drivers

### New $\pi$ -MOSVII Series ( $V_{DS} = 450\text{ V to }650\text{ V}$ )

The latest addition to the  $\pi$ -MOS portfolio, the  $\pi$ -MOSVII Series offers reduced capacitances due to optimized chip design and is available with a greatly wider range of electrical characteristics.

- Applications
- Switching power supplies ● AC adapters

### Super-Junction DTMOS Series ( $V_{DS} = 600, 650\text{ V}$ )

The super-junction DTMOS Series achieves low ON-resistance and low gate charge ( $Q_g$ ) due to the use of the latest super-junction structure.

- Applications
- Switching power supplies ● AC adapters
- Motor drivers

### High-Speed $\pi$ -MOS Series ( $V_{DS} = 450\text{ V to }600\text{ V}$ )

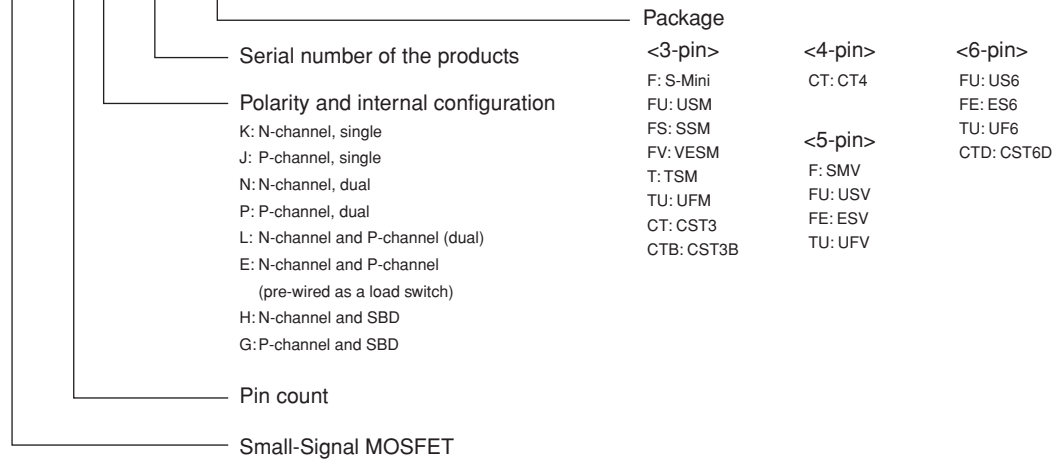
The new High-Speed  $\pi$ -MOS Series achieves higher switching speed than the well-proven  $\pi$ -MOS Series. Two series are available: high-speed switching series and high-speed diode series.

- Applications
- Inverters ● Switching power supplies
- Motor drivers ● AC adapters

## 2-2 Part Numbering Schemes

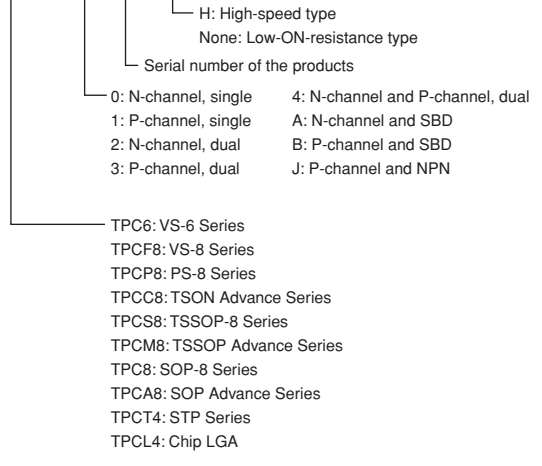
### Small-Signal MOSFET (SSM) Series

**SSM 3 K 101 TU**



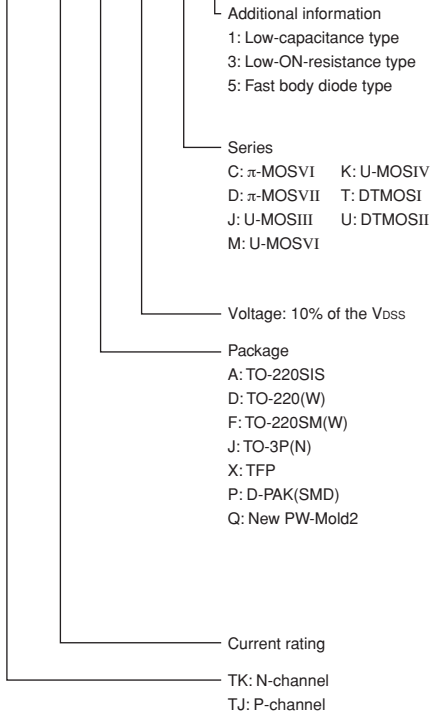
### Multi-Pin Series

**TPCM8 0 01 -H**



### New Series

**TK 55 A 10 J 1**



### Conventional Series

**2SK \*\*\*\***

N-channel MOS

**2SJ \*\*\*\***

P-channel MOS



V <sub>DSS</sub> (V) I <sub>D</sub> (A)	12	20	24	30	40	50	60	100	150	180	200	250	400	450	500	525	550	600	650	700	V <sub>DSS</sub> (V) I <sub>D</sub> (A)	
0.05						*2SJ343(50)① *2SJ344(50)①															0.05	
0.1		*SSM3K04FU(12)③ *SSM3K16FU(15)③ *SSM3J16FU(45)③ ⊙SSM3K04FS(12)③ ⊙SSM3K16FS(15)③ ⊙SSM3J16FS(45)③ ⊙SSM3J35FS(44)③ ⊕SSM3K03FV(12)③ ⊕SSM3K04FV(12)③ ⊕SSM3K16FV(15)③ ⊕SSM3J16FV(45)③ ⊕SSM3J35MFV(44)③ ⊕SSM3K16CT(15)③ ⊕SSM3J16CT(45)③ ⊕SSM3J35CT(44)③ △SSM6N04FU(12)③ △SSM6N16FU(15)③ △SSM6P16FU(45)③ △SSM6P35FU(44)③ ⊕SSM6N03FE(12)③ ⊕SSM6N16FE(15)③ ⊕SSM6P16FE(45)③ ⊕SSM6L16FE(15)③ ⊕SSM6P35FE(45)③ △SSM5N16FU(15)③ △SSM5P16FU(45)③ ⊕SSM5N03FE(12)③ ⊕SSM5N16FE(15)③ ⊕SSM5P16FE(45)③		*SSM3K15F(7)③ *SSM3J15F(32)③ *SSM3K15FU(7)③ *SSM3J15FU(32)③ ⊙SSM3K15FS(7)③ ⊙SSM3J15FS(32)③ ⊕SSM3K15FV(7)③ ⊕SSM3J15FV(32)③ ⊕SSM3K15CT(7)③ ⊕SSM3J15CT(32)③ △SSM6N15FU(7)③ △SSM6P15FU(32)③ △SSM5N15FU(7)③ △SSM5P15FU(32)③ ⊕SSM6N15FE(7)③ ⊕SSM6P15FE(32)③ ⊕SSM5N15FE(7)③ ⊕SSM5P15FE(32)③			*SSM3K17FU(40)② △SSM6N17FU(40)②														0.1	
0.18		⊙SSM3K35FS(20)③ ⊕SSM3K35MFV(20)③ ⊕SSM3K35CT(20)③ △SSM6N35FU(20)③ △SSM6L35FU(20)③ ⊕SSM6N35FE(20)③ ⊕SSM6L35FE(20)③																				0.18
0.2		*SSM3J05FU(4)③ △SSM6P05FU(4)③ △SSM5P05FU(4)③		*2SJ305(4)① *2SK2009(2)① *SSM3J09FU(4.2)③ △SSM6P09FU(4.2)③		*SSM3K7002F(3.3)③ *SSM3K7002AF(3.3)③ *SSM3K7002FU(3.3)③ *SSM3K7002AFU(3.3)③ △SSM6N7002FU(3.3)③ △SSM6N7002AFU(3.3)③ *2SJ168(2)① *2SK1062(1)①															0.2	
0.25		*SSM6N37CTD(5.6)③																			0.25	
0.33		△SSM3J36TU(3.6)③ ⊙SSM3J36FS(3.6)③ ⊕SSM3J36MFV(3.6)③ ⊕SSM6P36TU(3.6)③ ⊕SSM6P36FE(3.6)③																			0.33	
0.4		△SSM6L05FU(1.2)③ △SSM6N05FU(1.2)③ *SSM3K05FU(1.2)③ △SSM5N05FU(1.2)③		△SSM6L09FU(1.2)③ △SSM6N09FU(1.2)③ *SSM3K09FU(1.2)③																	0.4	
0.5		⊕SSM4K27CT(0.205)③ ⊕SSM6L10TU(0.145)③ ⊕SSM6L11TU(0.145)③ ⊕SSM6L12TU(0.145)③ ⊕SSM6N25TU(0.145)③ ⊕SSM6N36TU(1.52)③ ⊕SSM6P25TU(0.26)③ ⊕SSM6P26TU(0.23)③ ⊕SSM6J25FE(0.26)③ ⊕SSM6J26FE(0.23)③ ⊕SSM6K25FE(0.145)③ ⊕SSM6L36TU(1.52)③ ⊙SSM3K36FS(1.52)③ ⊕SSM3K36MFV(1.52)③ △SSM3K36TU(1.52)③ ⊕SSM6N36FE(1.52)③ ⊕SSM6L36FE(1.52)③		⊕SSM6N24TU(0.145)③ ⊕SSM6K24FE(0.145)③												▲SSM2998(20)② ☆SSM3302(18)② ◇SSM3471(18)②					0.5	
0.6																					0.6	
0.65		△SSM6J06FU(0.5)③																			0.65	
0.7		⊕SSM6P41FE(0.3)③																			0.7	
0.8		⊕SSM6L13TU(0.143)③ ⊕SSM6N29TU(0.143)③ ⊕SSM6P28TU(0.234)③ ⊕SSM6J205FE(0.234)③		△SSM6J07FU(0.8)③																	0.8	

Legend **Product series** ①: π-MOSIII ②: π-MOSV ③: π-MOSVI ④: L<sup>2</sup>-π-MOSV ⑤: L<sup>2</sup>-π-MOSVI ⑥: U-MOS ⑦: π-MOSVII ⑧: π-MOSIV ⑨: DTMOSI ⑩: DTMOSII

**Package** ◊PW-Mini ◊VS-8 ♥VS-6 ♣PS-8 ⊕STP ▲TO-92MOD ▼PW-Mold J New PW-Mold ⊕TSON Advance ◊New PW-Mold2 ◊TO-220SM(W) ◊TO-3P(N) ◊TO-3P(N)IS ●TO-3P(L) ◊Chip LGA ◊SOP-8 Lead Clamp ▶SOP Advance ◆TO-220NIS ⊗TO-220SIS ■TO-220AB ◻TO-220(W) ♣TFP ◊TO-220FL/SM ◊ES6 \*CST6D △USV \*UFV ☆ESV

Notes:  
 ( ) = R<sub>DS(on)</sub> max \* = 1.8-V drive P = P-ch NS = N-ch + SBD PD = P-ch + Driver  
 \$ = 10-V drive V = High-speed diode CN = Complementary N-ch PS = P-ch + SBD (load switch)  
 # = 2.5-V drive N = N-ch CP = Complementary P-ch [ ] = Under development

V <sub>DSS</sub> (V) I <sub>D</sub> (A)	12	20	24	30	40	50	60	100	150	180	200	250	400	450	500	525	550	600	800	900	1000	V <sub>DSS</sub> (V) I <sub>D</sub> (A)		
1	PS * SSM5G02TU(0.16)Ⓢ PS * SSM5G04TU(0.24)Ⓢ PD * SSM6E01TU(0.16)Ⓢ	△ SSM3J111TU(0.48)Ⓢ ▽ SSM3J46CTB(0.103)Ⓢ		PS * SSM5G01TU(0.8)Ⓢ			◇ 2SJ360 (0.73)Ⓢ ▲ 2SJ507 (0.7)Ⓢ	◇ 2SK2963 (0.7)Ⓢ ▲ 2SK2962 (0.7)Ⓢ ◇ 2SJ508 (1.9)Ⓢ ▲ 2SJ509 (1.9)Ⓢ	▲ 2SK3670 (1.7)	◆ 2SJ313 (5.0) ▼ 2SJ338 (5.0) ◆ 2SK2013 (5.0) ▼ 2SK2162 (5.0)	◇ 2SK2992 (3.5)Ⓢ	CP * TPC8404(2.55)Ⓢ CN * TPC8404(1.7)Ⓢ	▼ 2SK3498 (5.5)Ⓢ	▮ 2SK4023 (4.6)Ⓢ ☆ 2SK3374 (4.6)Ⓢ ▼ 2SK3472 (4.6)Ⓢ				▮ 2SK3371 (9)Ⓢ ▮ 2SK4026 (9)Ⓢ		■ 2SK2733 (9.0)Ⓢ ▼ 2SK2845 (9)Ⓢ ▼ 2SK3301 (20)Ⓢ			1	
1.1		△ SSM6K06FU(0.16)Ⓢ		△ SSM3J112TU(0.79)Ⓢ																			1.1	
1.2	▲ SSM6J23FE(0.16)Ⓢ	△ SSM3K106TU(0.53)Ⓢ ● SSM6P54TU(0.228)Ⓢ NS * SSM5H07TU(0.54)Ⓢ + SSM6K31FE(0.54)Ⓢ + SSM6K30FE(0.42)Ⓢ																					1.2	
1.3		△ SSM6J08FU(0.18)Ⓢ PS * TPCP8BA1(0.18)Ⓢ		+ SSM6J207FE(0.491)Ⓢ							⊠ TPCS8004-H (0.8)Ⓢ												1.3	
1.4	NS * SSM5H03TU(0.3)Ⓢ	+ SSM6K22FE(0.17)Ⓢ		△ SSM3J118TU(0.48)Ⓢ ● SSM6P40TU(0.403)Ⓢ PS * SSM5G11TU(0.403)Ⓢ NS * SSM5H01TU(0.45)Ⓢ + SSM6K210FE(0.371)Ⓢ																			1.4	
1.5	PS * SSM5G09TU(0.13)Ⓢ	△ SSM3K107TU(0.41)Ⓢ ● SSM6P39TU(0.213)Ⓢ NS * SSM5H05TU(0.16)Ⓢ NS * SSM5H08TU(0.16)Ⓢ		:- SSM3J02T(0.5)Ⓢ △ SSM3K128TU(0.36)Ⓢ PS * SSM5G10TU(0.213)Ⓢ △ SSM6K07FU(0.22)Ⓢ																			1.5	
1.6		NS * SSM5H10TU(0.19)Ⓢ NS * TPCP8AA1(0.105)Ⓢ ● SSM6L39TU(0.119)Ⓢ ● SSM6N39TU(0.119)Ⓢ △ SSM6K08FU(0.105)Ⓢ		:- SSM3J313T(0.268)Ⓢ NS * SSM5H11TU(0.182)Ⓢ ● SSM6L40TU(0.182)Ⓢ ● SSM6N40TU(0.182)Ⓢ																				1.6
1.7		△ SSM3J113TU(0.169)Ⓢ		:- SSM3J01T(0.4)Ⓢ :- SSM3J305T(0.477)Ⓢ								N ⊠ TPCS8008-H (0.58)Ⓢ											1.7	
1.8	PD * SSM6E03TU(0.144)Ⓢ	△ SSM3J108TU(0.158)Ⓢ △ SSM3J114TU(0.149)Ⓢ PD * SSM6E02TU(0.136)Ⓢ + SSM6J53FE(0.136)Ⓢ										★ TPC8012-H (0.4)Ⓢ											1.8	
1.9				NS * SSM5H12TU(0.133)Ⓢ + SSM6K208FE(0.133)Ⓢ								N ⊠ TPCS8007-H (0.45)Ⓢ											1.9	
2		△ SSM3J109TU(0.13)Ⓢ △ SSM3K122TU(0.123)Ⓢ ● SSM6K405TU(0.123)Ⓢ + SSM6J206FE(0.13)Ⓢ + SSM6K204FE(0.126)Ⓢ		△ SSM3J117TU(0.225)Ⓢ △ SSM3K127TU(0.123)Ⓢ ● SSM6J402TU(0.225)Ⓢ			◇ 2SK2615 (0.3)Ⓢ ▲ 2SK2961 (0.3)Ⓢ ◇ 2SK3658 (0.3)Ⓢ ● SSM6K407TU(0.44)Ⓢ ● SSM6K32TU(0.044)Ⓢ						▼ 2SJ610 (2.55)Ⓢ	⊗ 2SK3757 (2.45)Ⓢ ⊗ 2SK3766 (2.45)Ⓢ	☆ 2SK2599 (3.2)Ⓢ J 2SK3373 (3.2)Ⓢ				☆ 2SK2846 (5.0)Ⓢ J 2SK2865 (5.0)Ⓢ ⊗ 2SK3767 (4.5)Ⓢ ▮ 2SK4002 (5)Ⓢ ▮ TK2Q60D (5)Ⓢ				2	
2.1				△ SSM3K116TU(0.1)Ⓢ					N ⊠ TPCS8009-H (0.35)Ⓢ														2.1	
2.2		△ SSM3J115TU(0.098)Ⓢ △ SSM3K101TU(0.103)Ⓢ		△ SSM3K105TU(0.2)Ⓢ				▲ TPC8003-H (0.18)Ⓢ ★ TPC8214-H (0.18)Ⓢ															2.2	
2.3	△ SSM3J110TU(0.094)Ⓢ + SSM3J304T(0.127)Ⓢ			+ SSM6K202FE(0.085)Ⓢ																			2.3	
2.4				:- SSM3J306T(0.225)Ⓢ △ SSM3K124TU(0.12)Ⓢ																			2.4	
2.5		● SSM6J50TU(0.064)Ⓢ		△ SSM3K119TU(0.08)Ⓢ + SSM3K02T(0.2)Ⓢ ● SSM6J401TU(0.145)Ⓢ			:- SSM3K318T(0.145)Ⓢ					J 2SJ567 (2.0)Ⓢ ▮ 2SJ680 (2.0)Ⓢ							⊗ TK3A60DA (2.8)Ⓢ		⊗ 2SK3566 (6.4)Ⓢ		2.5	
2.6		△ SSM3K102TU(0.071)Ⓢ																					2.6	
2.7	+ SSM3J312T(0.091)Ⓢ	P# * TPC6105 (0.11)Ⓢ P# * TPCF8301 (0.11)Ⓢ PS# * TPCF8B01 (0.11)Ⓢ P# * TPCF8103 (0.11)Ⓢ		:- SSM3J14T(0.17)Ⓢ																			2.7	
2.8		+ SSM6K203FE(0.061)Ⓢ																					2.8	
2.9				:- SSM3K303T(0.12)Ⓢ																			2.9	
3	:- SSM3J13T(0.07)Ⓢ ● SSM6J21TU(0.05)Ⓢ	N# * TPCF8201 (0.049)Ⓢ NS# * TPCF8A01 (0.049)Ⓢ P# * TPCF8302 (0.059)Ⓢ P# * TPCF8303 (0.058)Ⓢ △ SSM3K104TU(0.056)Ⓢ ● SSM6K404TU(0.055)Ⓢ		:- SSM3K12T(0.175)Ⓢ :- SSM3K302T(0.071)Ⓢ ● SSM6K34TU(0.077)Ⓢ NS * SSM5H14F(0.078)Ⓢ				☆ 2SK2200 (0.35)Ⓢ J 2SK2201 (0.35)Ⓢ ▮ 2SK4018 (0.35)Ⓢ				J 2SK3462 (1.7)Ⓢ ▮ 2SK4022 (1.7)Ⓢ			◆ 2SK2862 (3.2)Ⓢ				▮ 2SK4003 (2.2)Ⓢ J 2SK3975 (2.2)Ⓢ	■ 2SK2603 (3.6)Ⓢ ○ 2SK2883 (3.6)Ⓢ	■ 2SK2608 (4.3)Ⓢ □ 2SK2719 (4.3)Ⓢ ⊗ 2SK3564 (4.3)Ⓢ			3
3.2		△ SSM3K121TU(0.048)Ⓢ + SSM6K211FE(0.047)Ⓢ		CP# * TPCF8402 (0.077)Ⓢ P# * TPCF8304 (0.072)Ⓢ + SSM3K01T(0.12)Ⓢ																			3.2	
3.4				CP# * TPCP8402 (0.072)Ⓢ				P# * TPCP8403 (0.070)Ⓢ															3.4	
3.5		+ SSM3K301T(0.056)Ⓢ		:- SSM3J314T(0.1)Ⓢ															⊗ TK4A55DA (2.45)Ⓢ		■ 2SK3085 (2.2)Ⓢ ⊗ 2SK3567 (2.2)Ⓢ ⊗ TK4A60DA (2.2)Ⓢ		3.5	
3.6		:- SSM3J317T(0.107)Ⓢ																					3.6	
3.8		P# * TPCP8303(0.04)Ⓢ																					3.8	
3.9				N# * TPC6006-H (0.075)Ⓢ																			3.9	
4	● SSM6J51TU(0.054)Ⓢ	△ SSM3J120TU(0.038)Ⓢ ● SSM6K18TU(0.04)Ⓢ		CN# * TPCF8402 (0.05)Ⓢ CN# * TPCP8404 (0.05)Ⓢ CP# * TPCP8404 (0.05)Ⓢ :- SSM3K316T(0.065)Ⓢ :- SSM3K14T(0.067)Ⓢ								N# * TPCA8008-H (0.58)Ⓢ							⊗ TK4A50D (2.0)Ⓢ		⊗ TK4A55D (1.9)Ⓢ ⊗ TK4A60D (1.7)Ⓢ	⊗ 2SK3798 (3.5)Ⓢ ■ 2SK1119 (3.8) ○ 2SK1930 (3.8)	4	

**Legend** **Product series** ① : π-MOSIII ② : π-MOSV ③ : π-MOSVI ④ : L<sup>2</sup>-π-MOSV ⑤ : L<sup>2</sup>-π-MOSVI ⑥ : U-MOS ⑦ : π-MOSVII ⑧ : π-MOSIV ⑨ : DTMOSI ⑩ : DTMOSII

**Package** ◇PW-Mini ↗VS-8 ♥VS-6 ♣PS-8 ⊕STP ▲TO-92MOD ▼PW-Mold J New PW-Mold ⊙TSON Advance ▮ New PW-Mold2 ▽DP ☆TPS ◀TSSOP Advance ⊠TSSOP-8 ★SOP-8  
 ⊙SOP-8 Lead Clamp ▶SOP Advance ◆TO-220NIS ⊗TO-220SIS ■TO-220AB □TO-220(W) ♣TFP ○TO-220FL/SM  
 \*S-Mini +TSM \*USM △UFM ⊕SSM +VESM +CST3 ◇CST3B ⊕CST4 +SMV /US6 ♣UF6 +ES6 \*CST6D /USV \*UFV ⊕ESV

**Notes:**  
 ( ) = Abs(max) \* = 1.8-V drive P = P-ch NS = N-ch + SBD PD = P-ch + Driver  
 \$ = 10-V drive Y = High-speed diode CN = Complementary N-ch PS = P-ch + SBD (load switch)  
 # = 2.5-V drive N = N-ch CP = Complementary P-ch [ ] = Under development

V <sub>DSS</sub> (V) I <sub>o</sub> (A)	12	20	24	30	40	50	60	100	150	180	200	250	400	450	500	525	550	600	650	700	800	900	1000	V <sub>DSS</sub> (V) I <sub>o</sub> (A)			
4.2		△SSM3K123TU(0.028)® ●SSM6K403TU(0.028)®		N★TPCP8201(0.05)® CN★TPCP8402(0.077)® +SSM3K3207T(0.077)®																					4.2		
4.4		△SSM3J130TU(0.0258)®		●SSM6K406TU(0.0385)®																					4.4		
4.5		P#♥TPC6107(0.055)®		P♥TPC6108(0.06)® CP★TPC8405(0.033)®								J 2SK3342(1.0)② J 2SK4021(1.0)②													4.5		
4.6		△SSM3J129TU(0.046)®																							4.6		
4.7		+SSM3K3097T(0.031)®			N★TPCP8403(0.040)® N★TPCP8203(0.040)®																				4.7		
4.8					P★TPCP8103-H(0.040)®																				4.8		
5		★TPC8208(0.05)® I TPCS8209(0.03)® N# I TPCS8210(0.03)® P# I TPCS8303(0.021)® P I TPCS8302(0.035)® P★TPCP8301(0.031)® P★TPCP8302(0.033)® +SSM3J3077T(0.031)® +SSM3K310T(0.028)®		I TPCS8209(0.05)® N# TPCF8001(0.032)® P★TPC8104-H(0.055)® N♥TPC6007-H(0.054)® P♥TPC6109-H(0.059)®	▲2SK2969(0.15)② ▲2SJ537(0.19)④	J 2SJ668(0.17)® J 2SJ681(0.17)® ☆2SJ378(0.19)④ ☆2SJ669(0.17)® ◆2SJ438(0.19)④ ☆2SK2229(0.16)④ J 2SK4017(0.1)® J 2SK4033(0.1)® ★TPC8213-H(0.05)®	J 2SK2399(0.23)④ ☆2SK2400(0.23)④ J 2SK4019(0.23)④	▼2SK3205(0.52)		◆2SJ512(1.25)②		◆2SJ407(1.0)② ◆2SK2381(0.8)② ☆2SK2835(0.8)② J 2SK2920(0.8)② J 2SK4020(0.8)②			○2SK2991(1.5)② ◆2SK3466(1.5)② ▽2SK3863(1.5)③ J 2SK4103(1.5)③ ▽○2SK3417(1.8)② ▽②2SK3868(1.7)③ ◎TK5A50D(1.5)⑦		◎TK5A55D(1.88)⑦	◎TK5A65D(1.45)⑦	◆2SK2274(1.7)	○2SK2884(2.2)①	◎2SK3565(2.5)⑧ □2SK3700(2.5)⑧ ◎2SK3742(2.5)⑧	□2SK1359(3.8)			5		
5.2		+SSM3J321T(0.046)®																							5.2		
5.4				+SSM3K131TU(0.0415)®																					5.4		
5.5	PD★TPC8401(0.038)® P♥TPC6103(0.035)®	P#♥TPC6111(0.04)®			N★TPC8211(0.036)® N★TPC8202(0.023)®						N▷TPCA8010-H(0.45)②		○2SK2838(1.2)② ◆2SK2679(1.2)②						◎TK6A55DA(1.48)⑦						5.5		
5.6		P#★TPCP8101(0.030)®																							5.6		
6	P#▷TPCF8101(0.028)®	N▷TPCT4201(0.031)® N▷TPCT4203(0.031)® N#♥TPC6004(0.024)® P#▷TPCF8102(0.030)® ★TPC8207(0.02)® I TPCS8211(0.024)® I TPCS8204(0.017)® P# I TPCS8102(0.02)® P# I TPCS8302(0.035)® N# I TPCS8212(0.024)® N# I TPCS8208(0.017)® N I TPCS8213(0.013)® N TPCL4201(0.031)®	N TPCL4203(0.036)®	N▷TPCT4202(0.036)® N▷TPCT4204(0.036)® N♥TPC6011(0.024)® N#♥TPC6005(0.028)® N▷TPCF8002(0.023)® PD★TPCP81(0.025)②⑦ P▷TPCF8104(0.028)® N I TPCS8214(0.135)® NS★TPC8A01(0.025)® ★TPC8212-H(0.021)® CN★TPC8405(0.025)® +SSM3K315T(0.0415)® N TPCL4202(0.04)®									◆2SJ516(0.8)②			◎TK6A50D(1.48)⑦ ◎TK6A53D(1.3)⑦				□2SK2602(1.25)② ○2SK2777(1.25)② ◆2SK3312(1.25)② ◎TK6A60D(1.25)⑦ ▽②2SK3947(1.4)③	◎TK6A65D(1.11)⑦		◎2SK4013(1.7)⑧ ◎2SK4014(2.0)⑧				6
6.5				N★TPC8216-H(0.020)®																		○2SK3879(1.7)⑧ ◎2SK3880(1.7)⑧			6.5		
6.7		●SSM6J409TU(0.0221)®																							6.7		
7				N▷TPCF8001(0.023)®	CN TPC8406-H(0.027)® CP TPC8406-H(0.03)®					N▷TPCA8009-H(0.35)②												□2SK3633(1.7)⑧ □2SK4115(2.0)⑧ ◎2SK1365(1.8)			7		
7.2		P#★TPCP8102(0.018)®		N★TPCP8001-H(0.016)®																					7.2		
7.5				N▷TPCA8020-H(0.027)® N★TPC8022-H(0.027)® P★TPC8116-H(0.03)® P▷TPCA8107-H(0.03)®									◆2SK2417(0.5)② ■2SK2914(0.5)②						◎TK6A55DA(1.07)⑦						7.5		
8				N★TPC8210(0.015)® N★TPC8021-H(0.017)®	P★TPC8110(0.025)®																	◎2SK2606(1.2)① ◎2SK2847(1.4)① ◎2SK3799(1.3)⑧	□2SK2613(1.7)①		8		
8.3				N★TPCP8004(0.009)®																					8.3		
8.5				NS★TPC8A01(0.018)⑤																			◎2SK3017(1.25)① □2SK3473(1.6)⑧ □2SK3878(1.3)⑧		8.5		
9		N★TPCP8006(0.01)®					N▷TPC8053-H(0.0232)®					◆2SK2350(0.4)②		◆2SK2952(0.55)②									□2SK2607(1.2)① □2SK3473(1.6)⑧ □2SK3878(1.3)⑧		9		
10		P★TPC8115(0.01)®		P★TPC8109(0.02)® P★TPC8119(0.012)® NS▷TPC8A05-H(0.012)®				J 2SK3669(0.125)⑦			□2SK200(0.83) □2SK1529(0.83) □2SK3497(0.15) □2SJ618(0.37)		■2SK2841(0.55)② ○2SK2949(0.55)②	○2SK3309(0.65)② ◆2SK3310(0.65)② ◎2SK3869(0.68)③	□2SK2601(1.0)② ◎TK10A50D(0.72)⑦					■2SK2866(0.75)② ○2SK2889(0.75)② ◆2SK3438(1.0)② ○2SK3437(1.0)② ○2SK3399(0.75)② ◎TK10A60D(0.75)⑦ ▽②2SK4015(0.86)③	◆2SK3265(1.0)⑧ ◎2SK3453(1.0)⑧		□2SK2968(1.25)①			10	

Legend **Product series** ①: π-MOSIII ②: π-MOSV ③: π-MOSVI ④: L<sup>2</sup>-π-MOSV ⑤: L<sup>2</sup>-π-MOSVI ⑥: U-MOS ⑦: π-MOSVII ⑧: π-MOSIV ⑨: DTMOSI ⑩: DTMOSII

**Package** ◊PW-Mini ▷VS-8 ♥VS-6 ♣PS-8 ◻STP ▲TO-92MOD ▼PW-Mold J New PW-Mold ○TSON Advance ◻ New PW-Mold2 ▽DP ☆TPS ◀TSSOP Advance X TSSOP-8 ★SOP-8 ◻ SOP-8 Lead Clamp ▶SOP Advance ◆TO-220NIS ◎TO-220SIS ■TO-220AB ◻TO-220(W) ♣TFP ○TO-220FLSM ◻TO-220SM(W) □TO-3P(N) ○TO-3P(N)JS ●TO-3P(L) ◻ Chip LGA

\*S-Mini +TSM \*USM △UFM ☆SSM +VESM +CST3 ◊CST3B ◎CST4 +SMV /US6 \*UF6 +ES6 \*CST6D /USV \*UFV ☆ESV

Notes:  
 ( ) = Rise/Fall max  
 \$ = 10-V drive  
 # = 2.5-V drive  
 \* = 1.8-V drive  
 ¥ = High-speed diode  
 N = N-ch  
 P = P-ch  
 CN = Complementary N-ch  
 CP = Complementary P-ch  
 NS = N-ch + SBD  
 PS = P-ch + SBD  
 PD = P-ch + Driver (load switch)  
 [ ] = Under development



V <sub>DSS</sub> (V) I <sub>D</sub> (A)	20	30	40	50	60	75	80	100	150	200	250	300	450	500	525	550	600	900/1000	V <sub>DSS</sub> (V) I <sub>D</sub> (A)		
11		N★ TPC8025 (0.009)Ⓢ N★ TPC8021-H (0.017)Ⓢ N★ TPC8014 (0.014)Ⓢ P★ TPC8111 (0.012)Ⓢ P★ TPC8113 (0.01)Ⓢ P Z TPCS8105 (0.0135)Ⓢ P Z TPCS8104 (0.012)Ⓢ N★ TPC8030 (0.0095) N★ TPC8031-H (0.0133)Ⓢ N★ TPC8005-H (0.0133)Ⓢ P★ TPC8121 (0.012)Ⓢ P★ TPC8123 (0.0090)Ⓢ				N○ TPC8050-H (0.0145)Ⓢ					◆ 2SK2965 (0.26)Ⓢ							⊗ TK11A55D (0.63)Ⓢ	⊗ TK11A60D (0.65)Ⓢ		11
12		N○ TPC8037-H (0.0114)Ⓢ N○ TPC8038-H (0.0114)Ⓢ	N○ TPC8052-H (0.0121)Ⓢ					◆ 2SJ380 (0.21)Ⓢ		◆ 2SJ201 (0.625) ◆ 2SK1530 (0.625)				○ 2SK3068 (0.52)Ⓢ ◆ 2SK3398 (0.52)Ⓢ ⊗ TK12A50D (0.52)Ⓢ ▼ ◆ 2SK3313 (0.62)Ⓢ	⊗ TK12A53D (0.58)Ⓢ ◆ TK12X53D (0.58)Ⓢ	□ TK12J55D (0.57)Ⓢ	□ 2SK2699 (0.65)Ⓢ ⊗ TK12A60U (0.4)Ⓢ ⊗ TK12D60U (0.4)Ⓢ □ TK12J60U (0.4)Ⓢ ⊗ TK12A60D (0.55)Ⓢ	1000V: ◆ 2SK1489 (1.0)		12	
12.5														⊗ TK13A50DA (0.47)Ⓢ						12.5	
13		N★ TPC8041 (0.007)Ⓢ N★ TPC8026 (0.0066)Ⓢ P★ TPC8107 (0.007)Ⓢ P○ TPC8112 (0.006)Ⓢ P○ TPC8118 (0.007)				N○ TPC8049-H (0.0107)Ⓢ		N○ TPC8051-H (0.0097)Ⓢ		◆ 2SK2508 (0.25)Ⓢ ○ 2SK2598 (0.25)Ⓢ			◆ 2SK3743 (0.4)Ⓢ ○ 2SK3403 (0.4)Ⓢ ◆ 2SK3544 (0.4)Ⓢ ⊗ TK13A45D (0.46)Ⓢ	⊗ TK13A50D (0.4)Ⓢ			⊗ TK13A60D (0.43)Ⓢ ▼ ⊗ 2SK4016 (0.5)Ⓢ	900V: □ 2SK4207 (0.95)		13	
14					◆ 2SJ304 (0.12) 2SJ312 (0.12)									○ 2SK2916 (0.4)Ⓢ		⊗ TK14A55D (0.37)Ⓢ	□ 2SK3903 (0.44)Ⓢ		14		
15		N○ TPC8032-H (0.0065)Ⓢ P○ TPC8102 (0.0185)Ⓢ			▶ TPCA8053-H (0.0229)Ⓢ					◆ 2SK2382 (0.18)Ⓢ ○ 2SK2401 (0.18)Ⓢ				⊗ TK15A50D (0.3)Ⓢ ▼ □ 2SK3314 (0.49)Ⓢ □ TK15J50D (0.4)Ⓢ			○ 2SK2953 (0.4)Ⓢ ⊗ TK15A60U (0.3)Ⓢ ⊗ TK15D60U (0.3)Ⓢ □ TK15J60U (0.3)Ⓢ ⊗ TK15A60D (0.37)Ⓢ		15		
16		NS★ TPC8A02-H (0.0056)Ⓢ	N○ TPC8047-H (0.0076)Ⓢ		N○ TPC8048-H (0.0069)Ⓢ			○ 2SJ412 (0.21)Ⓢ ◆ 2SJ619 (0.21)Ⓢ								□ TK16J55D (0.37)Ⓢ			16		
17		N○ TPC8033-H (0.0053)Ⓢ NS○ TPC8A03-H (0.0056)Ⓢ N○ TPC8039-H (0.0059)Ⓢ N○ TPC8003-H (0.0193)Ⓢ											⊗ 2SK3935 (0.25)Ⓢ	□ 2SK3905 (0.31)Ⓢ						17	
18		P○ TPC8114 (0.0045)Ⓢ N★ TPC8027 (0.0027)Ⓢ N★ TPC8028 (0.0043)Ⓢ N★ TPC8029 (0.0038)Ⓢ N○ TPC8034-H (0.0035)Ⓢ N★ TPC8042 (0.0034)Ⓢ P○ TPC8117 (0.0039)Ⓢ N○ TPC8036-H (0.0042)Ⓢ NS○ TPC8A04-H (0.0036)Ⓢ P○ TPC8120 (0.0032)Ⓢ P○ TPC8103 (0.013)Ⓢ	N○ TPC8045-H (0.0039)Ⓢ N○ TPC8046-H (0.0057)Ⓢ			◆ 2SJ464 (0.12)Ⓢ ◆ 2SJ620 (0.09)Ⓢ ▶ TPCA8006-H (0.067)	◆ 2SK2882 (0.12)Ⓢ ◆ 2SK3387 (0.12)Ⓢ								○ 2SK2917 (0.27)Ⓢ ⊗ TK18A50D (0.27)Ⓢ					18	
19														□ 2SK3904 (0.26)Ⓢ						19	
20		N○ TPC8001-H (0.015)Ⓢ N○ TPC8002-H (0.015)Ⓢ NS★ TPC8A05-H (0.0172)Ⓢ NS▶ TPCA8A05-H (0.0172)Ⓢ	N▶ TPCA8052-H (0.0118)Ⓢ	▼ 2SK2614 (0.046)Ⓢ	◆ 2SJ349 (0.045)Ⓢ ○ 2SJ401 (0.045)Ⓢ ▼ 2SK2782 (0.055)Ⓢ			◆ 2SK2391 (0.085)Ⓢ ⊗ TJ20A10M3 (0.090)Ⓢ				○ 2SK2993 (0.105)Ⓢ ◆ 2SK3445 (0.105)Ⓢ ◆ 2SK3994 (0.105)Ⓢ			□ TK20J50D (0.27)Ⓢ			□ 2SK3911 (0.32)Ⓢ ⊗ TK20A60U (0.19)Ⓢ ⊗ TK20D60U (0.19)Ⓢ □ TK20J60U (0.19)Ⓢ ▼ □ 2SK3906 (0.33)Ⓢ		20	
21		N★ TPC8007-H (0.0129)Ⓢ NS○ TPC8A01-H (0.012)Ⓢ																		21	
22								▶ TPCA8022-H (0.026)Ⓢ												22	
23																□ 2SK3907 (0.23)Ⓢ ▼ □ 2SK3936 (0.25)Ⓢ				23	

Legend **Product series** ① : π-MOSIII ② : π-MOSV ③ : π-MOSVI ④ : L<sup>2</sup>-π-MOSV ⑤ : L<sup>2</sup>-π-MOSVI ⑥ : U-MOS ⑦ : π-MOSVII ⑧ : π-MOSIV ⑨ : DTMOI ⑩ : DTMOII

**Package** ◊ PW-Mini ↗ VS-8 ♥ VS-6 ♣ PS-8 ⊕ STP ▲ TO-92MOD ▼ PW-Mold ↘ New PW-Mold ○ TSON Advance

⊙ SOP-8 Lead Clamp ▶ SOP Advance ◆ TO-220NIS ⊗ TO-220SIS ■ TO-220AB ⊞ TO-220(W) ⚡ TFP ○ TO-220FL/SM

\* S-Mini † TSM \* USM △ UFM ☆ SSM † VESM † CST3 ◊ CST3B ⊙ CST4 † SMV ∠ US6 \* UF6

🎵 New PW-Mold2 ▽ DP ☆ TPS ◀ TSSOP Advance ✂ TSSOP-8 ★ SOP-8

⚡ TO-220SM(W) □ TO-3P(N) ○ TO-3P(N)IS ● TO-3P(L) ⊞ Chip LGA

† ES6 \* CST6D ^ USV \* UFV ☆ ESV

Notes:  
 ( ) = R<sub>DS(on)</sub> max \* = 1.8-V drive P = P-ch NS = N-ch + SBD PD = P-ch + Driver  
 \$ = 10-V drive ¥ = High-speed diode CN = Complementary N-ch PS = P-ch + SBD (load switch)  
 # = 2.5-V drive N = N-ch CP = Complementary P-ch [ ] = Under development

V <sub>DSS</sub> (V) I <sub>D</sub> (A)	20	30	40	50	60	75	80	100	150	200	250	300	450	500	525	550	600	900/1000	V <sub>DSS</sub> (V) I <sub>D</sub> (A)		
24		N ◀ TPCM8004-H (0.011)Ⓞ N ▶ TPCA8030-H (0.011)Ⓞ N ▶ TPCA8031-H (0.011)Ⓞ NS ⊙ TPC8006-H (0.086)Ⓞ N ⊙ TPC8008 (0.007)Ⓞ			N ▶ TPCA8050-H (0.0142)Ⓞ															24	
25		P ◀ TPCM8102 (0.0077)Ⓞ N ◀ TPCM8006 (0.007)Ⓞ		◆ 2SK2507 (0.046)Ⓞ	◆ 2SK2232 (0.046)Ⓞ ○ 2SK2311 (0.046)Ⓞ N ▶ TPCA8016-H (0.021)Ⓞ			⊗ TK25A10K3 (0.040)Ⓞ		◆ 2SK3444 (0.082)Ⓞ ○ 2SK3625 (0.082)Ⓞ				● 2SK1544 (0.2)						25	
26		N ⊙ TPC8005-H (0.0073)Ⓞ	◆ 2SK3846 (0.016)Ⓞ																	26	
27	N ⊙ TPC8007 (0.0055)Ⓞ																			27	
28					N ▶ TPCA8049-H (0.0104)Ⓞ		N ▶ TPCA8051-H (0.0094)Ⓞ													28	
30		N ▶ TPCA8018-H (0.0062)Ⓞ N ▶ TPCA8027-H (0.010)Ⓞ	N ▶ TPCA8014-H (0.009)Ⓞ N ▶ TPCA8027-H (0.010)Ⓞ		◆ 2SJ334 (0.038)Ⓞ ○ 2SJ402 (0.038)Ⓞ ⊗ TK30A06J3A (0.026)Ⓞ				◆ 2SK3443 (0.055)Ⓞ	□ 2SK3176 (0.052)Ⓞ	□ 2SK2967 (0.068)Ⓞ ⊙ 2SK2995 (0.068)Ⓞ									30	
32			○ 2SK3847 (0.016)Ⓞ N ▶ TPCA8047-H (0.0073)Ⓞ											● 2SK1486 (0.095)						32	
34		NS ▶ TPCA802-H (0.0053)Ⓞ N ▶ TPCA8039-H (0.0055)Ⓞ																		34	
35		N ▶ TPCA8012-H (0.0049)Ⓞ N ▶ TPCA8024 (0.0043)Ⓞ	N ▶ TPCA8015-H (0.0054)Ⓞ		◆ 2SK3662 (0.0125)Ⓞ N ▶ TPCA8048-H (0.0066)Ⓞ															35	
36					◆ 2SK2385 (0.03)Ⓞ															36	
38		N ▶ TPCA8036-H (0.0038)Ⓞ	N ▶ TPCA8046-H (0.0054)Ⓞ																	38	
40	N ▶ TPCA8011-H (0.0035)Ⓞ	P ▶ TPCA8102 (0.006)Ⓞ P ▶ TPCA8103 (0.0042)Ⓞ P ▶ TPCA8106 (0.0037)Ⓞ N ▶ TPCA8012-H (0.0045)Ⓞ N ▶ TPCA8025 (0.0036)Ⓞ N ▶ TK40P03M1 (0.0108)Ⓞ	P ▶ TPCA8108 (0.0095)Ⓞ N ▶ TK40P04M1 (0.0103)Ⓞ		P ▶ TPCA8104 (0.016)Ⓞ	⊗ TK40A08K3 (0.009)Ⓞ			⊞ TK40D10J1 (0.015)Ⓞ ⊗ TK40A10J1 (0.015)Ⓞ ⊗ TK40A10K3 (0.015)Ⓞ ◆ TK40X10J1 (0.020)Ⓞ									□ TK40J60T (0.08)Ⓞ		40	
42		NS ▶ TPCA804-H (0.0032)Ⓞ																		42	
45		□ 2SK3506 (0.02) N ▶ TPCA8019-H (0.0031)Ⓞ N ▶ TPCA8026 (0.0022)Ⓞ N ▶ TPCA8042 (0.0033)Ⓞ		□ 2SK2550 (0.03)Ⓞ ◆ 2SK2886 (0.02)Ⓞ □ 2SK2744 (0.02)Ⓞ □ 2SK3051 (0.03)Ⓞ	□ 2SK2233 (0.03)Ⓞ ○ 2SK2266 (0.03)Ⓞ ○ 2SK2376 (0.017)Ⓞ □ 2SK2398 (0.03)Ⓞ ◆ 2SK3844 (0.0058)Ⓞ																45
46			N ▶ TPCA8045-H (0.0036)Ⓞ																	46	
50		N ▶ TPCA8028-H (0.0028)Ⓞ N ▶ TK50P03M1 (0.0075)Ⓞ	N ▶ TK50P04M1 (0.0087)Ⓞ	□ 2SK2551 (0.011)Ⓞ □ 2SK2745 (0.0095)Ⓞ	□ 2SK2173 (0.017)Ⓞ □ 2SK2445 (0.018)Ⓞ			□ 2SK1381 (0.032)	◆ TK50X15J1 (0.03)Ⓞ ◆ TK50F15J1 (0.03)Ⓞ					● 2SK3132 (0.09)Ⓞ ◆ 2SK3131 (0.11)Ⓞ						50	
55																				55	
60					● 2SK2267 (0.011)Ⓞ □ 2SK2313 (0.011)Ⓞ	⊞ TK60D08J1 (0.0078)Ⓞ ⊗ TK60A08J1 (0.0078)Ⓞ			● 2SK1382 (0.020)											60	
70			□ TK70J04J3 (0.0038)Ⓞ		□ 2SK3845 (0.0058)Ⓞ ⊞ TK70D06J1 (0.0064)Ⓞ ⊗ TK70A06J1 (0.0064)Ⓞ ⊗ TJ70A06J3 (0.008)Ⓞ															70	
75			◆ 2SK3843 (0.0035)Ⓞ		◆ 2SK4034 (0.0058)Ⓞ ◆ 2SK3842 (0.0058)Ⓞ															75	
80																				80	
100			◆ TK100F04K3 (0.003)Ⓞ		◆ TK100F06K3 (0.005)Ⓞ															100	
120					◆ TJ120F06J3 (0.008)Ⓞ															120	
130					◆ TK130F06K3 (0.0034)Ⓞ															130	
150			◆ TK150F04K3 (0.0021)Ⓞ																	150	

Legend **Product series** ① : π-MOSIII ② : π-MOSV ③ : π-MOSVI ④ : L<sup>2</sup>-π-MOSV ⑤ : L<sup>2</sup>-π-MOSVI ⑥ : U-MOS ⑦ : π-MOSVII ⑧ : π-MOSIV ⑨ : DTMOSI ⑩ : DTMOSII

**Package** ◊ PW-Mini } VS-8 ♥ VS-6 ♣ PS-8 ⊕ STP ▲ TO-92MOD ▼ PW-Mold } New PW-Mold ⊙ TSON Advance ] New PW-Mold2 ▽ DP ☆ TPS ◀ TSSOP Advance ✕ TSSOP-8 ★ SOP-8  
 ⊙ SOP-8 Lead Clamp ▶ SOP Advance ◆ TO-220NIS ⊗ TO-220SIS ■ TO-220AB ⊞ TO-220(W) ◆ TFP ○ TO-220FL/SM  
 \* S-Mini † TSM ‡ USM △ UFM ⊙ SSM † VESM ‡ CST3 ◊ CST3B ⊙ CST4 † SMV / US6 • UF6 † ES6 \* CST6D \ USV \* UFV ☆ ESV

Notes:  
 ( ) = R<sub>DS(on)</sub> max \* = 1.8-V drive P = P-ch NS = N-ch + SBD PD = P-ch + Driver  
 \$ = 10-V drive † = High-speed diode CN = Complementary N-ch PS = P-ch + SBD (load switch)  
 # = 2.5-V drive N = N-ch CP = Complementary P-ch [ ] = Under development

## 4-1 Packaging Options

### SSM Series

The SSM Series comes in small, thin packages suitable for portable devices. Chip-scale packages (1006 size) help reduce system size.

<p><b>CST3</b> Chip-Scale Package, Transfer Molded, 3-Pin</p> <p>Typical product: SSM3K35CT</p> <p>Thickness: 0.38 typ.</p> <p>Unit: mm</p>	<p><b>CST3B</b> Chip-Scale Package, Transfer Molded, 3-Pin, B-Type</p> <p>Typical product: SSM3J46CTB</p> <p>Thickness: 0.48 typ.</p> <p>Unit: mm</p>	<p><b>VESM (SOT-723)</b> Very Extreme Super-Mini</p> <p>Typical product: SSM3K35MFV</p> <p>Thickness: 0.5 typ.</p> <p>Unit: mm</p>	<p><b>SSM (SOT-416)(SC-75)</b> Small Super-Mini</p> <p>Typical product: SSM3K35FS</p> <p>Thickness: 0.7 typ.</p> <p>Unit: mm</p>	<p><b>USM (SOT-323)(SC-70)</b> Ultra-Super-Mini</p> <p>Typical product: SSM3K15FU</p> <p>Thickness: 0.9 typ.</p> <p>Unit: mm</p>
<p><b>UFM</b> Ultra-super-Mini Flat lead</p> <p>Typical product: SSM3J130TU</p> <p>Thickness: 0.7 typ.</p> <p>Unit: mm</p>	<p><b>S-Mini (SOT-346)(SC-59)</b> Super-Mini</p> <p>Typical product: SSM3K15F</p> <p>Thickness: 1.1 typ.</p> <p>Unit: mm</p>	<p><b>TSM</b> Thin Super-Mini</p> <p>Typical product: SSM3J304T</p> <p>Thickness: 0.7 typ.</p> <p>Unit: mm</p>	<p><b>CST4</b> Chip-Scale Package, Transfer Molded, 4-Pin</p> <p>Typical product: SSM4K27CT</p> <p>Thickness: 0.38 typ.</p> <p>Unit: mm</p>	<p><b>ESV (SOT-553)</b> Extreme Super-mini, 5-pin</p> <p>Typical product: SSM5N15FE</p> <p>Thickness: 0.55 typ.</p> <p>Unit: mm</p>
<p><b>USV (SOT-353)(SC-88A)</b> Ultra-Super-mini, 5-pin</p> <p>Typical product: SSM5N15FU</p> <p>Thickness: 0.9 typ.</p> <p>Unit: mm</p>	<p><b>UFV</b> Ultra-super-mini, Flat lead, 5-pin</p> <p>Typical product: SSM5H12TU</p> <p>Thickness: 0.7 typ.</p> <p>Unit: mm</p>	<p><b>SMV (SOT-25)(SC-74A)</b> Super-Mini, 5-pin</p> <p>Typical product: SSM5H14F</p> <p>Thickness: 1.1 typ.</p> <p>Unit: mm</p>	<p><b>CST6D</b> Chip-Scale Package, Transfer Molded, 6-Pin, D-Type</p> <p>Typical product: SSM6N37CTD</p> <p>Thickness: 0.38 typ.</p> <p>Unit: mm</p>	<p><b>ES6 (SOT-563)</b> Extreme Super-mini, 6-pin</p> <p>Typical product: SSM6N36FE</p> <p>Thickness: 0.55 typ.</p> <p>Unit: mm</p>
<p><b>US6 (SOT-353)(SC-88A)</b> Ultra-Super-mini, 6 pin</p> <p>Typical product: SSM6N15FU</p> <p>Thickness: 0.9 typ.</p> <p>Unit: mm</p>	<p><b>UF6</b> Ultra Super mini Flat lead 6-pin</p> <p>Typical product: SSM6J409TU</p> <p>Thickness: 0.7 typ.</p> <p>Unit: mm</p>			

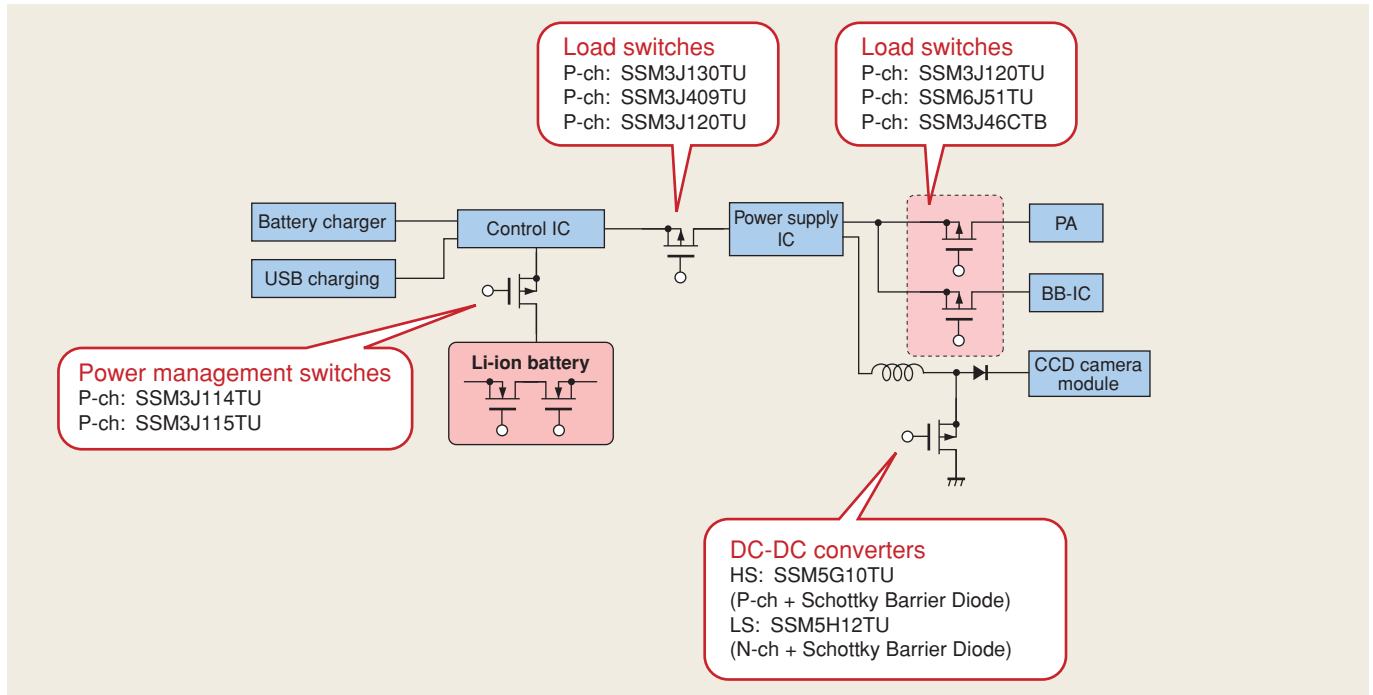
### TPC Series

The TPC Series comes in small, thin packages suitable for portable devices. The latest TSON Advance package allows the maximum permissible power dissipation equivalent to SOP-8, but occupies 64% less board space.

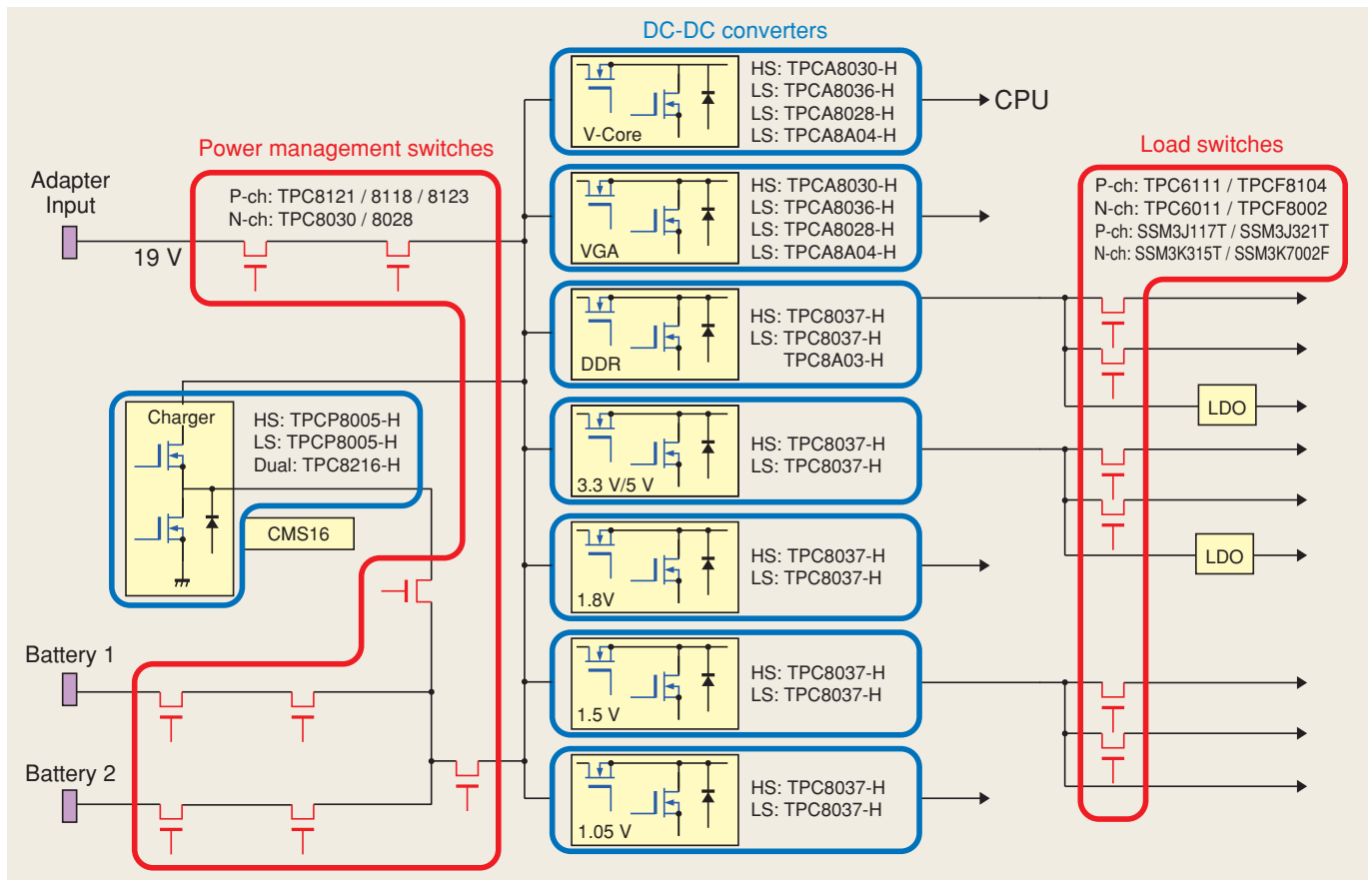
<p><b>VS-6</b> Very Thin &amp; Small, 6-pin</p> <p>Typical product: TPC6003</p> <p>Thickness: 0.75 typ.</p> <p>Unit: mm</p>	<p><b>VS-8</b> Very Thin &amp; Small, 8-pin</p> <p>Typical product: TPCF8101</p> <p>Thickness: 0.8 typ.</p> <p>Unit: mm</p>	<p><b>PS-8</b> Progressive &amp; Small 8-pin Series</p> <p>Typical product: TPCP8402</p> <p>Thickness: 0.8 typ.</p> <p>Unit: mm</p>	<p><b>Chip LGA</b> Land Grid Array</p> <p>Typical product: TPCL4201</p> <p>Thickness: 0.25 typ.</p> <p>Unit: mm</p>	<p><b>STP2</b> Small Thin Package</p> <p>Typical product: TPCT4204</p> <p>Thickness: 0.65 typ.</p> <p>Unit: mm</p>
<p><b>TSON Advance</b></p> <p>Typical product: TPCC8005-H</p> <p>Thickness: 0.85 typ.</p> <p>Unit: mm</p>	<p><b>TSSOP-8</b></p> <p>Typical product: TPCS8208</p> <p>Thickness: 0.9 typ.</p> <p>Unit: mm</p>	<p><b>TSSOP Advance</b></p> <p>Typical product: TPCM8001-H</p> <p>Thickness: 0.75 typ.</p> <p>Unit: mm</p>	<p><b>SOP-8</b></p> <p>Typical product: TPC8035-H</p> <p>Thickness: 1.6 typ.</p> <p>Unit: mm</p>	<p><b>SOP Advance</b></p> <p>Typical product: TPCA8028-H</p> <p>Thickness: 0.95 typ.</p> <p>Unit: mm</p>

## 4-2 Application Examples and Block Diagrams

### Cell Phone (Power Supply Circuit)

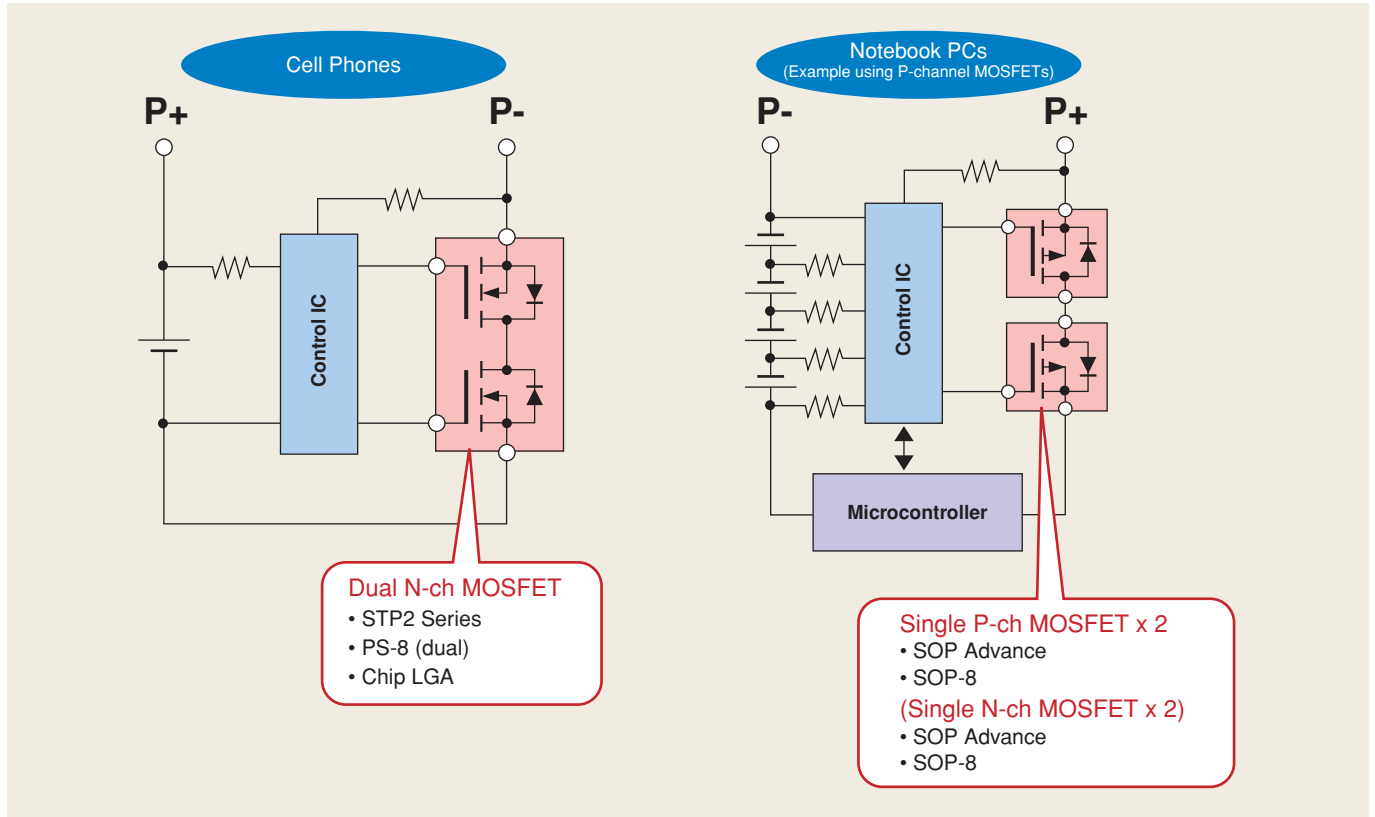


### Notebook PC (Power Supply Circuit)

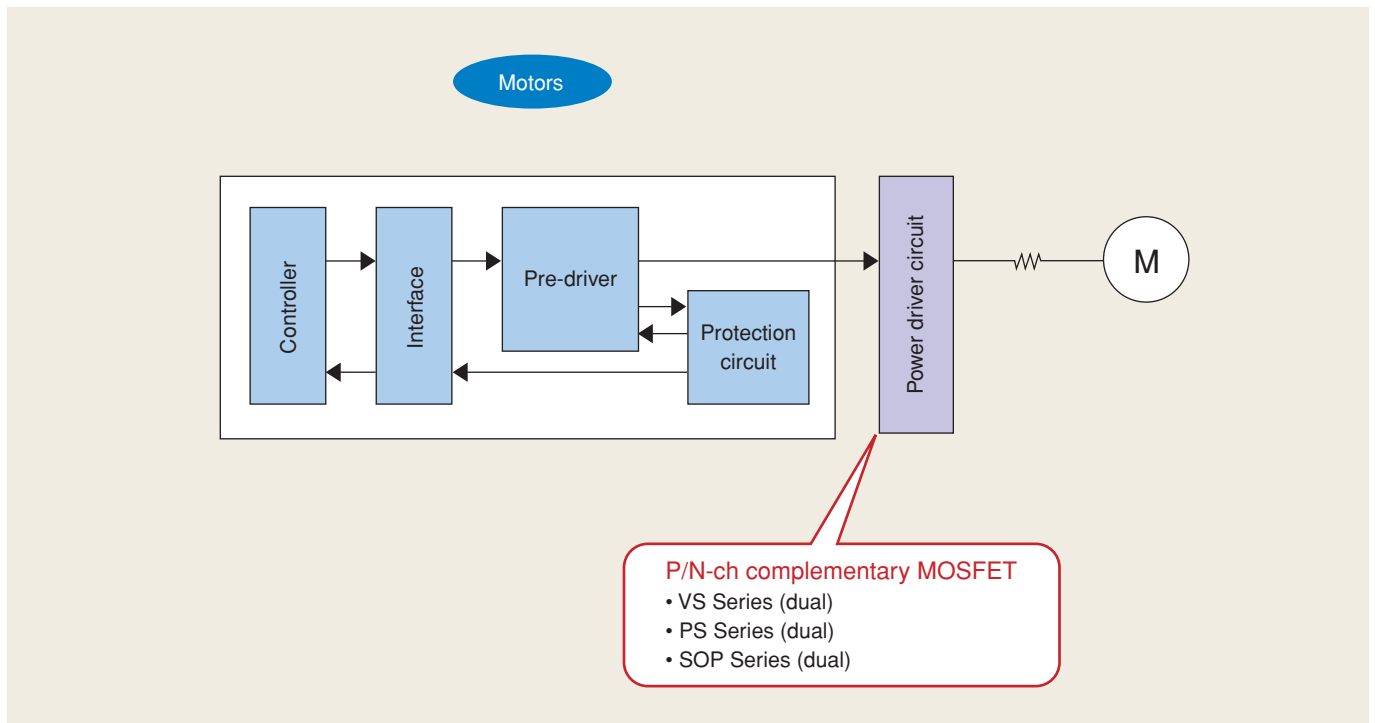


## 4-2 Application Examples and Block Diagrams

### Lithium-Ion Secondary Battery Protection Circuits



### Motor Driver (Power Driver Circuit)

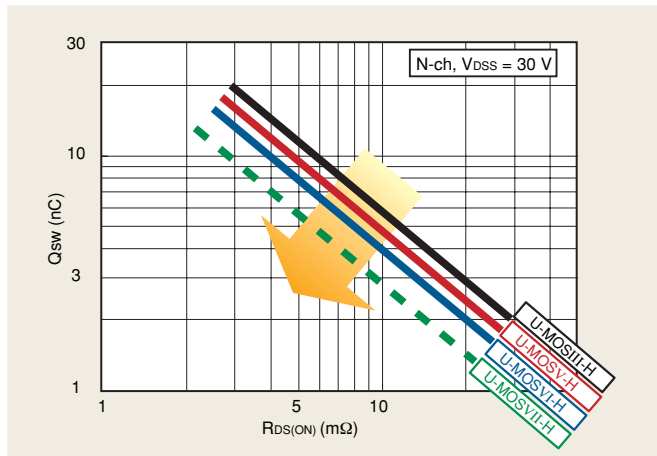




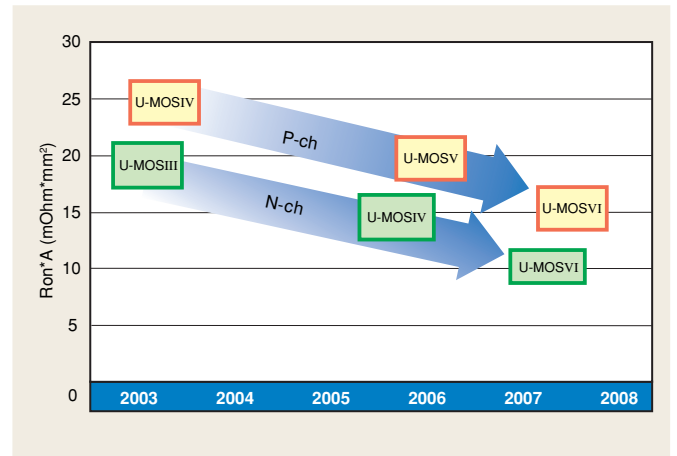
## 4-3 Low- $V_{DSS}$ MOSFET Roadmaps

### Roadmap for Trench MOSFETs

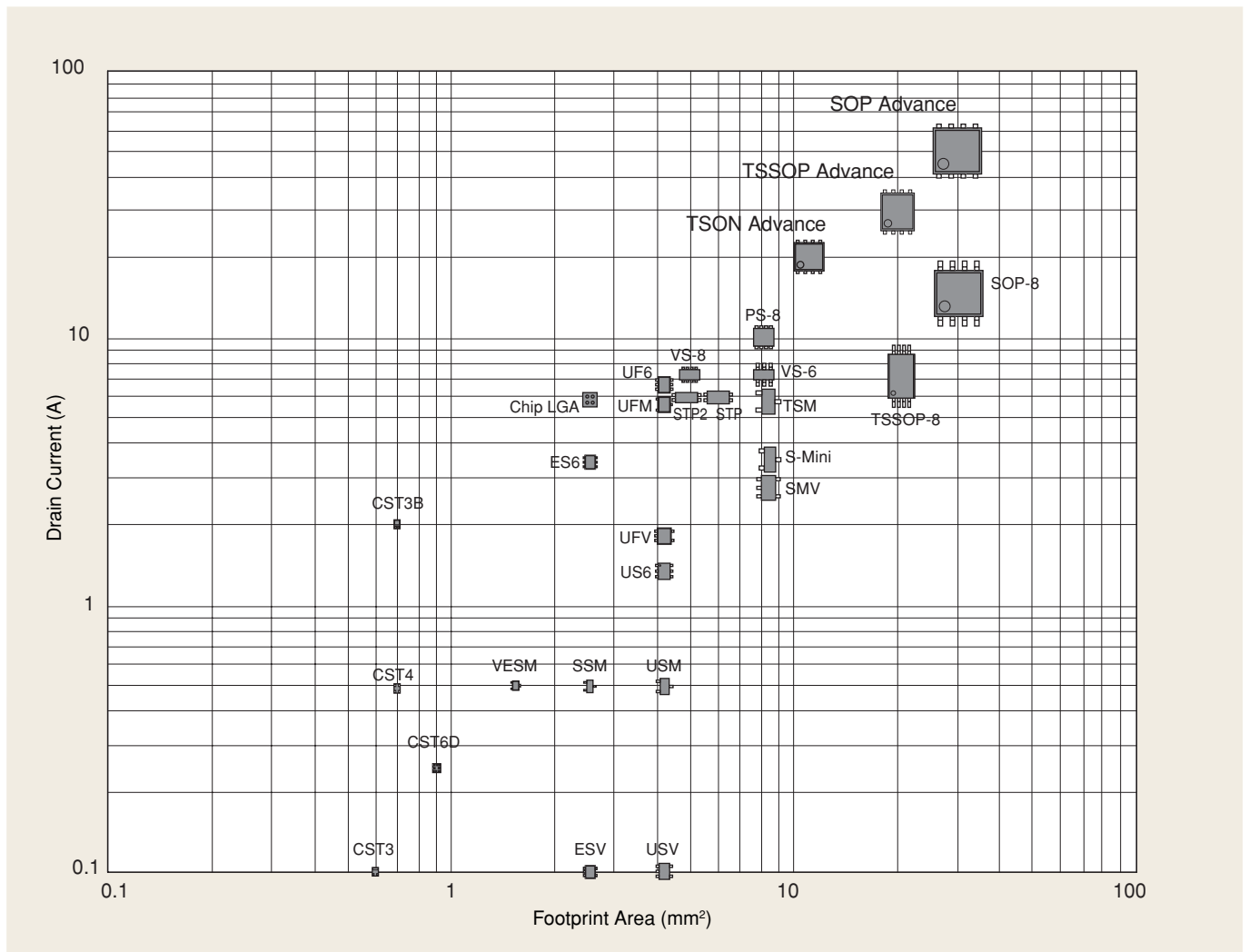
■ High-Speed, Low- $V_{DSS}$  U-MOS



■ Low-Ron Trench MOSFETs



### Package Options



# 4

# Low- $V_{DSS}$ MOSFETs (in Small SMD Packages)

## Ultra-Small Packages

	S-Mini	USM	SSM	VESM	CST3	US6	USV	ESV	CST6D
Footprint Area	7.3 mm <sup>2</sup>	4.2 mm <sup>2</sup>	2.6 mm <sup>2</sup>	1.4 mm <sup>2</sup>	0.6 mm <sup>2</sup>	4.2 mm <sup>2</sup>	4.2 mm <sup>2</sup>	2.6 mm <sup>2</sup>	0.9 mm <sup>2</sup>
Permissible Power Dissipation	0.2 W	0.2 W	0.1 W	0.15 W	0.1 W	0.2 W	0.2 W	0.15 W	0.14 W
Height (MAX)	1.4 mm	1.1 mm	0.9 mm	0.55 mm	0.4 mm	1.1 mm	1.1 mm	0.6 mm	0.4 mm

## Thermally-Enhanced Compact Packages

	TSM	UF6	SMV	UFV	UFM	ES6	CST3B	CST4
Footprint Area	8.1 mm <sup>2</sup>	4.2 mm <sup>2</sup>	8.1 mm <sup>2</sup>	4.2 mm <sup>2</sup>	4.2 mm <sup>2</sup>	2.6 mm <sup>2</sup>	1.0 mm <sup>2</sup>	1.0 mm <sup>2</sup>
Permissible Power Dissipation (Note)	0.7 W	0.5 W	0.75 W	0.5 W	0.5 W	0.5 W	0.4 W	0.4 W
Height (MAX)	0.85 mm	0.75 mm	1.4 mm	0.75 mm	0.75 mm	0.6 mm	0.5 mm	0.4 mm

Note: Mounted on FR4 Board (24.5 x 24.5 mm)

## Thermally Enhanced Packages

	SOP Adv.	SOP-8	TSSOP Adv.	TSON Adv.
Footprint Area	30 mm <sup>2</sup>	30 mm <sup>2</sup>	16.3 mm <sup>2</sup> (-46%)	10.9 mm <sup>2</sup> (-64%)
Permissible Power Dissipation	2.8 W (+47%)	1.9 W	2.3 W (+21%)	1.9 W
Height	1.0 mm (-47%)	1.9 mm	0.8 mm (-58%)	0.9 mm (-53%)

(Percentage relative to SOP-8)

## Compact Packages

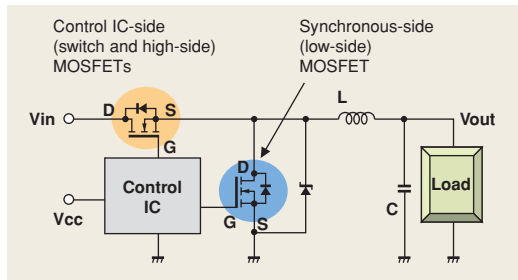
	VS-8	VS-6	PS8	LGA
Footprint Area	5.5 mm <sup>2</sup> (-32%)	8.1 mm <sup>2</sup>	8.1 mm <sup>2</sup>	2.56 mm <sup>2</sup>
Permissible Power Dissipation	2.5 W (+14%)	2.2 W	1.68 W (-24%)	—
Height	0.85 mm	0.85 mm	0.85 mm	0.25 mm

(Percentage relative to VS-6)

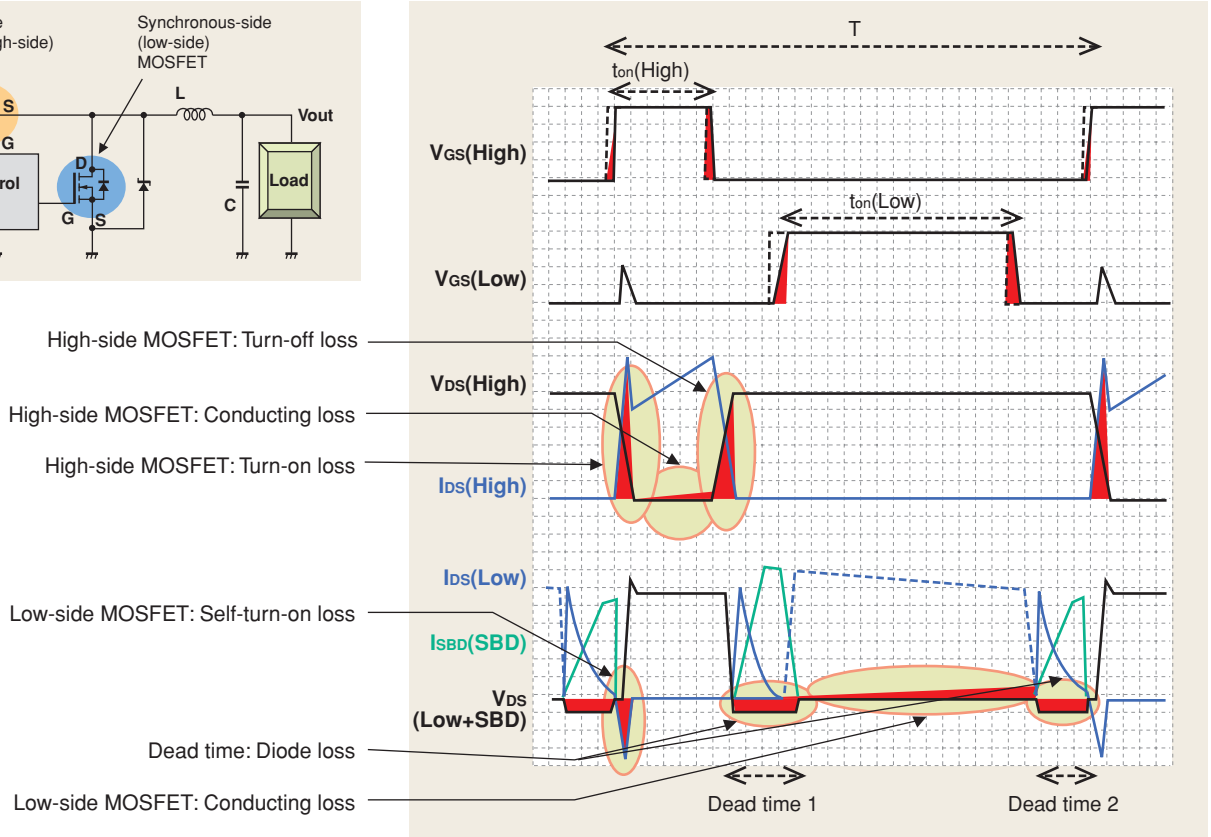
## 4-4 Low- $V_{DS}$ , High-Speed MOSFETs

### Synchronous Rectification DC-DC Converters – Block Diagram, Timing Chart and Power Loss Factors

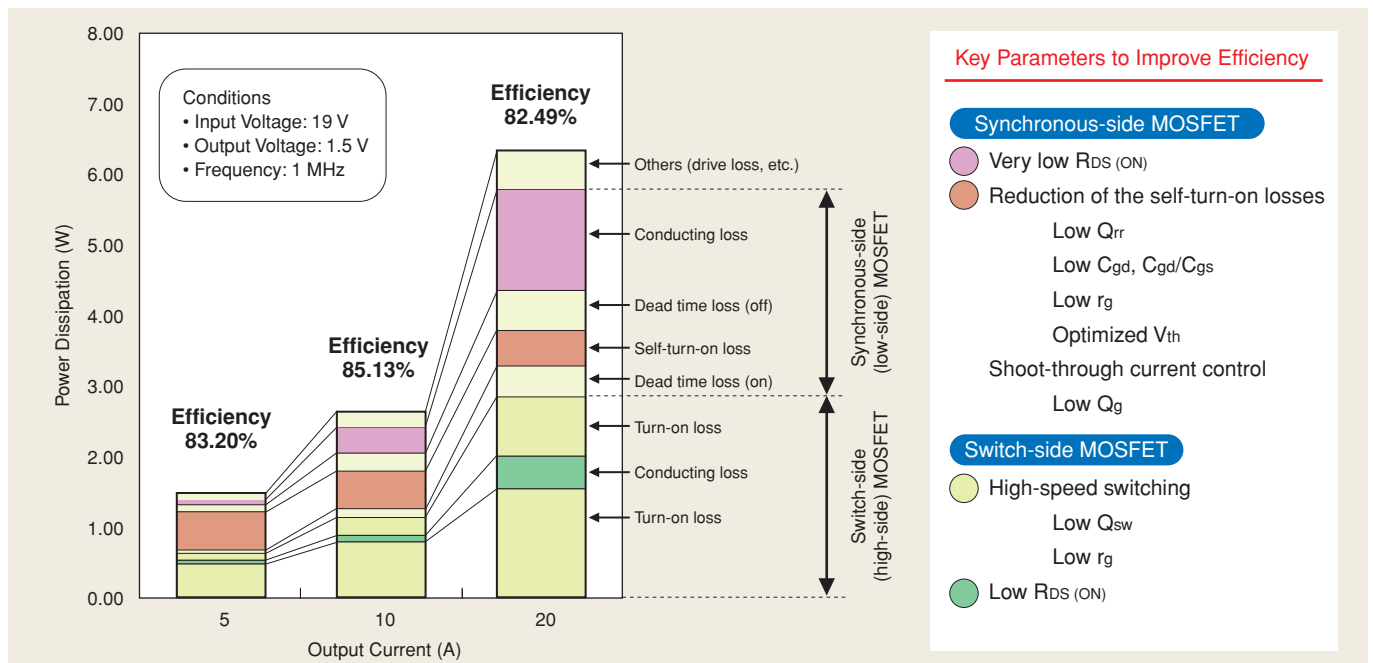
#### Block Diagram



#### Timing Chart



### Synchronous Rectification DC-DC Converters – Summary Results of Power Loss Simulation and Key Parameters for MOSFETs

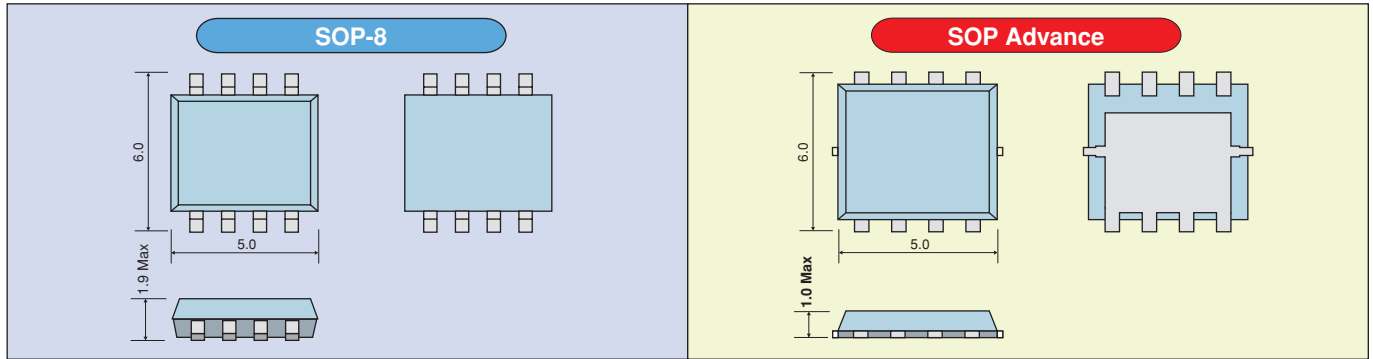


## Synchronous Rectification DC-DC Converters – Efficiency Improvement by Thermally Enhanced Package and New Process Technology

### Thermally Enhanced Package

Toshiba has developed the SOP Advance package with the same footprint area as the standard SOP-8 package. With an external heatsink on the bottom, the SOP Advance package offers enhanced thermal characteristics, realizing a high power dissipation and thus high-current capability.

Unit: mm



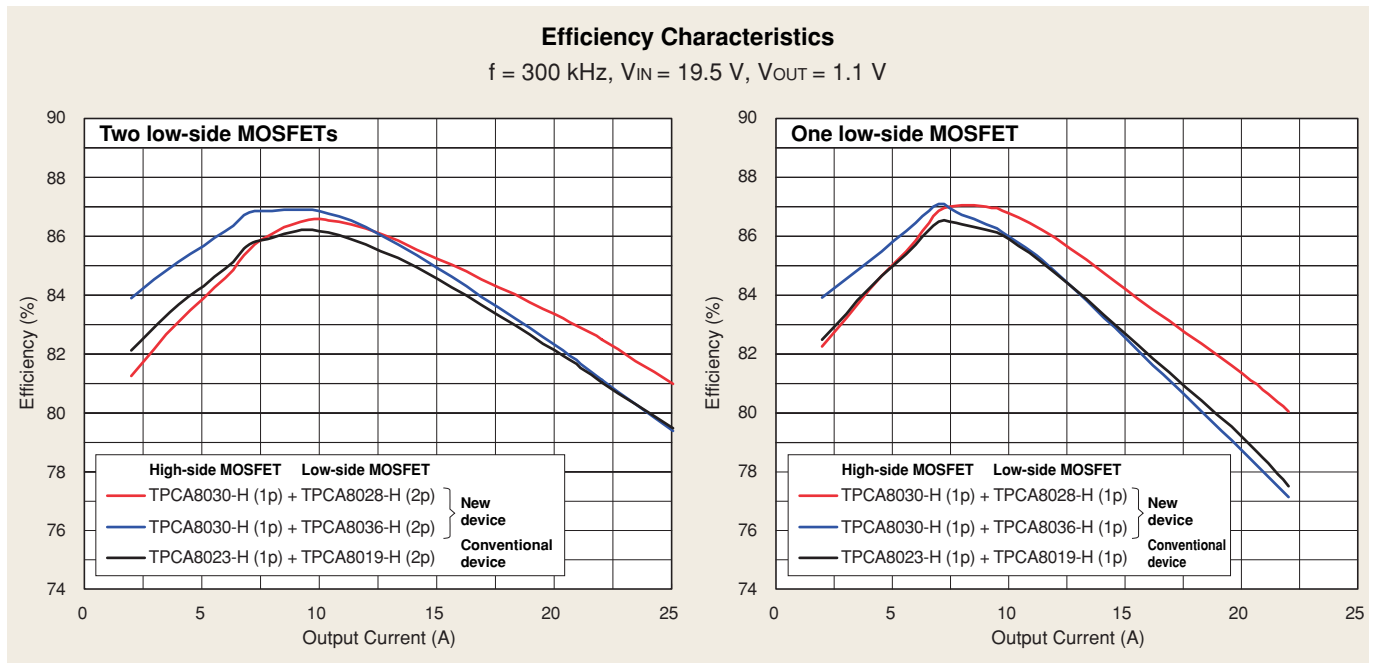
		SOP-8	SOP Advance	Features of the SOP Advance
Footprint Area	(mm <sup>2</sup> )	30	30	Same footprint area as the SOP-8
Total height (max)	(mm)	1.9	1.0	Low profile, Thinner by 0.9 mm
R <sub>th(ch-a)</sub> (t = 10 s) <sup>(Note 1)</sup>	(°C / W)	65.8	44.6	High power dissipation
Current rating	(A)	18	40	High current-carrying capacity
Package resistance <sup>(Note 2)</sup>	(mΩ)	1.6	0.5	Low package resistance

Note 1: When mounted on a glass-epoxy board (25.4 mm x 25.4 mm x 0.8 mm)    Note 2: Without chip resistance

### New Process Technology

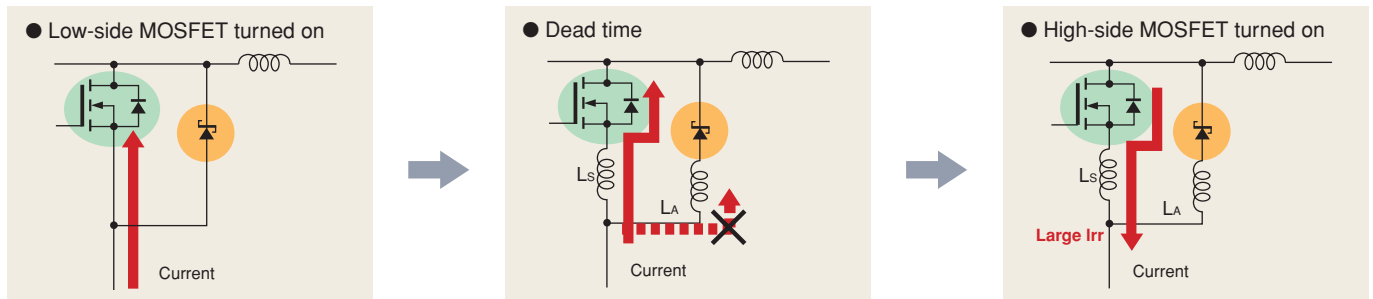
Toshiba has developed a new process technology to further reduce an internal gate resistance ( $r_g$ ) and gate capacitance ratio ( $C_{gd}/C_{gs}$ ) for minimizing the self-turn-on loss while maintaining both the low ON-resistance and low gate charge characteristics.

	R <sub>DS(ON)</sub> Typ. @4.5 V (mΩ)	$r_g$ Typ. (Ω)	C <sub>gd</sub> /C <sub>gs</sub> Typ. (%)
TPCA8028-H (New generation)	2.3	1.0	6.8
TPCA8019-H (One gen. ago)	3.1	1.0	6.6
TPCA8004-H (Two gen. ago)	4.8	2.4	12.7



## Synchronous Rectification DC-DC Converters – MOSBD (MOSFET with SBD)

### External SBD



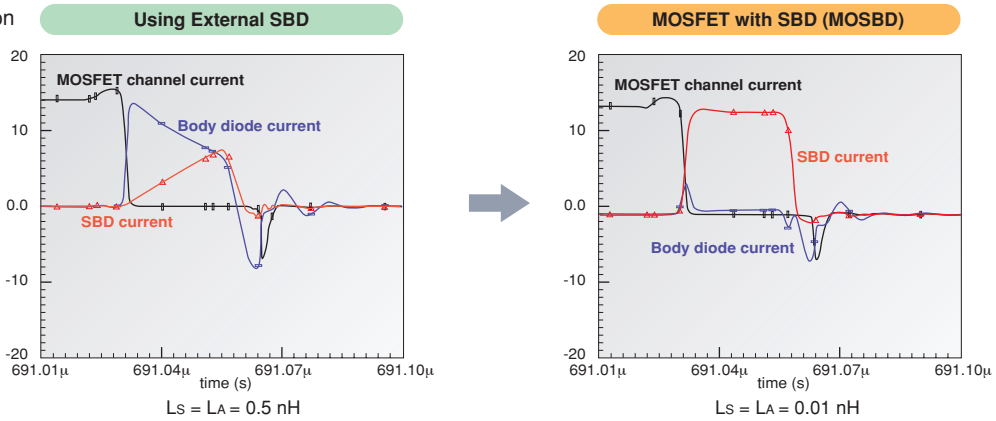
When an SBD is added externally, the SBD can't function fully due to the influence of wire inductances ( $L_s$  and  $L_A$ ); thus a body diode current during the dead time becomes larger and causes the following penalties.

- 1: Increase in the conducting loss of the body diode.
- 2: Increase in the reverse recovery loss due to high  $di/dt$ .
- 3: Induces a self-turn-on phenomenon.

### MOSFET with SBD (MOSBD)

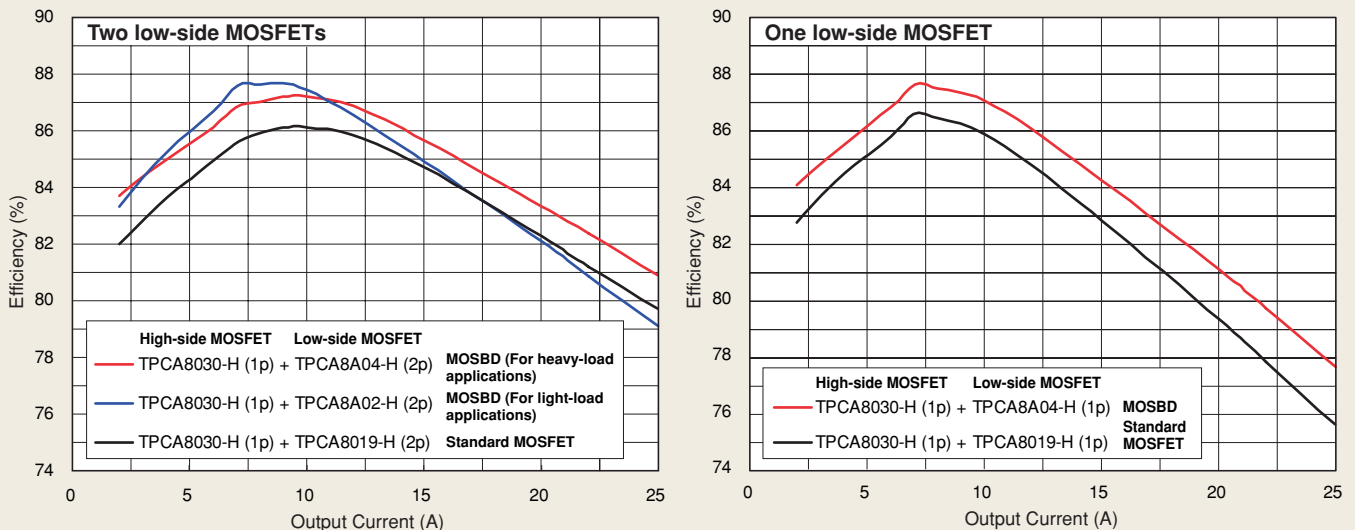
A MOSFET with SBD using a monolithic structure reduces a wire inductance ( $L_A$ ) and a parasitic inductance ( $L_s$ ). This structure makes it possible for the SBD to function fully and to reduce losses.

#### Current Waveform Simulation



### Efficiency Characteristics

$f = 300 \text{ kHz}$ ,  $V_{IN} = 19.5 \text{ V}$ ,  $V_{OUT} = 1.1 \text{ V}$





## High-Speed MOSFET Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	Package	R <sub>DS(ON)</sub> Max (mΩ)		Q <sub>sw</sub> Typ.(nC) @V <sub>DS</sub> = V <sub>DSS</sub> x 0.8	Series		
	V <sub>DSS</sub> (V)	V <sub>GSS</sub> (V)	I <sub>D</sub> (A)			4.5 V	10 V				
TPCA8011-H	20	±12	40	N-ch Single	SOP Advance	3.5	7.5*	16	U-MOSIII-H		
TPC6007-H	30	±20	5		VS-6	79	54	1.8	U-MOSIII-H		
TPC6109-H	-30		-5	P-ch Single	SOP-8	83	59	4.8	U-MOSIII-H		
TPC8216-H	30	6.4	N-ch Dual	23.0		20	3.4	U-MOSVI-H			
TPCP8005-H ☆		11	N-ch Single	PS-8	15.7	12.9	5.0	U-MOSV-H			
TPCC8001-H ☆		22		TSON Advance	10.2	6.9	7.1	U-MOSV-H			
TPCC8003-H ☆		13			19.3	16.9	4.2	U-MOSIV-H			
TPCC8002-H ☆		22			10.2	6.9	7.1	U-MOSV-H			
TPCC8006-H ☆		24			8.6	6.9	7.4	U-MOSIV-H			
TPCC8005-H ☆		26			7.3	6.0	9.1	U-MOSIV-H			
TPCM8003-H		21			TSSOP Advance	15.7	12.9	5.0	U-MOSV-H		
TPCM8004-H		24				13.4	11	5	U-MOSV-H		
TPCM8002-H		30				8.2	6.2	9.3	U-MOSV-H		
TPC8021-H		11				SOP-8	25	17	3.6	U-MOSIII-H	
TPC8031-H		11					16.1	13.3	5.0	U-MOSV-H	
TPC8037-H		12					13.9	11.4	5	U-MOSV-H	
TPC8038-H **		12					13.9	11.4	5	U-MOSV-H	
TPC8032-H		15					8.6	6.5	8.4	U-MOSV-H	
TPC8033-H		17					7.2	5.3	9.6	U-MOSV-H	
TPC8039-H		17					6.9	6.0	8.5	U-MOSVI-H	
TPC8034-H		18					4.5	3.5	16	U-MOSV-H	
TPC8036-H		18					5.1	4.5	13	U-MOSVI-H	
TPC8035-H		18					3.6	3.2	17	U-MOSVI-H	
TPCA8023-H		21					SOP Advance	15.7	12.9	5.0	U-MOSV-H
TPCA8030-H		24						13.4	11.0	5	U-MOSV-H
TPCA8031-H **		24						13.4	11.0	5	U-MOSV-H
TPCA8018-H		30						8.2	6.2	9.3	U-MOSV-H
TPCA8039-H		34						6.6	5.7	8.6	U-MOSVI-H
TPCA8036-H		38						4.8	4.2	13	U-MOSVI-H
TPCA8012-H	40	6.8						4.9	11.0	U-MOSV-H	
TPCA8060-H ☆	45	3.9	3.4					17	U-MOSIV-H		
TPCA8019-H	45	4.1	3.1	15.5				U-MOSV-H			
TPCA8028-H	50	3.2	2.8	20				U-MOSVI-H			
TPC6006-H	40	3.9	N-ch Single	VS-6				100	75	1.3	U-MOSIII-H
TPC8022-H		7.5		SOP-8				35	27	3.5	U-MOSIII-H
TPC8052-H ☆		(12)						(14.0)	(12.1)	TBD	U-MOSIV-H
TPC8047-H ☆		(16)			(8.8)			(7.6)	(13)	U-MOSIV-H	
TPC8046-H ☆		(18)			(6.6)			(5.7)	(15)	U-MOSIV-H	
TPC8045-H ☆		(18)			(4.4)			(3.9)	(23)	U-MOSIV-H	
TPCA8020-H		7.5			35	27		3.5	U-MOSIII-H		
TPCA8052-H ☆		(20)			(13.7)	(11.8)		TBD	U-MOSIV-H		
TPCA8014-H		30			14	9		7.4	U-MOSIII-H		
TPCA8027-H		30			—	10		8.1	U-MOSIII-H		
TPCA8047-H ☆		(32)			(8.5)	(7.3)		(13)	U-MOSIV-H		
TPCA8015-H		35			7.9	5.4		13	U-MOSIII-H		
TPCA8046-H ☆		(38)			(6.3)	(5.4)		(15)	U-MOSIV-H		
TPCA8045-H ☆		(46)			(4.1)	(3.6)		(23)	U-MOSIV-H		

\*: V<sub>GS</sub> = 2.5 V \*\*: r<sub>g</sub> = 3.4 Ω (Typ.)

☆: Under development

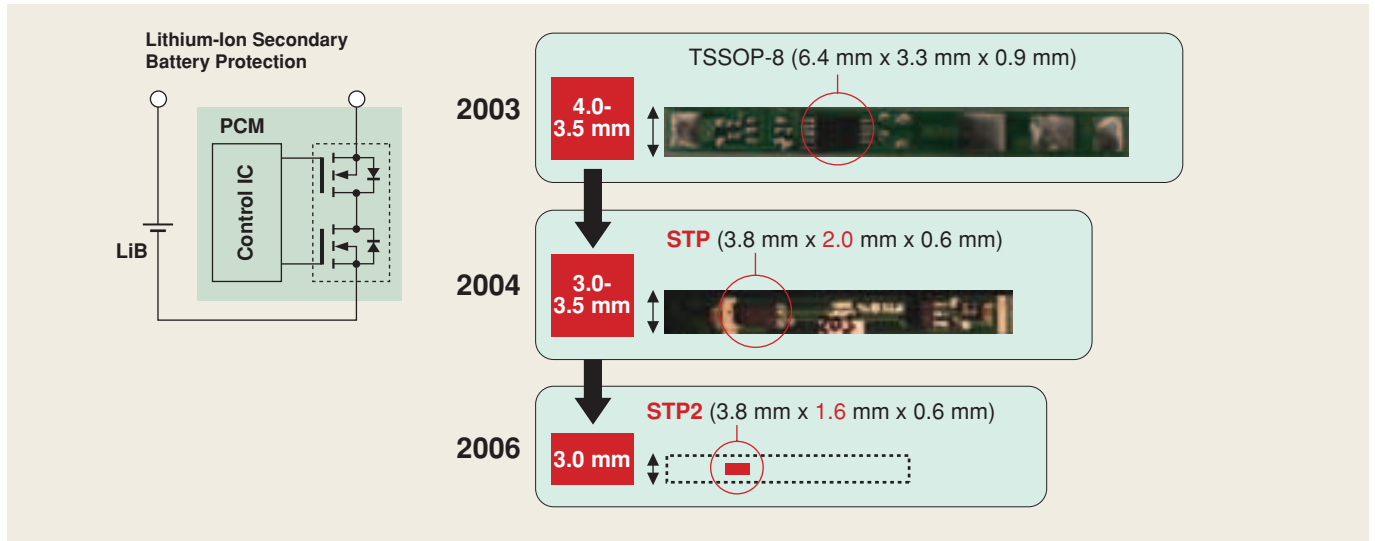
Part Number	Absolute Maximum Ratings			Circuit Configuration	Package	R <sub>ds(ON)</sub> Max (mΩ)		Q <sub>sw</sub> Typ.(nC) @V <sub>DS</sub> = V <sub>DS</sub> x 0.8	Series		
	V <sub>DS</sub> (V)	V <sub>GSS</sub> (V)	I <sub>D</sub> (A)			4.5 V	10 V				
TPC8213-H	60	±20	5	N-ch Dual	SOP-8	56	50	2.9	U-MOSIII-H		
TPC8053-H ☆			(9)	N-ch Single		SOP-8	(24.8)	(23.2)	(6.6)	U-MOSIV-H	
TPC8050-H ☆			(11)				SOP Advance	(15.6)	(14.5)	(10)	U-MOSIV-H
TPC8049-H ☆			(13)					(11.5)	(10.7)	(13)	U-MOSIV-H
TPC8048-H ☆			(16)					(7.4)	(6.9)	(19)	U-MOSIV-H
TPCA8053-H ☆			(15)		(24.5)			(22.9)	(6.6)	U-MOSIV-H	
TPCA8050-H ☆			(24)		(15.3)	(14.2)		(10)	U-MOSIV-H		
TPCA8016-H			25		26	21	6.6	U-MOSIII-H			
TPCA8049-H ☆			(28)		(11.2)	(10.4)	(13)	U-MOSIV-H			
TPCA8048-H ☆			(35)		(7.1)	(6.6)	(19)	U-MOSIV-H			
TPC8051-H ☆	80	±20	(13)		SOP-8	(10.1)	(9.7)	(18)	U-MOSIV-H		
TPCA8051-H ☆			(28)	SOP Advance	(9.8)	(9.4)	(18)	U-MOSIV-H			
TPCP8003-H	100	±20	2.2	PS-8	190	180	2.0	U-MOSIII-H			
TPC8214-H			2.2	N-ch Dual	SOP-8	190	180	2.0	U-MOSIII-H		
TPCA8022-H	150	±20	22	SOP Advance	—	26	14	U-MOSIII-H			
TPCS8009-H			2.1	N-ch Single	TSSOP-8	—	350	3.3	π-MOSV		
TPCA8009-H	7	SOP Advance	—		350	3.7	π-MOSV				
TPCS8007-H	200	1.9	TSSOP-8		—	450	3.3	π-MOSV			
TPCA8010-H		5.5	SOP Advance		—	450	3.7	π-MOSV			
TPCS8008-H	250	1.7	TSSOP-8		—	580	3.3	π-MOSV			
TPCA8008-H		4	SOP Advance		—	580	3.7	π-MOSV			
TPCP8A05-H ☆	30	±20	8		PS-8	21.9	17.5	3.7	U-MOSV-H		
TPCC8A01-H ☆			21		TSON Advance	12.0	8.3	4.1	U-MOSV-H		
TPCM8A05-H			20		TSSOP Advance	17.2	12.9	3.7	U-MOSV-H		
TPC8A05-H			10		MOSBD	SOP-8	17.6	13.3	3.7	U-MOSV-H	
TPC8A03-H			17	7.0			5.0	8.4	U-MOSV-H		
TPC8A04-H			18	4.5			3.6	13.4	U-MOSV-H		
TPCA8A05-H			20	SOP Advance			17.2	12.9	3.7	U-MOSV-H	
TPCA8A02-H			34				6.7	5.3	8.6	U-MOSV-H	
TPCA8A08-H ☆			38		5.1	3.9	11	U-MOSV-H			
TPCA8A04-H			42		4.1	3.2	13.4	U-MOSV-H			
TPCP8103-H	-40	±20	-4.8		PS-8	54	40	6.5	U-MOSIII-H		
TPC8116-H			-7.5	P-ch Single	SOP-8	37	30	9.7	U-MOSIII-H		
TPCA8107-H			-7.5	SOP Advance	37	30	9.7	U-MOSIII-H			
TPC8406-H	40	±20	6.5	N-ch/P-ch Dual	SOP-8	35	27	3.5	U-MOSIII-H		
	-40		-6.5			37	30	9.7	U-MOSIII-H		

\*: V<sub>GS</sub> = 2.5 V \*\* : r<sub>g</sub> = 3.4 Ω (Typ.)

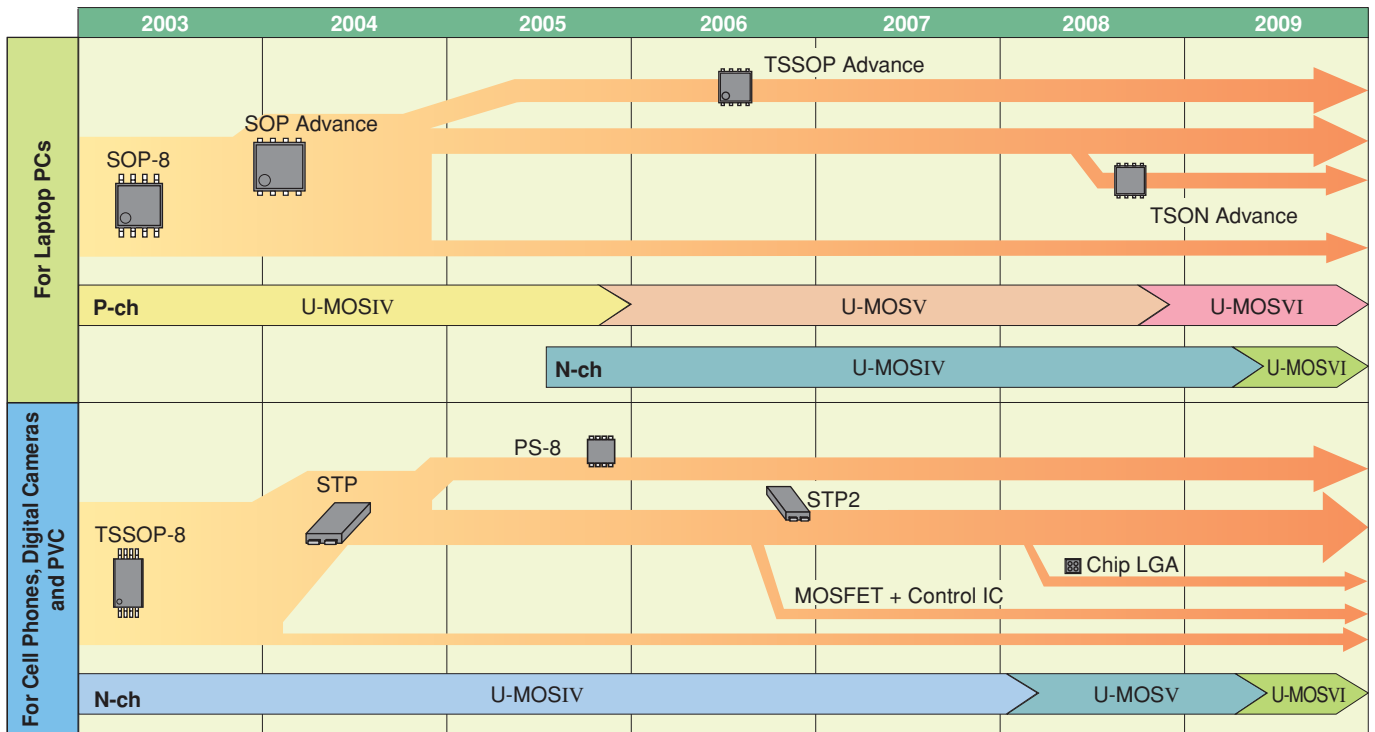
☆ : Under development

## 4-5 Low- $V_{DS}$ , Low- $R_{DS(ON)}$ MOSFETs (for Lithium-Ion Battery Protection)

### Lithium-Ion Battery Protection Circuit Trend



### MOSFET Roadmap



## ● Low-ON-resistance N-Channel Power MOSFETs

Part Number	Absolute Maximum Ratings			Circuit Configuration	Package	R <sub>DS(ON)</sub> Max (mΩ)			Mass Production
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)			2.5 V	4 V	10 V	
TPCT4203 ☆	20	±12	6	N-ch Dual	STP2	49	32	—	Y
TPCT4204 ☆	30	±12	6			52	39	—	Y
TPCL4201 ☆	20	±12	6		Chip LGA	52	31*	—	2009/4
TPCL4203 ☆	24	±12	6			55	36*	—	2009/4
TPCL4202 ☆	30	±12	6			64	40*	—	2009/4
TPCP8202	30	±12	5.5			39	24	—	Y
TPCP8006 ☆	20	±12	9.1	PS-8	13.7	10*	—	Y	
TPCP8004 ☆	30	±20	8.3		—	14*	8.5	Y	
TPCC8007 ☆	20	±12	(27)	TSON Advance	TBD	(5.5*)	—	2009/6	
TPCC8008 ☆	30	±25	(24)		—	TBD	(7)	2009/5	
TPC8014	30	±20	11	N-ch Single	SOP-8	—	22*	14	Y
TPC8025 ☆	30	±20	11			—	14.5*	9	Y
TPC8030 ☆	30	±25	11			—	17*	9	Y
TPC8041 ☆	30	±20	13			—	13.5*	7	Y
TPC8026 ☆	30	±20	13			—	10*	6.6	Y
TPC8028 ☆	30	±20	18			—	8*	4.3	Y
TPC8029 ☆	30	±20	18			—	7*	3.8	Y
TPC8042 ☆	30	±20	18			—	6.5*	3.4	Y
TPC8027 ☆	30	±20	18			—	5.5*	2.7	Y
TPC8208	20	±12	5			70	50	—	Y
TPC8207	20	±12	6			30	20	—	Y
TPC8211	30	±20	5.5			—	44*	36	Y
TPC8210	30	±20	8			—	20*	15	Y
TPCA8024 ☆	30	±20	35			N-ch Single	SOP Advance	—	7.8*
TPCA8025 ☆	30	±20	40	—	6.0*			3.5	Y
TPCA8042 ☆	30	±20	45	—	5.7*			3.3	Y
TPCA8026 ☆	30	±20	45	—	4.5*			2.2	Y

\*: V<sub>Gs</sub> = 4.5 V ☆: No protection Zener diode between gate and source

## ● Low-ON-resistance P-Channel Power MOSFETs

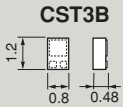

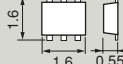
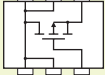
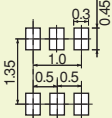
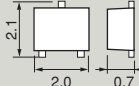
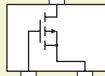
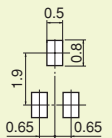
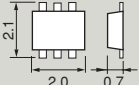
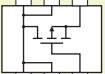
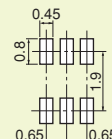
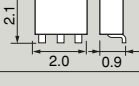
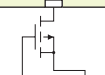
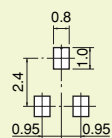
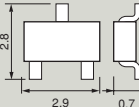
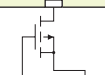
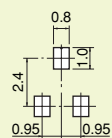
Part Number	Absolute Maximum Ratings			Circuit Configuration	Package	R <sub>DS(ON)</sub> Max (mΩ)			Mass Production	
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)			2.5 V	4 V	10 V		
TPCC8102 ☆	-30	±20	(-15)	P-ch Single	TSON Advance	—	(34)	(18.5)	Y	
TPCC8103 ☆	-30	±20	(-18)			—	(24)	(13)	2009/5	
TPC8115	-20	±8	-10		SOP-8	14	10*	—	Y	
TPC8109	-30	±20	-10			—	30	20	Y	
TPC8119 ☆	-30	±20	-10			—	28	13	Y	
TPC8121 ☆	-30	±20	-11			—	24	12	Y	
TPC8111	-30	±20	-11			—	18	12	Y	
TPC8113	-30	±20	-11			—	18	10	Y	
TPC8123 ☆	-30	-25/+20	-11			—	12.5*	9	Y	
TPC8122 ☆	-30	±20	-12			—	16.5	8	Y	
TPC8107	-30	±20	-13			—	15	7	Y	
TPC8118 ☆	-30	±20	-13			—	15	7	Y	
TPC8112	-30	±20	-13			—	14	6	Y	
TPC8114	-30	±20	-18			—	6.8	4.5	Y	
TPC8117 ☆	-30	±20	-18			—	7.9	3.9	Y	
TPC8120 ☆	-30	-25/+20	-18			—	4.2*	3.2	2009/6	
TPC8405	30	±20	6			N-ch/P-ch Dual	—	33*	26	Y
	-30	±20	-4.5				—	42*	33	
TPCM8102 ☆	-30	±20	-25	P-ch Single	TSSOP Advance	—	16	7.7	Y	
TPCA8105	-12	±8	-6		SOP Advance	51	33	—	Y	
TPCA8102	-30	±20	-40			—	14	6	Y	
TPCA8103	-30	±20	-40			—	6.8	4.2	Y	
TPCA8106 ☆	-30	±20	-40			—	7.8	3.7	Y	

\*: V<sub>Gs</sub> = 4.5 V ☆: No protection Zener diode between gate and source

## 4-6 Semi-Power MOSFET Offerings

### Semi-Power P-Channel Single MOSFETs

Unit: mm

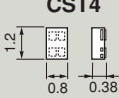

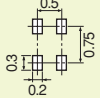
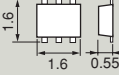
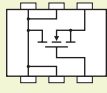
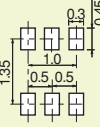
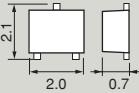
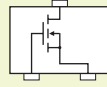
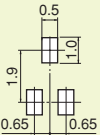
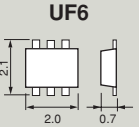
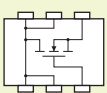
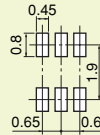
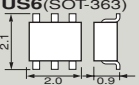
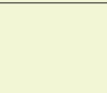

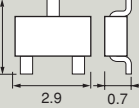
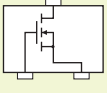
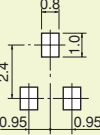
Package	Part Number	$V_{DSS}$ (V)	$V_{GS}$ (V)	$I_b$ (A)	$R_{DS(ON)}$ Max ( $m\Omega$ )				$C_{iss}$ (pF)	Series	*Internal Connections	Land Pattern Example
					$V_{GS} =  1.5V $	$V_{GS} =  1.8V $	$V_{GS} =  2.5V $	$V_{GS} =  4.0V $				
<b>CST3B</b> 	SSM3J46CTB	-20	$\pm 8$	-2.0	250	178	133	103 (@4.5V)	290	U-MOSVI	 TOP VIEW	—
<b>ES6 (SOT-563)</b> 	SSM6J53FE	-20	$\pm 8$	-1.8	364	204	136	—	568	U-MOSIV		
	SSM6J206FE	-20	$\pm 8$	-2.0	—	320	186	130	335	U-MOSIII		
	SSM6J205FE	-20	$\pm 8$	-0.8	—	460	306	234	250	U-MOSIII		
	SSM6J26FE	-20	$\pm 8$	-0.5	—	980	330	230	250	U-MOSIII		
	SSM6J23FE	-12	$\pm 8$	-1.2	—	—	210	160	420	U-MOSIII		
	SSM6J25FE	-20	$\pm 12$	-0.5	—	—	430	260	218	U-MOSIII		
	SSM6J207FE	-30	$\pm 20$	-1.4	—	—	—	491	137	U-MOSII		
<b>UFM</b> 	SSM3J130TU	-20	$\pm 8$	-4.4	63.2	41.1	31	25.8(@4.5V)	1800	U-MOSVI		
	SSM3J120TU	-20	$\pm 8$	-4.0	140	78	49	38	1484	U-MOSIV		
	SSM3J129TU	-20	$\pm 8$	-4.6	140	88	62	46(@4.5V)	640	U-MOSV		
	SSM3J115TU	-20	$\pm 8$	-2.2	353	193	125	98	568	U-MOSIV		
	SSM3J110TU	-12	$\pm 8$	-2.3	—	240	145	94	550	U-MOSIII		
	SSM3J109TU	-20	$\pm 8$	-2.0	—	300	172	130	335	U-MOSIII		
	SSM3J114TU	-20	$\pm 8$	-1.8	526	321	199	149	331	U-MOSIV		
	SSM3J108TU	-20	$\pm 8$	-1.8	—	363	230	158	250	U-MOSIII		
	SSM3J113TU	-20	$\pm 12$	-1.7	—	—	249	169	370	U-MOSIII		
	SSM3J111TU	-20	$\pm 12$	-1.0	—	—	680	480	160	U-MOSIII		
	SSM3J117TU	-30	$\pm 20$	-2.0	—	—	—	225	280	U-MOSII		
	SSM3J118TU	-30	$\pm 20$	-1.4	—	—	—	480	137	U-MOSII		
SSM3J112TU	-30	$\pm 20$	-1.1	—	—	—	790	86	U-MOSII			
<b>UF6</b> 	SSM6J409TU	-20	$\pm 8$	-6.7	72.3	46.3	30.2	22.1(@4.5V)	1100	U-MOSV		
	SSM6J51TU	-12	$\pm 8$	-4.0	150	85	54	—	1700	U-MOSIV		
	SSM6J50TU	-20	$\pm 10$	-2.5	—	205(@2.0V)	100	64(@4.5V)	800	U-MOSIV		
	SSM6J21TU	-12	$\pm 12$	-3.0	—	—	88	50	1300	U-MOSIII		
	SSM6J401TU	-30	$\pm 20$	-2.5	—	—	—	145	730	U-MOSIII		
	SSM6J402TU	-30	$\pm 20$	-2.0	—	—	—	225	280	U-MOSIII		
<b>US6(SOT-363)</b> 	SSM6J08FU	-20	$\pm 12$	-1.3	—	460(@2.0V)	260	180	370	U-MOSII		
	SSM6J06FU	-20	$\pm 12$	-0.65	—	—	700	500	160	$\pi$ -MOSVI		
	SSM6J07FU	-30	$\pm 20$	-0.8	—	—	—	800	130	$\pi$ -MOSVI		
<b>TSM</b> 	SSM3J307T	-20	$\pm 8$	-5.0	83	56	40	31(@4.5V)	1170	U-MOSV		
	SSM3J321T	-20	$\pm 8$	-5.2	137	88	62	46(@4.5V)	640	U-MOSV		
	SSM3J13T	-12	$\pm 8$	-3.0	—	180(@2.0V)	95	70	890	U-MOSIII		
	SSM3J312T	-12	$\pm 8$	-2.7	—	237	142	91	550	U-MOSIII		
	SSM3J304T	-20	$\pm 8$	-2.3	—	297	169	127	335	U-MOSIII		
	SSM3J317T	-20	$\pm 8$	-3.6	—	306	144	107(@4.5V)	390	U-MOSIII		
	SSM3J313T	-20	$\pm 8$	-1.6	—	640	396	268	170	U-MOSIII		
	SSM3J01T	-30	$\pm 10$	-1.7	—	—	600	400	240	$\pi$ -MOSVI		
	SSM3J02T	-30	$\pm 10$	-1.5	—	—	700	500	150	$\pi$ -MOSVI		
	SSM3J314T	-30	$\pm 20$	-3.5	—	—	—	100	505	U-MOSIII-H		
	SSM3J14T	-30	$\pm 20$	-2.7	—	—	—	170	413	U-MOSII		
	SSM3J306T	-30	$\pm 20$	-2.4	—	—	—	225	280	U-MOSII		
	SSM3J305T	-30	$\pm 20$	-1.7	—	—	—	477	137	U-MOSII		

\* The internal connection diagrams only show the general configurations of the circuits.



# Semi-Power N-Channel Single MOSFETs

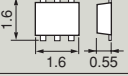
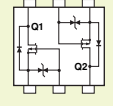
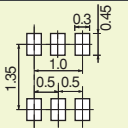
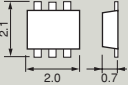
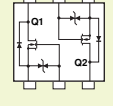
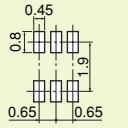
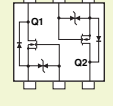
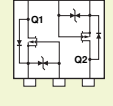
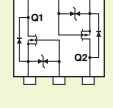
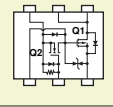
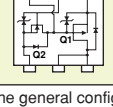
Unit: mm

Package	Part Number	V <sub>DSS</sub> (V)	V <sub>GSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max (mΩ)				C <sub>iss</sub> (pF)	Series	*Internal Connections	Land Pattern Example
					V <sub>GS</sub> =   1.5 V	V <sub>GS</sub> =   1.8 V	V <sub>GS</sub> =   2.5 V	V <sub>GS</sub> =   4.0 V				
<b>CST4</b> 	SSM4K27CT	20	±12	0.5	—	390	260	205	174	U-MOSIII	 TOP VIEW	
<b>ES6 (SOT-563)</b> 	SSM6K211FE	20	±10	3.2	118	82	59	47(@4.5 V)	510	U-MOSIII		
	SSM6K203FE	20	±10	2.8	153	106	76	61	400	U-MOSIII		
	SSM6K202FE	30	±12	2.3	—	145	101	85	270	U-MOSIII		
	SSM6K204FE	20	±10	2.0	307	214	164	126	195	U-MOSIII		
	SSM6K208FE	30	±12	1.9	—	296	177	133	123	U-MOSIII		
	SSM6K25FE	20	±12	0.5	—	395	190	145	268	U-MOSIII		
	SSM6K24FE	30	±12	0.5	—	—	180	145	245	U-MOSIII		
	SSM6K22FE	20	±12	1.4	—	—	230	170	125	U-MOSIII		
	SSM6K210FE	30	±20	1.4	—	—	—	371	57	U-MOSIII		
	SSM6K30FE	20	±20	1.2	—	—	—	420	60	π-MOSVII		
	SSM6K31FE	20	±20	1.2	—	—	—	540	36	π-MOSVII		
<b>UFM</b> 	SSM3K123TU	20	±10	4.2	66	43	32	28	1010	U-MOSIII		
	SSM3K121TU	20	±10	3.2	140	93	63	48	400	U-MOSIII		
	SSM3K104TU	20	±12	3.0	—	110	74	56	320	U-MOSIII		
	SSM3K119TU	30	±12	2.5	—	134	90	74	270	U-MOSIII		
	SSM3K102TU	20	±12	2.6	—	154	99	71	268	U-MOSIII		
	SSM3K122TU	20	±10	2.0	304	211	161	123	195	U-MOSIII		
	SSM3K101TU	20	±12	2.2	—	230	138	103	125	U-MOSIII		
	SSM3K127TU	30	±12	2.0	—	286	167	123	123	U-MOSIII		
	SSM3K116TU	30	±12	2.2	—	—	135	100	245	U-MOSIII		
	SSM3K131TU	30	±20	5.4	—	—	—	41.5(@4.5 V)	450	U-MOSIV		
	SSM3K124TU	30	±20	2.4	—	—	—	120	180	π-MOSVII		
	SSM3K105TU	30	±20	2.1	—	—	—	200	102	π-MOSVI		
	SSM3K128TU	30	±20	1.5	—	—	—	360	57	U-MOSIII		
	SSM3K107TU	20	±20	1.5	—	—	—	410	60	π-MOSVII		
SSM3K106TU	20	±20	1.2	—	—	—	530	36	π-MOSVII			
<b>UF6</b> 	SSM6K403TU	20	±10	4.2	66	43	32	28	1050	U-MOSIII		
	SSM6K404TU	20	±10	3.0	147	100	70	55	400	U-MOSIII		
	SSM6K405TU	20	±10	2.0	307	214	164	126	195	U-MOSIII		
	SSM6K18TU	20	±12	4.0	—	—	54	40	1100	U-MOSIII		
	SSM6K406TU	30	±20	4.4	—	—	—	38.5(@4.5 V)	490	U-MOSIV		
	SSM6K34TU	30	±20	3.0	—	—	—	77(@4.5 V)	470	U-MOSIII		
	SSM6K407TU	60	±20	2.0	—	—	—	440	150	π-MOSV		
	SSM6K32TU	60	±20	2.0	—	—	—	440	140	π-MOSV		
<b>US6(SOT-363)</b> 	SSM6K08FU	20	±12	1.6	—	210(@2.0 V)	140	105	306	U-MOSII		
	SSM6K06FU	20	±12	1.1	—	—	210	160	125	π-MOSVI		
	SSM6K07FU	30	±20	1.5	—	—	—	220	102	π-MOSVI		
	SSM3K310T	20	±10	5.0	66	43	32	28	1120	U-MOSIII		
<b>TSM</b> 	SSM3K309T	20	±12	4.7	—	47	35	31	1020	U-MOSIII		
	SSM3K301T	20	±12	3.5	—	110	74	56	320	U-MOSIII		
	SSM3K316T	30	±12	4.0	—	131	87	65(@4.5 V)	270	U-MOSIII		
	SSM3K302T	30	±12	3.0	—	131	87	71	270	U-MOSIII		
	SSM3K01T	30	±10	3.2	—	—	150	120	152	π-MOSVI		
	SSM3K02T	30	±10	2.5	—	—	250	200	115	π-MOSVI		
	SSM3K315T	30	±20	6.0	—	—	—	41.5(@4.5 V)	450	U-MOSIV		
	SSM3K14T	30	±20	4.0	—	—	—	67	460	U-MOSII		
	SSM3K320T	30	±20	4.2	—	—	—	77(@4.5 V)	190	U-MOSIV		
	SSM3K303T	30	±20	2.9	—	—	—	120	180	π-MOSVII		
	SSM3K12T	30	±20	3.0	—	—	—	175	120	π-MOSVII		
	SSM3K318T	60	±20	2.5	—	—	—	145	235	U-MOSIV		

\* The internal connection diagrams only show the general configurations of the circuits.

## ● Semi-Power Dual MOSFETs

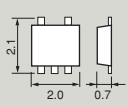
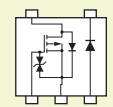
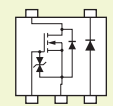
Unit: mm

Package	Polarity	Part Number	$V_{DSS}$ (V)	$V_{GS}$ (V)	$I_D$ (A)	$R_{DS(ON)}$ Max (m $\Omega$ )				$C_{iss}$ (pF)	Series	*Internal Connections	Land Pattern Example	
						$V_{GS} = 1.5V$	$V_{GS} = 1.8V$	$V_{GS} = 2.5V$	$V_{GS} = 4.0V$					
<b>ES6 (SOT-563)</b> 	P-ch x 2	<b>SSM6P41FE</b>	-20	$\pm 8$	-0.72	1040	670	440	300 (@4.5V)	110	U-MOSV			
		<div style="display: flex; justify-content: space-between;"> <div style="width: 30%;"> <b>UF6</b>   </div> <div style="width: 30%; text-align: center;">  </div> <div style="width: 30%; text-align: center;">  </div> </div>												
	N-ch x 2	<b>SSM6N39TU</b>	20	$\pm 10$	1.6	247	190	139	119	260	U-MOSIII			
		<b>SSM6N29TU</b>	20	$\pm 12$	0.8	—	235	178	143	268	U-MOSIII			
		<b>SSM6N25TU</b>	20	$\pm 12$	0.5	—	395	190	145	268	U-MOSIII			
		<b>SSM6N24TU</b>	30	$\pm 12$	0.5	—	—	180	145	245	U-MOSIII			
		<b>SSM6N40TU</b>	30	$\pm 20$	1.6	—	—	—	182	180	U-MOSIII			
	P-ch x 2	<b>SSM6P54TU</b>	-20	$\pm 8$	-1.2	555	350	228	—	331	U-MOSIV			
		<b>SSM6P39TU</b>	-20	$\pm 8$	-1.5	—	430	294	213	250	U-MOSIII			
		<b>SSM6P28TU</b>	-20	$\pm 8$	-0.8	—	460	306	234	250	U-MOSIII			
		<b>SSM6P26TU</b>	-20	$\pm 8$	-0.5	—	980	330	230	250	U-MOSIII			
		<b>SSM6P25TU</b>	-20	$\pm 12$	-0.5	—	—	430	260	218	U-MOSIII			
		<b>SSM6P40TU</b>	-30	$\pm 20$	-1.4	—	—	—	403	120	U-MOSIII			
	N-ch + P-ch		<b>SSM6L39TU</b>	20	$\pm 10$	1.6	247	190	139	119	260	U-MOSIII		
			<b>SSM6L13TU</b>	20	$\pm 12$	0.8	—	235	178	143	268	U-MOSIII		
			<b>SSM6L10TU</b>	20	$\pm 12$	0.5	—	395	190	145	268	U-MOSIII		
			<b>SSM6L11TU</b>	20	$\pm 12$	0.5	—	395	190	145	268	U-MOSIII		
			<b>SSM6L12TU</b>	30	$\pm 12$	0.5	—	—	180	145	245	U-MOSIII		
			<b>SSM6L12TU</b>	-20	$\pm 12$	-0.5	—	—	430	260	218	U-MOSIII		
			<b>SSM6L40TU</b>	30	$\pm 20$	1.6	—	—	—	182	180	U-MOSIII		
			<b>SSM6L40TU</b>	-30	$\pm 20$	-1.4	—	—	—	403	120	U-MOSIII		
	N-ch + P-ch (Load Switch)		<b>SSM6E02TU</b>	-20	$\pm 8$	-1.8	364	204	136	—	568	U-MOSIV		
<b>SSM6E03TU</b>			20	$\pm 10$	0.1	15 $\Omega$	—	4 $\Omega$	3 $\Omega$	9.3	$\pi$ -MOSVI			
<b>SSM6E03TU</b>			-20	$\pm 8$	-1.8	—	335	180	144	335	U-MOSIII			
<b>SSM6E03TU</b>			20	$\pm 10$	0.1	15 $\Omega$	—	4 $\Omega$	3 $\Omega$	9.3	$\pi$ -MOSVI			
		<b>SSM6E01TU</b>	-12	$\pm 12$	-1.0	—	—	240	160	310	U-MOSIII			
		<b>SSM6E01TU</b>	20	10	0.05	—	—	10 $\Omega$	—	11	$\pi$ -MOSVI			

\* The internal connection diagrams only show the general configurations of the circuits.

## ● MOSFET with a Schottky Barrier Diode

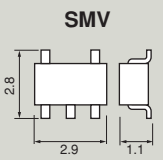
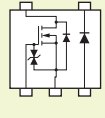
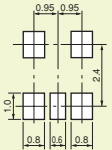
Unit: mm

Package	Polarity	Part Number	MOSFET							SBD				*Internal Connections	Land Pattern Example	
			$V_{DSS}$ (V)	$V_{GS}$ (V)	$I_D$ (A)	$R_{DS(ON)}$ Max (m $\Omega$ )				$C_{iss}$ (pF)	Series	$V_R$ (V)	$I_O$ (A)			$V_F$ Max (V) @ $I_F$ (A)
						$V_{GS} = 1.5V$	$V_{GS} = 1.8V$	$V_{GS} = 2.5V$	$V_{GS} = 4.0V$							
<b>UFV</b> 	P-ch+ SBD	<b>SSM5G09TU</b>	-12	$\pm 8$	-1.5	—	—	200	130	550	U-MOSII	12	0.5	0.43	0.5	
		<b>SSM5G02TU</b>	-12	$\pm 12$	-1.0	—	—	240	160	310	U-MOSII	12	0.5	0.43	0.5	
		<b>SSM5G10TU</b>	-20	$\pm 8$	-1.5	—	430	294	213	250	U-MOSIII	20	0.7	0.39	0.5	
		<b>SSM5G04TU</b>	-12	$\pm 12$	-1.0	—	—	420	240	170	U-MOSII	12	0.5	0.43	0.5	
		<b>SSM5G11TU</b>	-30	$\pm 20$	-1.4	—	—	—	403	120	U-MOSIII-H	30	0.7	0.41	0.5	
	N-ch+ SBD	<b>SSM5G01TU</b>	-30	$\pm 20$	-1.0	—	—	—	800	86	U-MOSII	20	0.5	0.45	0.3	
		<b>SSM5H10TU</b>	20	$\pm 10$	1.6	247	190	139	119	260	U-MOSIII	20	0.7	0.39	0.5	
		<b>SSM5H12TU</b>	30	$\pm 12$	1.9	—	296	177	133	123	U-MOSIII	30	0.7	0.41	0.5	
		<b>SSM5H05TU</b>	20	$\pm 12$	1.5	—	—	220	160	125	U-MOSIII	12	0.5	0.43	0.5	
		<b>SSM5H08TU</b>	20	$\pm 12$	1.5	—	—	220	160	125	U-MOSIII	20	0.5	0.45	0.3	
		<b>SSM5H03TU</b>	12	$\pm 12$	1.4	—	—	—	300	125	U-MOSIII	12	0.5	0.43	0.5	
		<b>SSM5H11TU</b>	30	$\pm 20$	1.6	—	—	—	182	180	U-MOSIII	30	0.7	0.41	0.5	
		<b>SSM5H01TU</b>	30	$\pm 20$	1.4	—	—	—	450	106	U-MOSII	20	0.5	0.45	0.3	
		<b>SSM5H07TU</b>	20	$\pm 20$	1.2	—	—	—	540	36	$\pi$ -MOSVII	12	0.5	0.43	0.5	

\* The internal connection diagrams only show the general configurations of the circuits.

## MOSFET with a Schottky Barrier Diode

Unit: mm

Package	Polarity	Part Number	MOSFET								SBD				*Internal Connections	Land Pattern Example	
			V <sub>DSS</sub> (V)	V <sub>GSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max (mΩ)				C <sub>iss</sub> (pF)	Series	V <sub>R</sub> (V)	I <sub>O</sub> (A)	V <sub>F</sub> Max (V)			
						V <sub>GS</sub> = 11.5V	V <sub>GS</sub> = 11.8V	V <sub>GS</sub> = 12.5V	V <sub>GS</sub> = 14.0V					@I <sub>F</sub> (A)			
<b>SMV</b> 	N-ch+ SBD	<b>SSM5H14F</b>	30	±12	3.0	—	138	94	78	270	U-MOSIII	45	0.1	0.6	0.1	 	

\* The internal connection diagrams only show the general configurations of the circuits.

## VS-6 Series ... [Part Number: TPC6xxx]

### Features

- Zener diode between gate and source for all products
- Thin package, with a board mounting height as low as 0.85 mm (max)

### Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	R <sub>DS(ON)</sub> Max (mΩ)					Q <sub>g</sub> Typ. (nC)	C <sub>iss</sub> Typ. (pF)	Marking	Series
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)		10 V	4.5 V	2.5 V	2.0 V	1.8 V				
<b>TPC6004</b>	20	±12	6	N-ch Single	—	24	32	37	—	17	1400	S2C	U-MOSIII
<b>TPC6011</b> ☆	30	±20	6		21	32	—	—	—	14	640	S2L	U-MOSIV
<b>TPC6005</b>	30	±12	6		—	28	35	41	—	19	1420	S2E	U-MOSIII
<b>TPC6007-H</b>	30	±20	5		54	79	—	—	—	2.8	240	S2G	U-MOSIII-H
<b>TPC6006-H</b>	40	±20	3.9		75	100	—	—	—	2.4	251	S2F	U-MOSIII-H
<b>TPC6103</b>	-12	±8	-5.5	P-ch Single	—	35	55	—	90	20	1520	S3C	U-MOSIII
<b>TPC6105</b>	-20	±8	-2.7		—	110	160	—	300	6	470	S3E	U-MOSIII
<b>TPC6107</b>	-20	±12	-4.5		—	55	100	180	—	9.8	680	S3G	U-MOSIV
<b>TPC6111</b>	-20	±8	-5.5		—	40	57	—	80	10	700	S3L	U-MOSIV
<b>TPC6108</b>	-30	±20	-4.5		60	100	—	—	—	13	570	S3H	U-MOSIV
<b>TPC6109-H</b>	-30	±20	-5	59	83	—	—	—	7.2	471	S3J	U-MOSIII-H	

☆: No protection Zener diode between gate and source



## VS-8 Series ... [Part Number: TPC8Fxxx]

### Features

- Ultra-low ON-resistance achieved by employing the U-MOS process
- Thin package, with a board mounting height as low as 0.85 mm (max)
- 32% reduction in mounting area compared with the VS-6 (TSOP-6) Series, due to the use of a high-density flat package
- P<sub>D</sub> = 2.5 W @ t = 5 s when the device is mounted on a glass epoxy board

### Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	R <sub>DS(ON)</sub> Max (mΩ)					Q <sub>g</sub> Typ. (nC)	C <sub>iss</sub> Typ. (pF)	Marking	Series
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)		10 V	4.5 V	2.5 V	2.0 V	1.8 V				
<b>TPCF8002</b> ☆	30	±20	6	N-ch Single	23	31	—	—	—	TBD	TBD	F2B	U-MOSIV
<b>TPCF8101</b>	-12	±8	-6	P-ch Single	—	28	40	—	85	18	1600	F3A	U-MOSIII
<b>TPCF8103</b>	-20	±8	-2.7		—	110	160	—	300	6	470	F3C	U-MOSIII
<b>TPCF8102</b>	-20	±8	-6		—	30	41	—	90	19	1550	F3B	U-MOSIII
<b>TPCF8104</b>	-30	±20	-6		28	38	—	—	—	34	1760	F3D	U-MOSIV
<b>TPCF8201</b>	20	±12	3	N-ch Dual	—	49	66	100	—	7.5	590	F4A	U-MOSIII
<b>TPCF8301</b>	-20	±8	-2.7	P-ch Dual	—	110	160	—	300	6	470	F5A	U-MOSIII
<b>TPCF8302</b>	-20	±10	-3		—	59	95	200	—	11	800	F5B	U-MOSIV
<b>TPCF8303</b>	-20	±8	-3		—	58	87	—	250	11	860	F5C	U-MOSIV
<b>TPCF8304</b>	-30	±20	-3.2		72	105	—	—	—	14	600	F5D	U-MOSIV
<b>TPCF8402</b>	30	±20	4	N-ch + P-ch	50	77	—	—	—	10	470	F6B	U-MOSIII
	-30	±20	-3.2		72	105	—	—	—	14	600		U-MOSIV
<b>TPCF8A01</b>	20	±12	3.0	N-ch + SBD	—	49	66	100	—	7.5	590	F7A	U-MOSIII
<b>TPCF8B01</b>	-20	±8	-2.7	P-ch + SBD	—	110	160	—	300	6	470	F8A	U-MOSIII

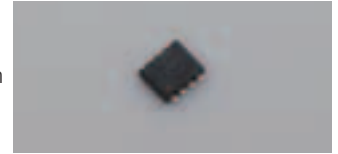
☆: No protection Zener diode between gate and source



## ● PS-8 Series ... [Part Number: TPCP8xxx]

### ■ Features

- Same mounting area as for the VS-6 (TSOP-6) Series
- Using flat leads and the latest U-MOS process (U-MOSIV), the PS-8 Series offers a 70% reduction in  $R_{DS(ON)}$  compared with the VS-6 Series.



### ■ Product Offerings

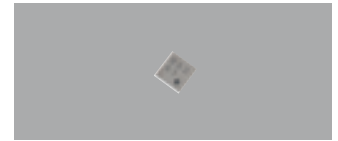
Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (m $\Omega$ )				Series	
	$V_{DSS}$ (V)	$V_{GSS}$	$I_D$ (A)		10 V	4.5 V	2.5 V	1.8 V		
TPCP8006 ☆	20	±12	9.1	N-ch Single	—	10	13.7	—	U-MOSIV	
TPCP8001-H	30	±20	7.2		16	25	—	—	U-MOSIII-H	
TPCP8004 ☆	30	±20	8.3		8.5	14.5	—	—	U-MOSIV	
TPCP8005-H ☆	30	±20	11		12.9	15.7	—	—	U-MOSV-H	
TPCP8A05-H ☆	30	±20	8	MOSBD	12.5	21.9	—	—	U-MOSV-H	
TPCP8003-H ☆	100	±20	2.2	N-ch Single	180	190	—	—	U-MOSIII-H	
TPCP8101	-20	±8	-5.6	P-ch Single	—	30	41	90	U-MOSIII	
TPCP8102	-20	±12	-7.2		—	18	30	—	—	U-MOSIV
TPCP8103-H	-40	±20	-4.8		40	54	—	—	—	U-MOSIII-H
TPCP8201	30	±20	4.2		N-ch Dual	50	77	—	—	U-MOSIII
TPCP8202	30	±12	5.5	P-ch Dual	—	23	39	—	U-MOSIV	
TPCP8203	40	±20	4.7		40	60	—	—	—	U-MOSIII
TPCP8301	-20	±12	-5		—	31	60	—	—	U-MOSIV
TPCP8302	-20	±12	-5		—	33*	45	95	—	U-MOSIV
TPCP8303	-20	±8	-3.8	N-ch/P-ch Load Switch	—	40	57	—	U-MOSV	
TPCP8401	20	±10	0.1		—	3 $\Omega$ *	4 $\Omega$	—	—	$\pi$ -MOSVI
TPCP8402	-12	±8	-5.5		—	38	58	103	—	U-MOSIII
	30	±20	4.2		N-ch + P-ch	50	77	—	—	U-MOSIII
TPCP8404 ☆	-30	±20	-3.4	N-ch + P-ch	72	105	—	—	U-MOSIV	
	30	±20	4		50	100	—	—	U-MOSIII	
TPCP8403	-30	±20	-4	N-ch + P-ch	50	100	—	—	U-MOSIV	
	40	±20	4.7		40	60	—	—	U-MOSIII	
TPCP8BA1	-40	±20	-3.4	MOSBD	70	105	—	—	U-MOSIII	
TPCP8AA1	-20	±12	-1.3		—	180*	260	—	—	U-MOSII
TPCP8J01	20	±12	1.6	P-ch + NPN	—	105*	140	—	—	U-MOSII
	-32	±20	-5.5		35	49*	—	—	—	U-MOSIV
	50	—	0.1		—	—	—	—	U-MOSIV + Bip-Tr	

\*:  $V_{GS} = 4$  V ☆: No protection Zener diode between gate and source

## ● Chip LGA Series

### ■ Features

- Chip-scale package for high-density board assembly (58% reduction in mounting area compared with the STP2 package)



### ■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (m $\Omega$ )			$Q_g$ Typ. (nC)	$C_{iss}$ Typ. (pF)	Series
	$V_{DSS}$ (V)	$V_{GSS}$	$I_D$ (A)		4.5 V	4 V	2.5 V			
TPCL4201 ☆	20	±12	6	N-ch Dual	31	33	52	11.5	720	U-MOSV
TPCL4203 ☆	24	±12	6		36	38	55	TBD	TBD	U-MOSV
TPCL4202 ☆	30	±12	6		40	42	64	TBD	TBD	U-MOSV

☆: No protection Zener diode between gate and source

## ● STP2 Series ... [Part Number: TPCT4xxx]

### ■ Features

- The combination of a new chip design using Toshiba U-MOSIV process technology and a new small pump-structured package, offers low ON-resistance.



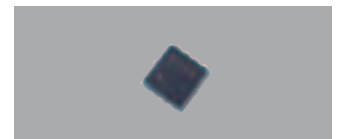
### ■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (m $\Omega$ )			$Q_g$ Typ. (nC)	$C_{iss}$ Typ. (pF)	Series
	$V_{DSS}$ (V)	$V_{GSS}$	$I_S$ (A)		2.5 V	4 V	4.5 V			
TPCT4203	20	±12	6	N-ch Dual	49	32	31	11	790	U-MOSIV
TPCT4204	30	±12	6		52	39	38	12	780	U-MOSIV

## ● TSON Advance Series

### ■ Features

- The small thermally enhanced package gives a 64% reduction in mounting area compared with SOP-8, yet an equivalent maximum permissible power dissipation.



### ■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (m $\Omega$ )			$Q_g$ Typ. (nC)	$C_{iss}$ Typ. (pF)	Series
	$V_{DSS}$ (V)	$V_{GSS}$	$I_D$ (A)		10 V	4.5 V	2.5 V			
TPCC8007 ☆	20	±12	(27)	N-ch Single	—	(5.5)	TBD	TBD	TBD	U-MOSIV
TPCC8008 ☆	30	±25	(24)		(7)	TBD	—	TBD	TBD	U-MOSIV
TPCC8003-H ☆	30	±20	13		16.9	19.3	—	8.6	990	U-MOSIV-H
TPCC8001-H * ☆	30	±20	22		6.9	10.2	—	14.3	1900	U-MOSV-H
TPCC8002-H * ☆ **	30	±20	22		6.9	10.2	—	14.3	1900	U-MOSV-H
TPCC8A01-H * ☆	30	±20	21		MOSBD	8.3	12.0	—	10.1	1430
TPCC8006-H * ☆	30	±20	24	N-ch Single	6.9	8.6	—	15.0	1700	U-MOSIV-H
TPCC8005-H * ☆	30	±20	26		6.0	7.3	—	19.0	2200	U-MOSV-H
TPCC8102 ☆	-30	±20	(-15)	P-ch Single	(18.5)	(34 *)	—	TBD	TBD	U-MOSV
TPCC8103 ☆	-30	±20	(-18)		(13)	(24 *)	—	TBD	TBD	U-MOSV

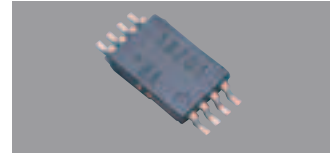
\*:  $V_{GS} = 4$  V \*\*: Al straps \*\*\*:  $rg = 3.2$   $\Omega$  (Typ.) ☆: No protection Zener diode between gate and source

## ● TSSOP-8 Series ... [Part Number: TPCS8xxx]

### ■ Features

- Common-drain types are available:  
Ideal for lithium-ion battery protection and reverse-current prevention

### ■ Product Offerings

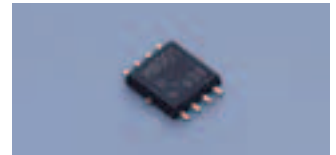


Part Number	Absolute Maximum Ratings			Circuit Configuration	R <sub>DS(ON)</sub> Max (mΩ)				Q <sub>g</sub> Typ. (nC)	C <sub>iss</sub> Typ. (pF)	Series	
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)		10 V	4 V	2.5 V	2.0 V				
TPCS8004	200	±20	1.3	N-ch Single	800	—	—	—	12	380	π-MOSV	
TPCS8009-H	150	±20	2.1		350	—	—	—	10	600	π-MOSV MACHII	
TPCS8007-H	200	±20	1.9		450	—	—	—	10	600	π-MOSV MACHII	
TPCS8008-H	250	±20	1.7		580	—	—	—	10	600	π-MOSV MACHII	
TPCS8104	-30	±20	-11	P-ch Single	12	18	—	—	107	5710	U-MOSIV	
TPCS8105	-30	±20	-10		13.5	19.5	—	—	107	5710	U-MOSIV	
TPCS8209	20	±12	5	N-ch Dual	—	30	40	60	15	1280	U-MOSIII	
TPCS8210 #	20	±12	5		—	30	40	60	15	1280	U-MOSIII	
TPCS8204	20	±12	6		—	17	22	35	22	2160	U-MOSIII	
TPCS8208 #	20	±12	6		—	17	22	35	22	2160	U-MOSIII	
TPCS8211	20	±12	6		—	24	29	45	20	1590	U-MOSIII	
TPCS8212 #	20	±12	6		—	24	29	45	20	1590	U-MOSIII	
TPCS8213 #	20	±12	6		—	13	18	—	49	3140	U-MOSIII	
TPCS8214 #	30	±12	6		—	13.5	18.5	—	42	3240	U-MOSIII	
TPCS8302	-20	±12	-5		P-ch Dual	—	35*	60	95	28.5	1590	U-MOSIII
TPCS8303	-20	±12	-5			—	21*	30	80	33	2560	U-MOSIV

#: Common drain \*: V<sub>GSS</sub> = 4.5 V

## ● TSSOP Advance Series ... [Part Number: TPCM8xxx]

### ■ Product Offerings



Part Number	Absolute Maximum Ratings			Circuit Configuration	R <sub>DS(ON)</sub> Max (mΩ)		Q <sub>g</sub> Typ. (nC)	C <sub>iss</sub> Typ. (pF)	Series
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)		10 V	4.5 V			
TPCM8001-H *	30	±20	20	N-ch Single	9.5	14	19	1130	U-MOSIII-H
TPCM8003-H ☆	30	±20	21		12.9	15.7	11	1433	U-MOSV-H
TPCM8004-H *☆	30	±20	24		11	13.4	11	1433	U-MOSV-H
TPCM8006	30	±20	25		7.0	13.5	26	1270	U-MOSIV
TPCM8002-H *☆	30	±20	30		6.2	8.2	18	2270	U-MOSV-H
TPCM8A05-H *☆	30	±20	20		MOSBD	12.9	17.2	7.4	1300
TPCM8102	-30	±20	-25	P-ch Single	7.7	16*	60	2450	U-MOSV

\*: 4 V \*: Al straps ☆: No protection Zener diode between gate and source

## ● SOP-8 Series ... [Part Number: TPC8xxx]

### ■ Features

- Low ON-resistance and high-speed-switching series are available.  
Low ON-resistance series: U-MOSIV/V/VI  
High-speed-switching series: U-MOSIII-H and U-MOSV-H
- ON-resistance reduction through the use of an Al strap structure

### ■ Product Offerings



Part Number	Absolute Maximum Ratings			Circuit Configuration	R <sub>DS(ON)</sub> Max (mΩ)				Q <sub>g</sub> Typ. (nC)	C <sub>iss</sub> Typ. (pF)	Series
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)		10 V	4.5 V	4 V	2.5 V			
TPC8021-H	30	±20	11	N-ch Single	17	25	—	—	11	640	U-MOSIII-H
TPC8025 ☆	30	±20	11		9	14.5	—	—	26	1270	U-MOSIV
TPC8030 ☆	30	±25	11		8.5	17	—	—	24	1140	U-MOSIV
TPC8037-H *☆	30	±20	12		11.4	13.9	—	—	11	1433	U-MOSV-H
TPC8038-H *☆	30	±20	12		11.4	13.9	—	—	11	1433	U-MOSV-H
TPC8041 *☆	30	±20	13		7	13.5	—	—	27	1270	U-MOSIV
TPC8026 ☆	30	±20	13		6.6	10	—	—	42	1800	U-MOSIV
TPC8032-H *☆	30	±20	15		6.5	8.6	—	—	17	2270	U-MOSV-H
TPC8039-H *☆	30	±20	17		5.7	6.6	—	—	18	2600	U-MOSV-H
TPC8033-H *☆	30	±20	17		5.3	7.2	—	—	22	2900	U-MOSV-H

\*: Al straps ☆: No protection Zener diode between gate and source



## ■ Product Offerings

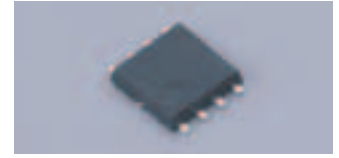
Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (m $\Omega$ )				$Q_g$ Typ. (nC)	$C_{iss}$ Typ. (pF)	Series
	$V_{DSS}$ (V)	$V_{GSS}$	$I_D$ (A)		10 V	4.5 V	4 V	2.5 V			
TPC8028 *☆	30	±20	18	N-ch Single	4.3	8	—	—	45	1800	U-MOSIV
TPC8029 *☆	30	±20	18		3.8	7	—	—	49	2200	U-MOSIV
TPC8036-H *☆	30	±20	18		4.5	5.1	—	—	26	3500	U-MOSVI-H
TPC8034-H *☆	30	±20	18		3.5	4.5	—	—	35	4614	U-MOSV-H
TPC8035-H *☆	30	±20	18		3.2	3.6	—	—	44	6000	U-MOSVI-H
TPC8042 *☆	30	±20	18		3.4	6.5	—	—	56	2900	U-MOSIV
TPC8027 *☆	30	±20	18		2.7	5.5	—	—	113	4200	U-MOSIV
TPC8022-H	40	±20	7.5		27	35	—	—	11	650	U-MOSIII-H
TPC8052-H **	40	±20	(12)		(15.2)	TBD	—	—	TBD	(1620)	U-MOSVI-H
TPC8047H **	40	±20	(16)		(17.6)	(8.8)	—	—	(23)	(2590)	U-MOSVI-H
TPC8046-H **	40	±20	(18)		(5.7)	(6.6)	—	—	(29)	(3545)	U-MOSVI-H
TPC8045-H **	40	±20	(18)		(3.9)	(4.4)	—	—	(47)	(5800)	U-MOSVI-H
TPC8053-H **	60	±20	(9)		(23.2)	(24.8)	—	—	(13)	(1620)	U-MOSVI-H
TPC8050-H **	60	±20	(11)		(14.5)	(15.6)	—	—	(21)	(2590)	U-MOSVI-H
TPC8049-H **	60	±20	(13)		(10.7)	(11.5)	—	—	(29)	(3545)	U-MOSVI-H
TPC8048-H **	60	±20	(16)		(6.9)	(7.4)	—	—	(46)	(5800)	U-MOSVI-H
TPC8051-H **	80	±20	(13)		(9.7)	(10.1)	—	—	(47)	(5800)	U-MOSVI-H
TPC8012-H	200	±20	1.8		400	—	—	—	11	440	$\pi$ -MOSV
TPC8208	20	±12	5		—	—	50	70	9.5	780	U-MOSIII
TPC8207	20	±12	6		—	—	20	30	22	2010	U-MOSIII
TPC8211	30	±20	5.5	36	44	—	—	25	1250	U-MOSIII	
TPC8212-H	30	±20	6	21	27	—	—	16	840	U-MOSIII-H	
TPC8216-H ☆	30	±20	6.4	20	23	—	—	7.6	900	U-MOSVI-H	
TPC8210	30	±20	8	15	20	—	—	75	3530	U-MOSIII	
TPC8213-H	60	±20	5	50	56	—	—	6	625	U-MOSIII-H	
TPC8214-H	100	±20	2.2	180	190	—	—	4.5	360	U-MOSIII-H	
TPC8115	-20	±8	-10	—	10	—	14	115	9130	U-MOSIV	
TPC8109	-30	±20	-10	20	—	30	—	45	2260	U-MOSIII	
TPC8119 *☆	-30	±20	-10	13	—	28	—	40	1560	U-MOSV	
TPC8121 *☆	-30	±20	-11	12	—	24	—	42	1770	U-MOSV	
TPC8111 *	-30	±20	-11	12	—	18	—	107	5710	U-MOSIV	
TPC8113 *	-30	±20	-11	10	—	18	—	107	4500	U-MOSIV	
TPC8123 *☆	-30	-25/+20	-11	9	12.5	—	—	68	2940	U-MOSVI	
TPC8122 *☆	-30	±20	-12	8	—	16.5	—	62	2450	U-MOSV	
TPC8107	-30	±20	-13	7	—	15	—	130	5880	U-MOSIII	
TPC8118 *☆	-30	±20	-13	7	—	15	—	65	2700	U-MOSV	
TPC8112 *	-30	±20	-13	6	—	14	—	130	5880	U-MOSIII	
TPC8114 *	-30	±20	-18	4.5	—	6.8	—	180	7480	U-MOSIV	
TPC8117 *☆	-30	±20	-18	3.9	—	7.9	—	130	4600	U-MOSV	
TPC8120 *☆	-30	-25/+20	-18	3.2	4.2	—	—	180	7420	U-MOSVI	
TPC8116-H	-40	±20	-7.5	30	37	—	—	27	1190	U-MOSIII-H	
TPC8110	-40	±20	-8	25	—	35	—	48	2180	U-MOSIII	
TPC8405	30	±20	6	26	33	—	—	27	1240	U-MOSIII	
	-30	±20	-4.5	33	42	—	—	40	1540	U-MOSIV	
TPC8406-H	40	±20	6.5	27	35	—	—	11	650	U-MOSIII-H	
	-40	±20	-6.5	30	37	—	—	27	1190	U-MOSIII-H	
TPC8404	250	±20	1.1	1.7	—	—	—	10	267	$\pi$ -MOSV	
	-250	±20	-0.9	2.55	—	—	—	12	381	$\pi$ -MOSV	
TPC8A01	30		6	25	30	—	—	17	940	U-MOSIII	
	30		8.5/1	18	21	—	—	49	2295	U-MOSIII	
TPC8A05-H *☆	30	±20	10/1	13.3	17.6	—	—	7.4	1300	U-MOSV-H	
TPC8A03-H *☆	30	±20	17/1	5.6	7	—	—	19	2640	U-MOSV-H	
TPC8A04-H *☆	30	±20	18/1	3.6	4.5	—	—	29	4400	U-MOSV-H	

\* : Al straps \*\* : Under development ☆ : No protection Zener diode between gate and source

## ● SOP Advance Series ... [Part Number: TPCA8xxx]

### ■ Features

- Low ON-resistance and high-speed-switching series are available.  
Low ON-resistance series: UMOSIV/V  
High-speed-switching series: U-MOSIII-H and U-MOSIV-H
- High-current, thin and thermally enhanced package



### ■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	R <sub>DS(ON)</sub> Max (mΩ)					Q <sub>g</sub> Typ. (nC)	C <sub>iss</sub> Typ. (pF)	Series
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)		10 V	4.5 V	4 V	2.5 V	1.8 V			
TPCA8011-H	20	±12	40	N-ch Single	—	3.5	—	7.5	—	32	2900	U-MOSIII-H
TPCA8030-H *☆	30	±20	24		11.0	13.4	—	—	—	83	1433	U-MOSV-H
TPCA8031-H *☆	30	±20	24		11.0	13.4	—	—	—	83	1433	U-MOSV-H
TPCA8018-H ☆	30	±20	30		6.2	8.2	—	—	—	18	2270	U-MOSV-H
TPCA8039-H *☆	30	±20	34		5.7	6.6	—	—	—	19	2600	U-MOSV-H
TPCA8024 ☆	30	±20	35		4.3	7.8	—	—	—	45	1800	U-MOSIV
TPCA8036-H *☆	30	±20	38		4.2	4.8	—	—	—	26	3500	U-MOSV-H
TPCA8012-H ☆	30	±20	40		4.9	6.8	—	—	—	22	2900	U-MOSV-H
TPCA8025 ☆	30	±20	40		3.5	6.0	—	—	—	49	2200	U-MOSIV
TPCA8060-H *☆	30	±20	45		3.4	3.9	—	—	—	34	4600	U-MOSV-H
TPCA8042 *☆	30	±20	45		3.3	5.7	—	—	—	56	2900	U-MOSIV
TPCA8019-H ☆	30	±20	45		3.1	4.1	—	—	—	34	4614	U-MOSV-H
TPCA8026 ☆	30	±20	45		2.2	4.5	—	—	—	113	4200	U-MOSIV
TPCA8028-H ☆	30	±20	50		2.8	3.2	—	—	—	46	6000	U-MOSV-H
TPCA8020-H	40	±20	7.5		27	35	—	—	—	11	650	U-MOSIII-H
TPCA8052-H *☆	40	±20	(20)		(14.9)	TBD	—	—	—	TBD	(1620)	U-MOSV-H
TPCA8014-H	40	±20	30		9	14	—	—	—	22	1365	U-MOSIII-H
TPCA8027-H	40	±20	30		10	—	—	—	—	23	1430	U-MOSIII-H
TPCA8047-H *☆	40	±20	(32)		(7.3)	(8.5)	—	—	—	(23)	(2590)	U-MOSV-H
TPCA8015-H	40	±20	35		5.4	7.9	—	—	—	37	2155	U-MOSIII-H
TPCA8046-H *☆	40	±20	(38)		(5.4)	(6.3)	—	—	—	(29)	(3545)	U-MOSV-H
TPCA8045-H *☆	40	±20	(46)		(3.6)	(4.1)	—	—	—	(47)	(5800)	U-MOSV-H
TPCA8053-H *☆	60	±20	(15)		(22.9)	(24.5)	—	—	—	(13)	(1620)	U-MOSV-H
TPCA8050-H *☆	60	±20	(24)		(14.2)	(15.3)	—	—	—	(21)	(2590)	U-MOSV-H
TPCA8016-H	60	±20	25		21	26	—	—	—	22	1375	U-MOSIII-H
TPCA8049-H *☆	60	±20	(28)		(10.4)	(11.2)	—	—	—	(29)	(3545)	U-MOSV-H
TPCA8048-H *☆	60	±20	(35)		(6.6)	(7.1)	—	—	—	(46)	(5800)	U-MOSV-H
TPCA8051-H *☆	80	±20	(28)		(9.4)	(9.8)	—	—	—	(47)	(5800)	U-MOSV-H
TPCA8006-H	100	±20	18		67	—	—	—	—	12	780	π-MOSV-II
TPCA8022-H	100	±20	22		26	—	—	—	—	38	2330	U-MOSIII-H
TPCA8009-H	150	±20	7		350	—	—	—	—	10	600	π-MOSV MACHII
TPCA8010-H	200	±20	5.5		450	—	—	—	—	10	600	π-MOSV MACHII
TPCA8008-H	250	±20	4	580	—	—	—	—	10	600	π-MOSV MACHII	
TPCA8105	-12	±8	-6	—	33	—	51	92	18	1600	U-MOSIV	
TPCA8102	-30	±20	-40	6	—	14	—	—	109	4600	U-MOSIII	
TPCA8103	-30	±20	-40	4.2	—	6.8	—	—	184	7880	U-MOSIV	
TPCA8106 ☆	-30	±20	-40	3.7	—	7.8	—	—	120	4600	U-MOSV	
TPCA8107-H	-40	±20	-7.5	30	37	—	—	—	27	1190	U-MOSIII-H	
TPCA8108	-40	±20	-40	9.5	—	—	—	—	100	4820	U-MOSIII	
TPCA8104	-60	±20	-40	16	—	24	—	—	90	4300	U-MOSIII	
TPCA8A05-H *☆	30	±20	10	12.9	17.2	—	—	—	7.4	1300	U-MOSV-H	
TPCA8A02-H *☆	30	±20	34	5.3	6.7	—	—	—	19	2640	U-MOSV-H	
S3U72 *☆	30	±20	TBD	TBD	(4.9)	—	—	—	TBD	(3700)	U-MOSV-H	
TPCA8A04-H *☆	30	±20	42	3.2	4.1	—	—	—	30	4400	U-MOSV-H	

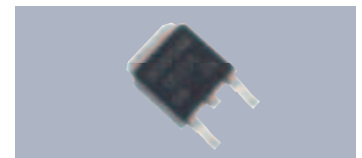
\*: Al straps ☆: No protection Zener diode between gate and source

## ● D-PAK Series ... [Part Number: TKxxPxxxM1]

### ■ Features

- High-current, thermally enhanced package







### ■ Product Offerings



Part Number	Absolute Maximum Ratings			Circuit Configuration	R <sub>DS(ON)</sub> Max (mΩ)		Q <sub>g</sub> Typ. (nC)	C <sub>iss</sub> Typ. (pF)	Series
	V <sub>DSS</sub> (V)	V <sub>GSS</sub>	I <sub>D</sub> (A)		10 V	4.5 V			
TK40P03M1	30	±20	40	N-ch Single	10.8	14.4	9.4	1150	U-MOSV-H
TK50P03M1	30	±20	50		7.5	9.8	13.3	1700	U-MOSV-H
TK40P04M1	40	±20	40		10.3	13.4	29	1920	U-MOSV-H
TK50P04M1	40	±20	50		8.7	10.2	38	2600	U-MOSV-H







## 4-7 Standard MOSFET Series ( $I_D < 500$ mA)

### Single MOSFETs

Polarity	Absolute Maximum Ratings			Package						$V_{th}$ (V)	$R_{DS(ON)}$ Typ. (Max) ( $\Omega$ )	$V_{GS}$ (V)
	$V_{DSS}$ (V)	$V_{GSS}$ (V)	$I_D$ (mA)	S-Mini (SOT-346) 2925 size, 3-pin 	USM (SOT-323) 2021 size, 3-pin 	UFM 2021 size, 3-pin 	SSM (SOT-416) 1616 size, 3-pin 	VSEM (SOT-723) 1212 size, 3-pin 	CST3 1006 size, 3-pin 			
N-ch	20	$\pm 10$	180	—	—	—	SSM3K35FS	SSM3K35MFV	SSM3K35CT	0.4 to 1.0	5 (20)	1.2
	20	$\pm 10$	100	—	SSM3K16FU	—	SSM3K16FS	SSM3K16FV	SSM3K16CT	0.6 to 1.1	5.2 (15)	1.5
	20	$\pm 10$	500	—	—	SSM3K36TU	SSM3K36FS	SSM3K36MFV	—	0.35 to 1.0	0.95 (1.52)	1.5
	20	10	100	—	—	—	—	SSM3K03FV	—	0.7 to 1.3	4 (12)	2.5
	20	10	100	—	**SSM3K04FU	—	**SSM3K04FS	**SSM3K04FV	—	0.7 to 1.3	4 (12)	2.5
	20	$\pm 12$	400	—	SSM3K05FU	—	—	—	—	0.6 to 1.1	0.85 (1.20)	2.5
	30	$\pm 20$	100	SSM3K15F	SSM3K15FU	—	SSM3K15FS	SSM3K15FV	SSM3K15CT	0.8 to 1.5	4.0 (7.0)	2.5
	30	$\pm 20$	200	2SK2009	—	—	—	—	—	0.5 to 1.5	1.2 (2.0)	2.5
	30	$\pm 20$	400	—	SSM3K09FU	—	—	—	—	1.1 to 1.8	0.8 (1.2)	4.0
	50	$\pm 7$	100	—	SSM3K17FU	—	—	—	—	0.9 to 1.5	22 (40)	2.5
	60	$\pm 20$	200	2SK1062	—	—	—	—	—	2.0 to 3.5	0.6 (1.0)	10
	60	$\pm 20$	200	SSM3K7002F	SSM3K7002FU	—	—	—	—	1.0 to 2.5	2.2 (3.3)	4.5
60	$\pm 20$	200	SSM3K7002AF	SSM3K7002AFU	—	—	—	—	1.0 to 2.5	1.8 (3.3)	4.5	
P-ch	-20	$\pm 10$	-100	—	—	—	SSM3J35FS	SSM3J35MFV	SSM3J35CT	-0.4 to -1.0	11 (44)	-1.2
	-20	$\pm 10$	-100	—	SSM3J16FU	—	SSM3J16FS	SSM3J16FV	SSM3J16CT	-0.6 to -1.1	18 (45)	-1.5
	-20	$\pm 8$	-330	—	—	SSM3J36TU	SSM3J36FS	SSM3J36MFV	—	-0.3 to -1.0	2.23 (3.6)	-1.5
	-20	$\pm 12$	-200	—	SSM3J05FU	—	—	—	—	-0.6 to -1.1	3.2 (4.0)	-2.5
	-30	$\pm 20$	-100	SSM3J15F	SSM3J15FU	—	SSM3J15FS	SSM3J15FV	SSM3J15CT	-1.1 to -1.7	14 (32)	-2.5
	-30	$\pm 20$	-200	2SJ305	—	—	—	—	—	-0.5 to -1.5	2.4 (4.0)	-2.5
	-30	$\pm 20$	-200	—	SSM3J09FU	—	—	—	—	-1.1 to -1.8	3.3 (4.2)	-4.0
	-50	-7	-50	2SJ343	2SJ344	—	—	—	—	-0.8 to -2.5	20 (50)	-4.0
	-60	$\pm 20$	-200	2SJ168	—	—	—	—	—	-2.0 to -3.5	1.3 (2.0)	-10

\*\* : Built-in 1-M $\Omega$  gate-source resistor

### Dual MOSFETs

Polarity	Absolute Maximum Ratings			Package						$V_{th}$ (V)	$R_{DS(ON)}$ Typ. (Max) ( $\Omega$ )	$V_{GS}$ (V)	Constituent Devices
	$V_{DSS}$ (V)	$V_{GSS}$ (V)	$I_D$ (mA)	US6 (SOT-363) 2021 size, 6-pin 	UF6 2021 size, 6-pin 	USV (SOT-353) 2021 size, 5-pin 	ES6 (SOT-563) 1616 size, 6-pin 	ESV (SOT-553) 1616 size, 5-pin 	CST6D 1009 size, 6-pin 				
N-chx2	20	$\pm 10$	180	SSM6N35FU	—	—	SSM6N35FE	—	—	0.4 to 1.0	5 (20)	1.2	SSM3K35FSx2
	20	$\pm 10$	100	SSM6N16FU	—	SSM5N16FU	SSM6N16FE	SSM5N16FE	—	0.6 to 1.1	5.2 (15)	1.5	SSM3K16FUx2
	20	$\pm 10$	250	—	—	—	—	—	SSM6N37CTD	0.35 to 1.0	3.07 (5.6)	1.5	—
	20	$\pm 10$	500	—	SSM6N36TU	—	SSM6N36FE	—	—	0.35 to 1.0	0.95 (1.52)	1.5	SSM3K36FSx2
	20	10	100	—	—	—	SSM6N03FE	SSM5N03FE	—	0.7 to 1.3	4 (12)	2.5	SSM3K03FEx2
	20	10	100	**SSM6N04FU	—	—	—	—	—	0.7 to 1.3	4 (12)	2.5	SSM3K04FUx2
	20	$\pm 12$	400	SSM6N05FU	—	SSM5N05FU	—	—	—	0.6 to 1.1	0.85 (1.2)	2.5	SSM3K05FUx2
	30	$\pm 20$	100	SSM6N15FU	—	SSM5N15FU	SSM6N15FE	SSM5N15FE	—	0.8 to 1.5	4.0 (7.0)	2.5	SSM3K15FUx2
	30	$\pm 20$	400	SSM6N09FU	—	—	—	—	—	1.1 to 1.8	0.8 (1.2)	4.0	SSM3K09FUx2
	50	$\pm 7$	100	SSM6N17FU	—	—	—	—	—	0.9 to 1.5	22 (40)	2.5	SSM3K17FUx2
	60	$\pm 20$	200	SSM6N7002FU	—	—	—	—	—	1.0 to 2.5	2.2 (3.3)	4.5	SSM3K7002FUx2
	60	$\pm 20$	200	SSM6N7002AFU	—	—	—	—	—	1.0 to 2.5	1.8 (3.3)	4.5	SSM3K7002AFUx2
P-chx2	-20	$\pm 10$	-100	SSM6P35FU	—	—	SSM6P35FE	—	—	-0.4 to -1.0	11 (44)	-1.2	SSM3J35FSx2
	-20	$\pm 10$	-100	SSM6P16FU	—	SSM5P16FU	SSM6P16FE	SSM5P16FE	—	-0.6 to -1.1	18 (45)	-1.5	SSM3J16FUx2
	-20	$\pm 8$	-330	—	SSM6P36TU	—	SSM6P36FE	—	—	-0.3 to -1.0	2.23 (3.6)	-1.5	SSM3J36FSx2
	-20	$\pm 12$	-200	SSM6P05FU	—	SSM5P05FU	—	—	—	-0.6 to -1.1	3.2 (4.0)	-2.5	SSM3J05FUx2
	-30	$\pm 20$	-100	SSM6P15FU	—	SSM5P15FU	SSM6P15FE	SSM5P15FE	—	-1.1 to -1.7	14 (32)	-2.5	SSM3J15FUx2
	-30	$\pm 20$	-200	SSM6P09FU	—	—	—	—	—	-1.1 to -1.8	3.3 (4.2)	-4.0	SSM3J09FUx2
N-ch+ P-ch	20	$\pm 10$	180	SSM6L35FU	—	—	SSM6L35FE	—	—	0.4 to 1.0	5 (20)	1.2	SSM3K35FS
	-20	$\pm 10$	-100	—	—	—	SSM6L16FE	—	—	-0.4 to -1.0	11 (44)	-1.2	+SSM3J35FS
	20	$\pm 10$	100	—	—	—	SSM6L16FE	—	—	0.6 to 1.1	5.2 (15)	1.5	SSM3K16FS
	-20	$\pm 10$	-100	—	—	—	SSM6L16FE	—	—	-0.6 to -1.1	18 (45)	-1.5	+SSM3J16FS
	20	$\pm 10$	500	—	SSM6L36TU	—	SSM6L36FE	—	—	0.35 to 1.0	0.95 (1.52)	1.5	SSM3K36FS
	-20	$\pm 8$	-330	—	SSM6L36TU	—	SSM6L36FE	—	—	-0.3 to -1.0	2.23 (3.6)	-1.5	+SSM3J36FS
	20	$\pm 12$	400	SSM6L05FU	—	—	—	—	—	0.6 to 1.1	0.85 (1.2)	2.5	SSM3K05FU
	-20	$\pm 12$	-200	SSM6L05FU	—	—	—	—	—	-0.6 to -1.1	3.2 (4.0)	-2.5	+SSM3J05FU
30	$\pm 20$	400	SSM6L09FU	—	—	—	—	—	1.1 to 1.8	0.8 (1.2)	4.0	SSM3K09FU	
-30	$\pm 20$	-200	SSM6L09FU	—	—	—	—	—	-1.1 to -1.8	3.3 (4.2)	-4.0	+SSM3J09FU	

\*\* : Built-in 1-M $\Omega$  gate-source resistor

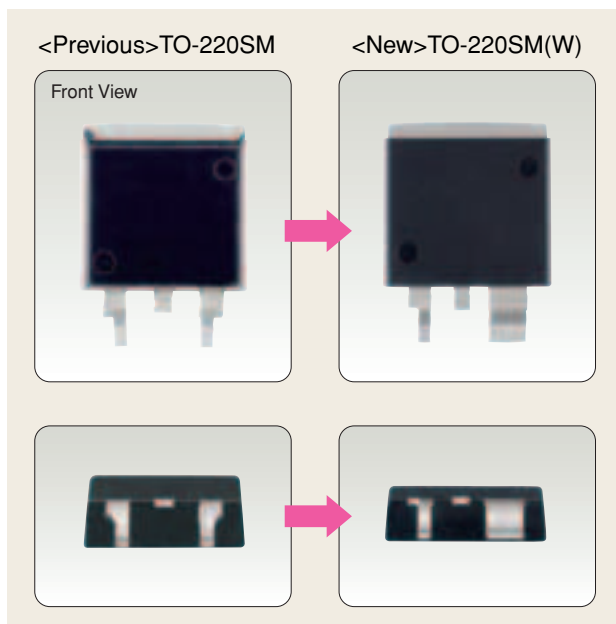
## 5-1 TO-220SM(W) Series

The TO-220SM(W) package, which uses Cu connectors and a wide source terminal, realizes low ON-resistance and a high current-carrying capability.

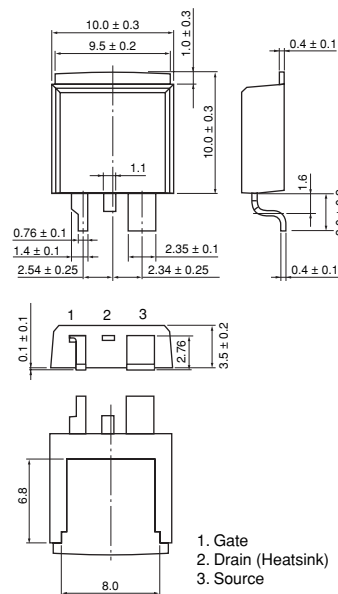
### ■ Features

- Achieves low ON-resistance, low package inductance and low thermal resistance due to the use of Cu connectors.
- Achieves a high current-carrying capability due to the use of a wide source terminal ( $I_D$  (DC) = 150 A max)
- AEC-Q101-qualified at a channel temperature ( $T_{ch}$ ) of 175°C
- Thin package: 3.7-mm (max) thick, much thinner than the previous TO-220SM package with a thickness of 4.7 mm (max)

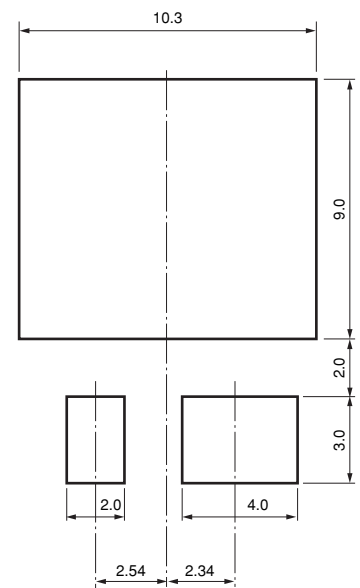
### ■ Package



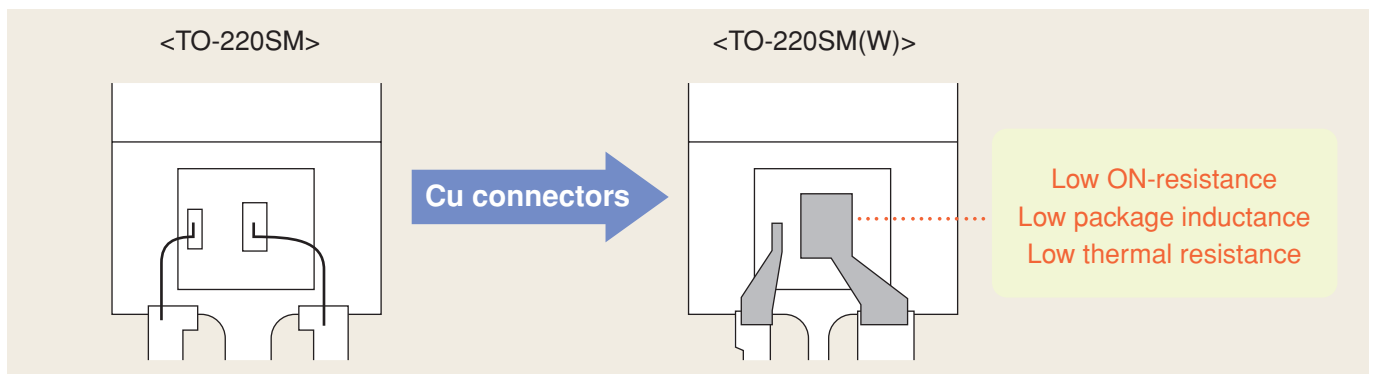
### ■ Package Dimensions



### ■ Land Pattern Example



### ■ Characteristics of the WARP Series

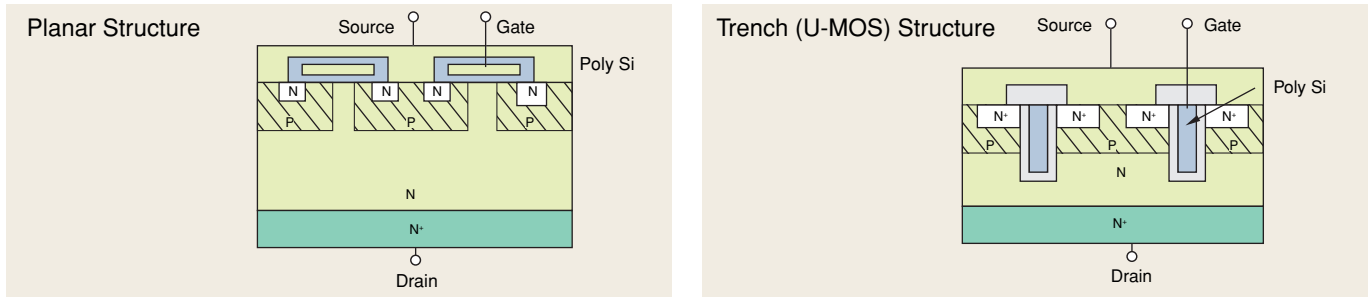


### ■ Product Offerings

Part Number	Absolute Maximum Ratings			$R_{DS(ON)}$ Max (m $\Omega$ )		$C_{iss}$ Typ. (pF)	$Q_g$ Typ. (nC)	Series
	$V_{DSS}$ (V)	$V_{GS}$ (V)	$I_D$ (A)	Typ.	Max			
TJ120F06J3	-60	$\pm 20$	-120	5.5	8.0	11500	258	U-MOSIII
TK100F04K3	40	$\pm 20$	100	2.5	3.0	4500	102	U-MOSIV
TK150F04K3	40	$\pm 20$	150	1.7	2.1	7500	166	U-MOSIV
TK100F06K3	60	$\pm 20$	100	4.0	5.0	4500	98	U-MOSIV
TK130F06K3	60	$\pm 20$	130	2.6	3.4	8400	170	U-MOSIV
TK50F15J1	150	$\pm 20$	50	22	30	4300	75	U-MOSIII

## 5-2 U-MOS (Trench Type) Series

Fabricated using a trench structure, the U-MOS Series ultra-high integration density and thus



### ■ Features

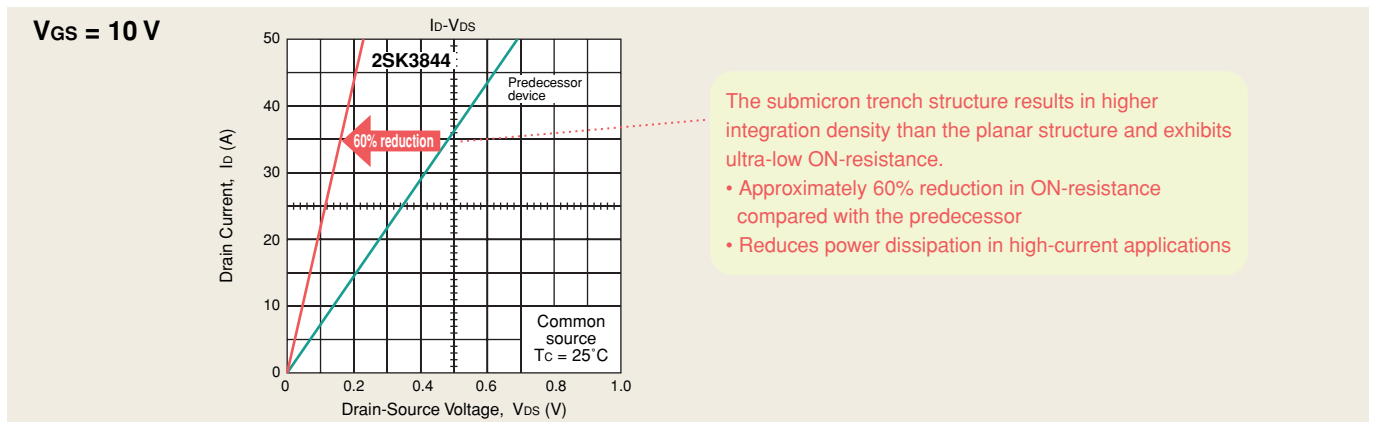
- High density through the use of submicron technology
- 60% reduction in  $R_{DS(ON)}$  by per unit area (as compared with the maximum  $R_{DS(ON)}$  of  $L^2$ - $\pi$ -MOSV)
- Guaranteed avalanche capability and improved di/dt rate
- Protection Zener diode between gate and source

### ■ Product Offerings

Applications	Part Number	Absolute Maximum Ratings				Package	$R_{DS(ON)}$ Max (m $\Omega$ )			$R_{DS(ON)}$ Max (m $\Omega$ )			$Q_g$ Typ. (nC)	Series	
		$V_{DS}$ (V)	$I_D$ (A)	$V_{GS}$ (V)	$P_D$ (W)		$V_{GS}$ (V)	$I_D$ (A)	$V_{GS}$ (V)	$I_D$ (A)					
motor drive Solenoids Lamp drivers DC-DC converters	2SJ668	-60	-5	$\pm 20$	20	PW-Mold	170	-10	-2.5	250	-4	-2.5	15	U-MOSIII	
	2SJ681	-60	-5	$\pm 20$	20	New PW-Mold2	170	-10	-2.5	250	-4	-2.5	15		
	2SJ669	-60	-5	$\pm 20$	1.2	TPS	170	-10	-2.5	250	-4	-2.5	15		
DC-DC converters	TPCA8104	-60	-40	$\pm 20$	45	SOP Advance	16	-10	-20	24	-4	-20	90	U-MOSVI	
	TJ120F06J3	-60	-120	$\pm 20$	300	TO-220SM(W)	8.0	-10	-60	—	—	—	258		
LCD backlight inverter	TJ20A10M3 *	-100	-20	$\pm 20$	35	TO-220SIS	90	-10	-10	—	—	—	120	U-MOSVI	
motor drive Solenoids Lamp drivers DC-DC converters	2SK3754	30	5	$\pm 20$	25	TO-220NIS	89	10	2.5	99	4.5	2.5	2.5	U-MOSIII	
	2SK3846	40	26	$\pm 20$	25	TO-220NIS	16	10	13	28	4.5	13	40		
	2SK3847	40	32	$\pm 20$	30	TO-220SM	16	10	16	28	4.5	16	40		
	TK70J04J3	40	70	$\pm 20$	150	TO-3P(N)	3.8	10	35	8.3	4.5	35	210	U-MOSIV	
	2SK3843	40	75	$\pm 20$	125	TFP	3.5	10	38	8.0	4.5	38	210		
	TK100F04K3	40	100	$\pm 20$	200	TO-220SM(W)	3.0	10	50	—	—	—	102		
	TK150F04K3	40	150	$\pm 20$	300	TO-220SM(W)	2.1	10	75	—	—	—	166	U-MOSIII	
	2SK4017	60	5	$\pm 20$	20	New PW-Mold2	100	10	2.5	150	4	2.5	15		
	2SK4033	60	5	$\pm 20$	20	New PW-Mold	100	10	2.5	150	4	2.5	15		
	DC-DC converters	TK30A06J3A	60	30	$\pm 20$	25	TO-220SIS	26	10	15	35	4.5	15	36	U-MOSIII
		2SK3662	60	35	$\pm 20$	35	TO-220NIS	12.5	10	18	19	4	18	91	
		2SK3842	60	75	$\pm 20$	125	TFP	5.8	10	38	—	—	—	196	
		2SK4034	60	75	$\pm 20$	125	TFP	5.8	10	38	10	4.5	38	196	
		2SK3844	60	45	$\pm 20$	45	TO-220NIS	5.8	10	23	—	—	—	196	
		2SK3845	60	70	$\pm 20$	125	TO-3P(N)	5.8	10	23	—	—	—	196	
		TK100F06K3	60	100	$\pm 20$	200	TO-220SM(W)	5.0	10	50	—	—	—	98	
	LCD backlight inverter	TK130F06K3	60	130	$\pm 20$	300	TO-220SM(W)	3.4	10	65	—	—	—	170	U-MOSIV
		2SK3940	75	70	$\pm 20$	150	TO-3P(N)	7.0	10	35	—	—	—	200	U-MOSIII
		TK25A10K3 *	100	25	$\pm 20$	25	TO-220SIS	40	10	12	—	—	—	34	U-MOSIV

\*: No protection Zener diode between gate and source

### ■ MOSFET with $R_{DS(ON)}$ of 5.8 m $\Omega$ (max) in the TO-220 package





## 5-3 U-MOS Series for Synchronous Rectification ( $V_{DSS} = 60\text{ V to }150\text{ V}$ )

Fabricated using a trench technology, the U-MOS Series is ideal for synchronous rectification on the secondary side of power supply circuits.

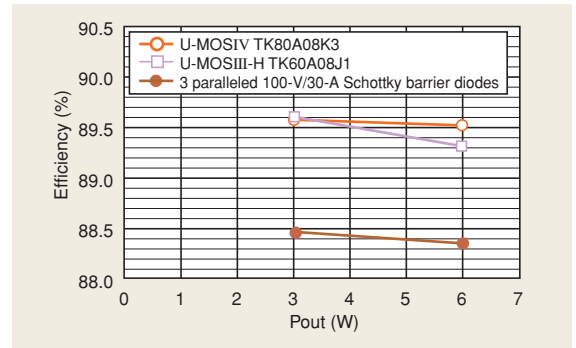
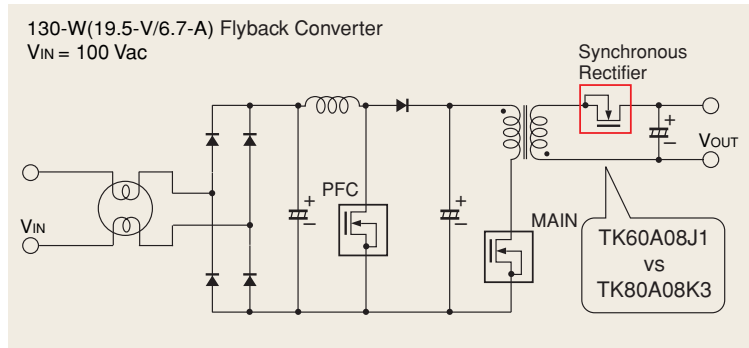
### ■ Features

- Low ON-resistance achieved by high density through the use of submicron technology
- Guaranteed avalanche capability
- High power dissipation achieved by having the series housed in the TO-220(W) package with an exposed heatsink on the bottom of the package

### ■ Comparisons Between Synchronous Rectification MOSFETs

Characteristic	Symbol	Test Conditions	TK80A08K3			TK60A08J1			Unit
			Min	Typ	Max	Min	Typ	Max	
Gate leakage current	+IGSS	$V_{GS} = 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	1	—	—	10	$\mu\text{A}$
	-IGSS	$V_{GS} = -16\text{ V}, V_{DS} = 0\text{ V}$	—	—	-1	—	—	-10	$\mu\text{A}$
Drain cut-off current	IDSS	$V_{DS} = 75\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	—	—	10	$\mu\text{A}$
Drain-source breakdown voltage	+V(BR)DSS	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	75	—	—	75	—	—	V
	-V(BR)DSX	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	50	—	—	60	—	—	V
Gate threshold voltage	Vth	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	2.0	—	4.0	1.1	—	2.3	V
Drain-source ON-resistance	RDS(ON)	$V_{GS} = 10\text{ V}, I_D = 30\text{ A}$	—	3.6	4.5	—	6.2	7.8	m $\Omega$
Input capacitance	Ciss	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}$ $f = 1\text{ MHz}$	—	8200	—	—	5450	—	pF
Reverse transfer capacitance	Crss		—	770	—	—	320	—	pF
Forward voltage	VDSF	$I_{DR} = 60\text{ A}, V_{GS} = 0\text{ V}$	—	0.9	-1.2	—	0.9	-1.2	V

### ■ Efficiency Test Circuit



Efficiency approx. 1% higher than Schottky barrier diodes

### ■ Product Offerings

Part Number	Absolute Maximum Ratings				$R_{DS(ON)}$ (m $\Omega$ ) @ $V_{GS} = 10\text{ V}$		$Q_g$ (nC) Typ.	$Q_{sw}$ (nC) Typ.	Package	Series
	$V_{DSS}$ (V)	$I_D$ (A)	$V_{GSS}$ (V)	$P_D$ (W)	Typ.	Max				
TK70D06J1	60	70	$\pm 20$	140	5.1	6.4	87	30	TO-220(W)	U-MOSIII-H
TK70A06J1	60	70	$\pm 20$	45	5.1	6.4	87	30	TO-220SIS	U-MOSIII-H
TK60D08J1	75	60	$\pm 20$	140	6.2	7.8	86	27	TO-220(W)	U-MOSIII-H
TK60A08J1	75	60	$\pm 20$	45	6.2	7.8	86	27	TO-220SIS	U-MOSIII-H
TK40A08K3	75	40	$\pm 20$	42	7.0	9.0	80	—	TO-220SIS	U-MOSIV
TK80D08K3	75	80	$\pm 20$	100	3.6	4.5	175	80	TO-220(W)	U-MOSIV
TK80A08K3	75	80	$\pm 20$	40	3.6	4.5	175	80	TO-220SIS	U-MOSIV
TK40A10K3	100	40	$\pm 20$	40	11.5	15	85	40	TO-220SIS	U-MOSIV
TK40D10J1	100	40	$\pm 20$	100	11.5	15	76	25	TO-220(W)	U-MOSIII-H
TK40A10J1	100	40	$\pm 20$	40	11.5	15	76	25	TO-220SIS	U-MOSIII-H
TK40X10J1	100	40	$\pm 20$	125	15	20	59	25	TFP	U-MOSIII-H
TK55D10J1	100	55	$\pm 20$	140	8.4	10.5	110	33	TO-220(W)	U-MOSIII-H
TK55A10J1	100	55	$\pm 20$	45	8.4	10.5	110	33	TO-220SIS	U-MOSIII-H
TK50X15J1	150	50	$\pm 20$	125	22	30	75	33	TFP	U-MOSIII-H



## 6-1 $\pi$ -MOSVII Series ( $V_{DSS} = 450\text{ V to }650\text{ V}$ )

The latest addition to the  $\pi$ -MOS portfolio, the  $\pi$ -MOSVII Series offers reduced capacitances due to optimized chip design and is available with a greatly wider range of electrical characteristics.

### ■ Features

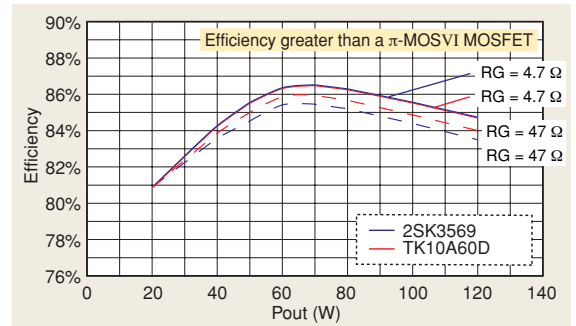
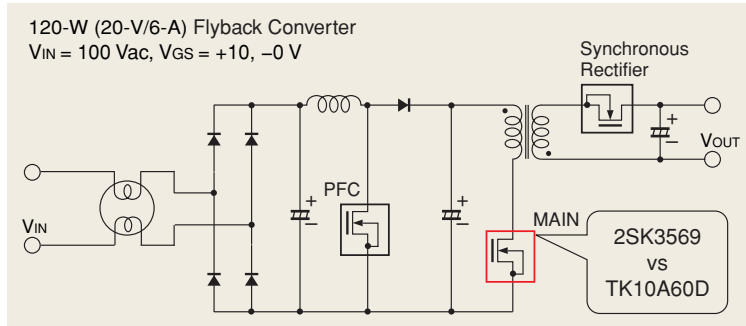
- 40% reduction in  $Q_g$  from  $\pi$ -MOSVI due to optimized chip design
- Available in 50-V steps of  $V_{DSS}$  and in finer steps of  $R_{DS(ON)}$ .
- Rated avalanche and reverse recovery current capabilities

### ■ Performance Comparisons Between $\pi$ -MOSVII and $\pi$ -MOSVI Devices (600 V/10 A)

Characteristic	Symbol	Test Conditions	Series			Series			Unit
			Min	Typ.	Max	Min	Typ.	Max	
Gate leakage current	$\pm I_{GSS}$	$V_{GS}$ condition <sup>*1</sup> , $V_{DS} = 0\text{ V}$	—	—	$\pm 1$	—	—	$\pm 10$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 600\text{ V}$ , $V_{GS} = 0\text{ V}$	—	—	100	—	—	100	$\mu\text{A}$
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = +10\text{ mA}$ , $V_{GS} = 0\text{ V}$	600	—	—	600	—	—	V
Gate threshold voltage	$V_{th}$	$V_{DS} = 10\text{ V}$ , $I_D = 1\text{ mA}$	2.0	—	4.0	2.0	—	4.0	V
Drain-source ON-resistance	$R_{DS(ON)}$	$V_{GS} = 10\text{ V}$ , $I_D = 5\text{ A}$	—	—	0.75	—	—	0.75	$\Omega$
Total gate charge	$Q_g$	$V_{DD} = 400\text{ V}$ , $V_{GS} = 10\text{ V}$ , $I_D = 10\text{ A}$	—	25	—	—	42	—	nC
Diode forward voltage	$V_{DSF}$	$I_{DR} = 10\text{ A}$ , $V_{GS} = 0\text{ V}$	—	—	-1.7	—	—	-1.7	V

\*1: Test conditions: TK10A60D:  $V_{GS} = \pm 30\text{ V}$ , 2SK3569:  $V_{GS} = \pm 25\text{ V}$

### ■ Efficiency Test Circuit



### ■ Product Offerings

Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ ( $\Omega$ ) $V_{GS} = 10\text{ V}$	Equivalent $\pi$ -MOSVI Part	Package	
	$V_{DSS}$ (V)	$I_D$ (A)				
TK13A45D	450	13	0.46	2SK3743	TO-220SIS	
TK4A50D		4	2.0	—	TO-220SIS	
TK5A50D		5	1.5	2SK3563	TO-220SIS	
TK6A50D		6	1.4	—	TO-220SIS	
TK7A50D		7	1.2	—	TO-220SIS	
TK8A50DA *		7.5	1.0	—	TO-220SIS	
TK8A50D		8	0.85	2SK3561	TO-220SIS	
TK10A50D		10	0.72	—	TO-220SIS	
TK11A50D *		11	0.6	—	TO-220SIS	
TK12A50D		12	0.52	2SK3568	TO-220SIS	
TK13A50DA	500	12.5	0.47	—	TO-220SIS	
TK13A50D		13	0.4	2SK4012	TO-220SIS	
TK15J50D		15	0.4	2SK4107	TO-3P(N)	
TK15A50D		15	0.3	2SK3934	TO-220SIS	
TK18A50D		18	0.27	—	TO-220SIS	
TK20J50D		20	0.27	2SK4108	TO-3P(N)	
TK4A53D *		525	4	1.7	—	TO-220SIS
TK5A53D *			5	1.5	2SK3563	TO-220SIS
TK6A53D			6	1.3	—	TO-220SIS
TK6P53D *			6	1.3	—	D-PAK
TK12A53D	12		0.58	—	TO-220SIS	
TK12X53D	12		0.58	2SK3398	TFP	
TK4A55DA	550		3.5	2.45	—	TO-220SIS
TK4A55D			4	1.9	—	TO-220SIS
TK5A55D			5	1.7	—	TO-220SIS
TK6A55DA			5.5	1.48	—	TO-220SIS

Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ ( $\Omega$ ) $V_{GS} = 10\text{ V}$	Equivalent $\pi$ -MOSVI Part	Package
	$V_{DSS}$ (V)	$I_D$ (A)			
TK8A55DA	550	7.5	1.07	—	TO-220SIS
TK9A55DA		8.5	0.86	—	TO-220SIS
TK11A55D		11	0.63	—	TO-220SIS
TK12A55D *		12	0.57	—	TO-220SIS
TK12J55D		12	0.57	—	TO-3P(N)
TK13A55DA *		12.5	0.48	—	TO-220SIS
TK14A55D		14	0.37	—	TO-220SIS
TK16A55D *		16	0.33	—	TO-220SIS
TK16J55D		16	0.37	—	TO-3P(N)
TK2Q60D		2	5.0	2SK4002	New PW-Mold 2
TK3A60DA	600	2.5	2.8	—	TO-220SIS
TK4A60DA		3.5	2.2	2SK3567	TO-220SIS
TK4A60DB *		3.7	2	—	TO-220SIS
TK4A60D		4	1.7	—	TO-220SIS
TK6A60D		6	1.25	2SK3562	TO-220SIS
TK8A60DA		7.5	1	2SK3667	TO-220SIS
TK10A60D		10	0.75	2SK3569	TO-220SIS
TK11A60D		11	0.65	—	TO-220SIS
TK12A60D		12	0.55	—	TO-220SIS
TK13A60D		13	0.43	2SK3797	TO-220SIS
TK15A60D	15	0.37	—	TO-220SIS	
TK5A65D	650	5	1.43	—	TO-220SIS
TK6A65D		6	1.11	—	TO-220SIS
TK8A65D		8	0.84	—	TO-220SIS
TK12A65D *		12	0.50	—	TO-220SIS

\*: Under development

## 6-2 Super-Junction DTMOS Series ( $V_{DSS} = 600\text{ V}, 650\text{ V}$ )

The DTMOS devices employ a new super-junction structure that enables an ultra-low ON-resistance with the maximum  $V_{DSS}$  rating of 600 V. The DTMOS Series helps reduce the power consumption and size of electronic equipment.

### ■ Features

- Low ON-resistance TK40J60T:  $80\text{ m}\Omega$  (max) @  $V_{GS} = 10\text{ V}, I_D = 20\text{ A}$
- Low gate charge TK20A60U:  $Q_g = 27\text{ nC}$  typ.,  $600\text{ V} / 20\text{ A}$
- Avalanche capability guaranteed up to the rated maximum current e.g.) TK20A60U  $I_{AR} = 20\text{ A}$  @  $V_{DD} = 90\text{ V}, R_g = 25\ \Omega, L = 0.63\text{ mH}$
- The rugged internal drain-source diode is not damaged at  $di/dt = 500\text{ A}/\mu\text{s}$  (@  $V_{DS} = 400\text{ V}, 150^\circ\text{C}$ ).

### ■ Product Offerings

Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ Max ( $\Omega$ )	$Q_g$ Typ. (nC)	$C_{iss}$ Typ. (pF)	Package	Series
	$V_{DSS}$ (V)	$I_D$ (A)	$V_{GS} = 10\text{ V}$				
TK12A60U	600	12	0.4	14	720	TO-220SIS	DTMOSII
TK12D60U						TO-220(W)	
TK12J60U						TO-3P(N)	
TK15J60T		15	0.3	21	1200	TO-3P(N)	DTMOSI
TK15A60U		15	0.3	17	950	TO-220SIS	DTMOSII
TK15D60U						TO-220(W)	
TK15J60U						TO-3P(N)	
TK20A60T		20	0.19	30	1580	TO-220SIS	DTMOSI
TK20D60T						TO-220(W)	
TK20J60T						TO-3P(N)	
TK20A60U		20	0.19	27	1470	TO-220SIS	DTMOSII
TK20D60U						TO-220(W)	
TK20J60U	TO-3P(N)						
TK40J60T	40	0.08	67	3900	TO-3P(N)	DTMOSI	
TK50J60U *	50	0.065	70	4300	TO-3P(N)	DTMOSII	
TK13A65U	650	13	0.38	17	950	TO-220SIS	DTMOSII

\*: Under development

### ■ Performance Comparisons Between the New DTMOS and Conventional MOSFET ( $\pi$ -MOSVI) Devices (600 V/20 A)

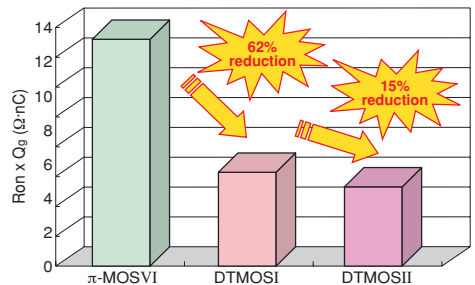
Characteristic	Symbol	Test Conditions	Series			Series			Unit
			DTMOSII			$\pi$ -MOSVI			
			Min	Typ.	Max	Min	Typ.	Max	
Gate leakage current	$\pm I_{GSS}$	$V_{GS}$ condition <sup>*1</sup> , $V_{DS} = 0\text{ V}$	—	—	$\pm 1$	—	—	$\pm 10$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 600\text{ V}, V_{GS} = 0\text{ V}$	—	—	100	—	—	100	$\mu\text{A}$
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	600	—	—	600	—	—	V
Gate threshold voltage	$V_{th}$	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	3.0	—	5.0	2.0	—	4.0	V
Drain-source ON-resistance	$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 10\text{ A}$	—	0.165	0.19	—	0.22	0.32	$\Omega$
Total gate charge	$Q_g$	$V_{DD} = 400\text{ V}, V_{GS} = 10\text{ V}, I_D = 20\text{ A}$	—	27	—	—	60	—	nC
Diode forward voltage	$V_{DSF}$	$I_{DR} = 20\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.7	—	—	-1.7	V

\*1: Test conditions: TK20J60U:  $V_{GS} = \pm 30\text{ V}$ , 2SK3911:  $V_{GS} = \pm 25\text{ V}$

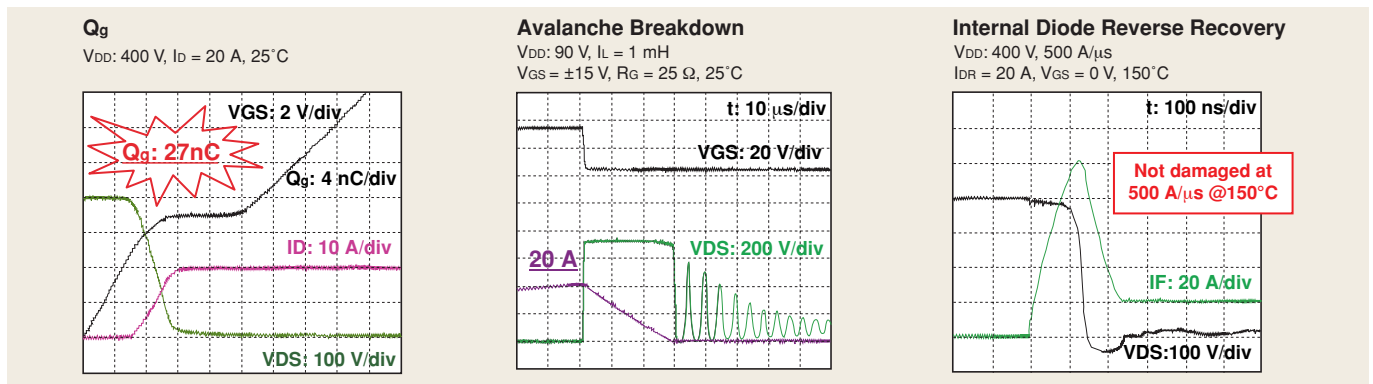
### ■ Figure-of-Merit (FOM) Comparison

$R_{on} \times Q_g$ , the product of ON-resistance and total gate charge, is reduced by 62%, compared with the conventional MOSFETs with the same chip size.

\*  $R_{on} \times Q_g$  is a figure-of-merit index for the switching speed of MOSFETs.



### ■ Performance Characteristics of the New DTMOS Series TK20A60U Electrical Characteristics



## 6-3 High-speed $\pi$ -MOS Series ( $V_{DSS} = 450\text{ V to }600\text{ V}$ )

To support the development of high-efficiency equipment, Toshiba has developed two series of high-speed power MOSFETs: a high-speed switching series for AC adapters and switching power supplies; and a high-speed diode series for motor controllers and inverter circuits.

- MACH Series: Achieves a higher switching speed than the existing  $\pi$ -MOS Series, which is currently well established in the market.
- High-Speed Diode Series: Achieves a higher internal diode speed by using lifetime control.

### ■ Product Offerings

- MACH Series

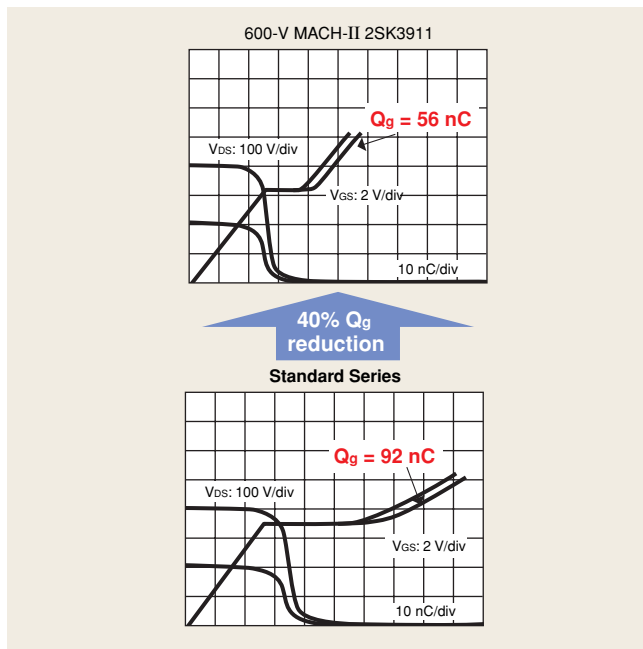
Applications	Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ Max ( $\Omega$ )	$V_{GS}$ (V)	$I_D$ (A)	$Q_g$ Typ. (nC)	Standard Type	Series
		$V_{DSS}$ (V)	$I_D$ (A)	$P_D$ (W)							
AC adapters Switching power supplies	2SK3310	450	10	40	TO-220NIS	0.65	10	5	23	2SK3126	MACH-I
	2SK3309	450	10	65	TO-220FL/SM	0.65	10	5	23	—	
	2SK3743	450	13	40	TO-220NIS	0.4	10	6	34	—	
	2SK3403	450	13	100	TO-220FL/SM	0.4	10	6	34	—	
	2SK3312	600	6	65	TO-220FL/SM	1.25	10	3	25	2SK2777	
	2SK3437	600	10	80	TO-220FL/SM	1	10	5	28	2SK2996	
	2SK3399	600	10	100	TO-220FL/SM	0.75	10	5	35	2SK2866	
	2SK3907	500	23	150	TO-3P(N)	0.23	10	11.5	60	—	MACH-II
2SK3911	600	20	150	TO-3P(N)	0.32	10	10	60	—		

- High-Speed Diode Series (HSD Series)

Applications	Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ Max ( $\Omega$ )	$V_{GS}$ (V)	$I_D$ (A)	trr Typ. (ns)	Standard Type
		$V_{DSS}$ (V)	$I_D$ (A)	$P_D$ (W)						
Motor control Inverters Switching power supplies	2SK3868	500	5	35	TO-220SIS	1.7	10	2.5	150	2SK3563
	2SK3417	500	5	50	TO-220FL/SM	1.8	10	2.5	60	2SK2991
	2SK4042	500	8	40	TO-220SIS	0.97	10	4	185	2SK3561
	2SK3313	500	12	40	TO-220NIS	0.62	10	6	90	2SK2842
	2SK3314	500	15	150	TO-3P(N)	0.49	10	7	105	2SK2698
	2SK3131	500	50	250	TO-3P(L)	0.11	10	25	105	2SK3132
	2SK3936	500	23	150	TO-3P(N)	0.25	10	11.5	380	2SK3907
	2SK3947	600	6	40	TO-220SIS	1.4	10	3	150	2SK3562
	2SK4015	600	10	45	TO-220SIS	0.86	10	5	170	2SK3569
	2SK4016	600	13	50	TO-220SIS	0.50	10	6.5	160	2SK3911
	2SK3906	600	20	150	TO-3P(N)	0.33	10	10	400	2SK3797

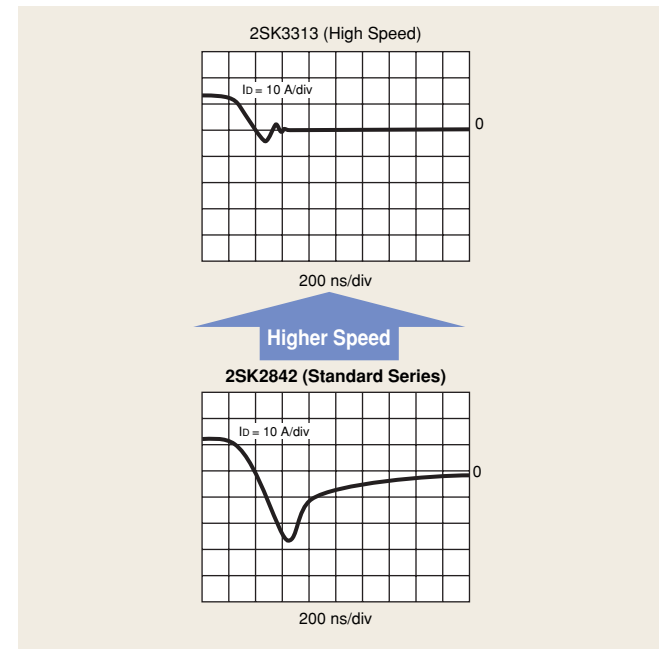
### ■ Characteristics of the MACHII Series

40% reduction in  $Q_g$  losses



### ■ Characteristics of the High-Speed Diode Series

Faster internal diode



## 6-4 $\pi$ -MOS Series

### ■ $\pi$ -MOSVI Series ( $V_{DSS} = 450\text{ V to }600\text{ V}$ )

Series	Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ Max ( $\Omega$ )		$Q_g$ Typ. (nC)	$C_{ISS}$ Typ. (pF)	Equivalent Predecessor Part	Package
		$V_{DSS}$ (V)	$I_D$ (A)	$V_{GS} = 10\text{ V}$					
$\pi$ -MOSVI	2SK3757	450	2	2.45	9	330	2SK3543	TO-220SIS	
	2SK3766		2	2.45	8	270	2SK3543	TO-220SIS	
	2SK3869		10	0.68	28	1050	2SK3407	TO-220SIS	
	2SK3935		17	0.25	62	3100	—	TO-220SIS	
	2SK3904		19	0.26	62	3100	—	TO-3P(N)	
	2SK3563		5	1.5	16	550	2SK2662	TO-220SIS	
	2SK3863	5	1.5	16	550	—	DP		
	2SK4103	5	1.5	16	550	2SK3863	New Pw-Mold		
	2SK3561	8	0.85	28	1050	2SK2543	TO-220SIS		
	2SK3568	12	0.52	42	1500	2SK2842	TO-220SIS		
	2SK4012	13	0.4	50	2400	—	TO-220SIS		
	2SK3934	15	0.3	62	3100	—	TO-220SIS		
	2SK4107	15	0.4	48	2450	2SK2698	TO-3P(N)		
	2SK3905	17	0.31	62	3100	—	TO-3P(N)		
	2SK4108	20	0.27	70	3400	2SK2837	TO-3P(N)		
	2SK3767	2	4.5	9	320	2SK3067	TO-220SIS		
	2SK3567	3.5	2.2	17	550	2SK2750	TO-220SIS		
	2SK3562	6	1.25	28	1050	2SK2545	TO-220SIS		
	2SK3667	7.5	1.0	33	1300	2SK2996	TO-220SIS		
	2SK3569	10	0.75	42	1500	2SK2843	TO-220SIS		
	2SK3797	13	0.43	62	3150	—	TO-220SIS		
	2SK3903	14	0.44	62	3100	—	TO-3P(N)		

### ■ $\pi$ -MOSIV Series ( $V_{DSS} = 800\text{ V to }900\text{ V}$ )

Series	Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ Max ( $\Omega$ )		$Q_g$ Typ. (nC)	$C_{ISS}$ Typ. (pF)	Equivalent Predecessor Part	Package
		$V_{DSS}$ (V)	$I_D$ (A)	$V_{GS} = 10\text{ V}$					
$\pi$ -MOSIV	2SK3633	800	7	1.7	35	1500	2SK2746	TO-3P(N)	
	2SK3879		6.5	1.7	35	1500	—	TO-220FL/SM	
	2SK3880		6.5	1.7	35	1500	—	TO-3P(N)IS	
	2SK4013		6	1.7	45	1400	—	TO-220SIS	
	2SK3566		2.5	6.4	12	470	2SK2718	TO-220SIS	
	2SK3564		3	4.3	17	700	2SK2700	TO-220SIS	
	2SK3798	4	3.5	26	800	—	TO-220SIS		
	2SK3565	5	2.5	28	1150	2SK2717	TO-220SIS		
	2SK3742	5	2.5	25	1150	2SK2717	TO-220SIS		
	2SK3700	5	2.5	28	1150	2SK2610	TO-3P(N)		
	2SK4014	6	2.0	45	1400	—	TO-220SIS		
	2SK4115	7	2.0	45	1650	2SK2749	TO-3P(N)		
	2SK3799	8	1.3	60	2200	—	TO-220SIS		
	2SK3473	9	1.6	38	1450	—	TO-3P(N)		
	2SK3878	9	1.3	60	2200	2SK2611	TO-3P(N)		
	2SK4207	13	0.95	45	2790	—	TO-3P(N)		

### ■ $L^2$ - $\pi$ -MOSV and VI Series ( $V_{DSS} = 30\text{ V to }100\text{ V}$ )

Part Number	$V_{DSS}$ (V)	$I_D$ (A)	$P_D$ (W)	Package	$R_{DS(ON)}$ ( $\Omega$ )				$R_{DS(ON)}$ ( $\Omega$ )				$Q_g$ Typ. (nC)
					Typ.	Max	$V_{GS}$ (V)	$I_D$ (A)	Typ.	Max	$V_{GS}$ (V)	$I_D$ (A)	
2SJ537	-50	-5	0.9	LSTM	0.16	0.19	-10	-2.5	0.27	0.34	-4	-1.3	18
2SJ360	-60	-1	0.5	PW-Mini	0.55	0.73	-10	-0.5	0.86	1.2	-4	-0.5	6.5
2SJ507	-60	-1	0.9	LSTM	0.5	0.7	-10	-0.5	0.72	1.0	-4	-0.5	5.6
2SJ438	-60	-5	25	TO-220NIS	0.16	0.19	-10	-2.5	0.24	0.28	-4	-2.5	22
2SJ378	-60	-5	1.2	TPS	0.16	0.19	-10	-2.5	0.24	0.28	-4	-2.5	22
2SJ349	-60	-20	45	TO-220NIS	0.033	0.045	-10	-10	0.05	0.09	-4	-10	90
2SJ401	-60	-20	100	TO-220FL/SM	0.033	0.045	-10	-10	0.05	0.09	-4	-10	90
2SJ334	-60	-30	45	TO-220NIS	0.029	0.038	-10	-15	0.046	0.06	-4	-15	110
2SJ402	-60	-30	100	TO-220FL/SM	0.029	0.038	-10	-15	0.046	0.06	-4	-15	110
2SJ508	-100	-1	1.5	PW-Mini	1.34	1.9	-10	-0.5	1.68	2.5	-4	-0.5	6.3
2SJ509	-100	-1	0.9	LSTM	1.34	1.9	-10	-0.5	1.68	2.5	-4	-0.5	6.3
2SJ380	-100	-12	35	TO-220NIS	0.15	0.21	-10	-6	0.25	0.32	-4	-6	48
2SJ412	-100	-16	60	TO-220FL/SM	0.15	0.21	-10	-6	0.25	0.32	-4	-6	48
2SJ619	-100	-16	75	TFP	0.15	0.21	-10	-6	0.25	0.32	-4	-6	48
2SJ620	-100	-18	25	TFP	0.063	0.09	-10	-9	0.085	0.12	-4	-9	140
2SJ464	-100	-18	45	TO-220NIS	0.064	0.09	-10	-9	0.085	0.12	-4	-9	140
2SK3506	30	45	100	TO-3P(N)	0.016	0.02	10	25	—	—	—	—	39
2SK2989	50	5	0.9	LSTM	0.12	0.15	10	2.5	0.24	0.33	4	1.3	6.5
2SK2614	50	20	40	DP	0.032	0.046	10	10	0.055	0.08	4	5	25
2SK2507	50	25	30	TO-220NIS	0.034	0.046	10	12	0.058	0.08	4	6	25
2SK2886	50	45	40	TO-220NIS	0.014	0.02	10	25	0.027	0.036	4	25	66
2SK3051	50	45	40	TO-220FL/SM	0.024	0.03	10	25	—	—	—	—	36
2SK2744	50	45	125	TO-3P(N)	0.015	0.02	10	25	—	—	—	—	68
2SK2550	50	45	100	TO-3P(N)	0.024	0.030	10	25	—	—	—	—	36
2SK2551	50	50	150	TO-3P(N)	0.0072	0.011	10	25	—	—	—	—	130
2SK2745	50	50	150	TO-3P(N)	0.007	0.0095	10	25	0.011	0.016	4	25	130

Part Number	$V_{DS}$ (V)	$I_D$ (A)	$P_D$ (W)	Package	$R_{DS(ON)}$ ( $\Omega$ )				$R_{DS(ON)}$ ( $\Omega$ )				Qg Typ. (nC)
					Typ.	Max	$V_{GS}$ (V)	$I_D$ (A)	Typ.	Max	$V_{GS}$ (V)	$I_D$ (A)	
2SK2615	60	2	0.5	PW-Mini	0.23	0.3	10	1	0.33	0.44	4	1	6
2SK2961	60	2	0.9	LSTM	0.2	0.27	10	1	0.26	0.38	4	1	5.8
2SK2229	60	5	1.2	TPS	0.12	0.16	10	2.5	0.2	0.3	4	1.3	12
2SK2782	60	20	40	DP	0.039	0.055	10	10	0.06	0.090	4	5	25
2SK2232	60	25	35	TO-220NIS	0.036	0.046	10	12	0.057	0.08	4	12	38
2SK2311	60	25	40	TO-220FL/SM	0.036	0.046	10	12	0.057	0.08	4	12	38
2SK2385	60	36	40	TO-220NIS	0.022	0.03	10	18	0.04	0.055	4	15	60
2SK2233	60	45	100	TO-3P(N)	0.022	0.03	10	25	0.04	0.055	4	15	60
2SK2266	60	45	65	TO-220FL/SM	0.022	0.03	10	25	0.04	0.055	4	15	60
2SK2376	60	45	100	TO-220FL/SM	0.013	0.017	10	25	0.019	0.025	4	25	110
2SK2398	60	45	100	TO-3P(N)	0.022	0.03	10	25	—	—	—	—	60
2SK2173	60	50	125	TO-3P(N)	0.013	0.017	10	25	0.019	0.025	4	25	110
2SK2445	60	50	125	TO-3P(N)	0.014	0.018	10	25	—	—	—	—	110
2SK2267	60	60	150	TO-3P(L)	0.008	0.011	10	30	0.012	0.015	4	30	170
2SK2313	60	60	150	TO-3P(N)	0.008	0.011	10	30	0.012	0.015	4	30	170
2SK2962	100	1	0.9	LSTM	0.5	0.7	10	0.5	0.65	0.95	4	0.5	6.3
2SK2963	100	1	0.5	PW-Mini	0.5	0.7	10	0.5	0.65	0.95	4	0.5	6.3
2SK2200	100	3	1.3	TPS	0.28	0.35	10	2	0.36	0.45	4	2	13.5
2SK2201	100	3	20	New PW-Mold	0.28	0.35	10	2	0.36	0.45	4	2	13.5
2SK4018	100	3	20	New PW-Mold2	0.28	0.35	10	2	0.35	0.45	4	2	13.5
2SK2399	100	5	20	New PW-Mold	0.17	0.23	10	2.5	0.22	0.3	4	2.5	22
2SK2400	100	5	1.2	TPS	0.17	0.23	10	2.5	0.22	0.3	4	2.5	22
2SK4019	100	5	20	New PW-Mold2	0.17	0.23	10	2.5	0.22	0.3	4	2.5	22
2SK2391	100	20	35	TO-220NIS	0.068	0.085	10	10	0.09	0.13	4	10	50
2SK2314	100	27	75	TO-220AB	0.066	0.085	10	15	0.09	0.13	4	15	50
2SK2789	100	27	60	TO-220FL/SM	0.066	0.085	10	15	0.09	0.13	4	15	50
2SK3387	150	18	100	TFP	0.08	0.12	10	9	0.09	0.18	4	9	57

■  $\pi$ -MOSV Series ( $V_{DS} = 150\text{ V to }250\text{ V}$ )

Applications	Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ ( $\Omega$ )				Qg Typ. (nC)
		$V_{DS}$ (V)	$I_D$ (A)	$P_D$ (W)		$R_{DS(ON)}$ ( $\Omega$ )		$V_{GS}$ (V)	$I_D$ (A)	
						Typ.	Max			
DC-DC converters Monitors Motor controllers	2SJ618	-180	-10	130	TO-3P(N)	—	0.37	-10	-5	18
	2SJ407	-200	-5	30	TO-220NIS	0.8	1.0	-10	-2.5	20
	2SJ567	-200	-2.5	20	New PW-Mold	1.6	2.0	-10	-1.5	10
	2SJ676	-200	-2.5	1.3	TPS	1.6	2.0	-10	-1.5	10
	2SJ680	-200	-2.5	20	New PW-Mold2	1.6	2.0	-10	-1.5	10
	2SJ610	-250	-2	20	PW-Mold	1.85	2.55	-10	-1.0	24
	2SJ512	-250	-5	30	TO-220NIS	1.0	1.25	-10	-2.5	22
	2SJ516	-250	-6.5	35	TO-220NIS	0.6	0.8	-10	-3	29
	2SK3670	150	0.67	0.9	LSTM	1.0	1.7	4	0.5	4.6
	2SK3205	150	5	20	PW-Mold	0.36	0.5	10	2.5	12
	2SK2882	150	18	45	TO-220NIS	0.08	0.12	10	9	57
	2SK3497	180	10	130	TO-3P(N)	—	0.15	10	5	—
	2SK2992	200	1	1.5	PW-Mini	2.2	3.5	10	0.5	3
	2SK2835	200	5	1.3	TPS	0.56	0.8	10	2.5	10
	2SK2381	200	5	25	TO-220NIS	0.56	0.8	10	2.5	10
	2SK2920	200	5	20	New PW-Mold	0.56	0.8	10	2.5	10
	2SK4020	200	5	20	New PW-Mold2	0.52	0.8	10	2.5	10
	2SK2350	200	8.5	30	TO-220NIS	0.26	0.4	10	5	17
	2SK2965	200	11	35	TO-220NIS	0.15	0.26	10	5.5	30
	2SK2382	200	15	45	TO-220NIS	0.13	0.18	10	10	40
	2SK2401	200	15	75	TO-220FL/SM	0.13	0.18	10	10	40
	2SK3625	200	25	100	TO-220FL/SM	0.065	0.082	10	12.5	44
	2SK3444	200	25	125	TFP	0.067	0.082	10	12.5	44
	2SK3176	250	30	150	TO-3P(N)	0.038	0.052	10	15	125
	2SK3462	250	3	20	New PW-Mold	1.2	1.7	10	1.5	12
	2SK4022	250	3	20	New PW-Mold2	1.2	1.7	10	1.5	12
	2SK3342	250	4.5	20	New PW-Mold	0.8	1.0	10	2.5	10
	2SK4021	250	4.5	20	New PW-Mold2	0.8	1.0	10	2.5	10
	2SK2417	250	7.5	30	TO-220NIS	0.42	0.5	10	3.5	20
	2SK2914	250	7.5	20	TO-220AB	0.42	0.5	10	3.5	20
	2SK2508	250	13	45	TO-220NIS	0.18	0.25	10	6.5	40
	2SK2598	250	13	60	TO-220FL/SM	0.18	0.25	10	6.5	40
	2SK2993	250	20	100	TO-220FL/SM	0.082	0.105	10	10	100
2SK3994	250	20	45	TO-220NIS	0.090	0.105	10	10	45	
2SK3388	250	20	125	TFP	0.082	0.105	10	10	100	
2SK3445	250	20	125	TFP	0.09	0.105	10	10	45	
2SK2967	250	30	150	TO-3P(N)	0.048	0.068	10	15	132	
2SK2995	250	30	90	TO-3P(N)IS	0.048	0.068	10	15	132	



■ π-MOSV Series ( $V_{DSS} = 400\text{ V to }700\text{ V}$ )

Applications	Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$				Qg Typ. (nC)
		$V_{DSS}$ (V)	$I_D$ (A)	$P_D$ (W)		$(\Omega)$		$V_{GS}$ (V)	$I_D$ (A)	
						Typ.	Max			
115-Vac switching power supplies Ballast inverters Motor controllers	2SK3498	400	1	20	PW-Mold	4.2	5.5	10	0.5	5.7
	2SK2838	400	5.5	40	TO-220FL/SM	0.84	1.2	10	3	17
	2SK2679	400	5.5	35	TO-220NIS	0.84	1.2	10	3	17
	2SK2952	400	8.5	40	TO-220NIS	0.4	0.55	10	5	34
	2SK2841	400	10	80	TO-220AB	0.4	0.55	10	5	34
	2SK2949	400	10	80	TO-220FL/SM	0.4	0.55	10	5	34
	2SK3499	400	10	80	TFP	0.4	0.55	10	5	34
	2SK3472	450	1	20	New PW-Mold	4.0	4.6	10	0.5	5
	2SK3374	450	1	20	TPS	3.7	4.6	10	5	5
	2SK4023	450	1	20	New PW-Mold2	4.0	4.6	10	0.5	5
	2SK3544	450	13	100	TFP	0.29	0.4	10	6	34
	2SK2998	500	0.5	0.9	LSTM	10	18	10	0.25	3.8
	2SK3302	500	0.5	1.3	TPS	10	18	10	0.25	3.8
	2SK3471	500	0.5	0.5	PW-Mini	10	18	10	0.25	3.8
	2SK2599	500	2	1.3	TPS	2.9	3.2	10	1	9
	2SK3373	500	2	20	New PW-Mold	2.9	3.2	10	1	9
	2SK2862	500	3	25	TO-220NIS	2.9	3.2	10	1	9
	2SK2991	500	5	50	TO-220FL/SM	1.35	1.5	10	2.5	17
	2SK3466	500	5	50	TO-220FL/SM	1.35	1.5	10	2.5	17
	2SK2542	500	8	80	TO-220AB	0.75	0.85	10	4	30
	2SK2776	500	8	65	TO-220FL/SM	0.75	0.85	10	4	30
	2SK3538	500	8	65	TFP	0.75	0.85	10	4	30
	2SK2601	500	10	125	TO-3P(N)	0.56	1.0	10	5	30
	2SK3068	500	12	100	TO-220FL/SM	0.4	0.52	10	6	45
	2SK3398	500	12	100	TFP	0.4	0.52	10	6	45
	2SK2916	500	14	80	TO-3P(N)IS	0.35	0.4	10	7	58
	2SK2917	500	18	90	TO-3P(N)IS	0.21	0.27	10	10	80
	2SK3132	500	50	250	TO-3P(L)	0.07	0.095	10	25	280
	2SK3371	600	1	20	New PW-Mold	6.4	9.0	10	0.5	9
	2SK4026	600	1	20	New PW-Mold2	6.4	9	10	0.5	9
	2SK2846	600	2	1.3	TPS	4.2	5.0	10	1	9
	2SK2865	600	2	20	New PW-Mold	4.2	5.0	10	1	9
	2SK4002	600	2	20	New PW-Mold2	4.2	5	10	1	9
	2SK4003	600	3	20	New PW-Mold2	1.7	2.2	10	1.5	20
	2SK3975	600	3	20	New PW-Mold	1.7	2.2	10	1.5	20
	2SK3085	600	3.5	75	TO-220AB	1.7	2.2	10	1.8	20
	2SK3130	600	6	40	TO-220NIS	1.26	1.55	10	3	30
	2SK2777	600	6	65	TO-220FL/SM	0.9	1.25	10	3	30
	2SK2602	600	6	125	TO-3P(N)	0.9	1.25	10	3	30
	2SK3312	600	6	65	TO-220FL/SM	0.95	1.25	10	3	22
	2SK3438	600	10	80	TFP	0.78	1.0	10	5	28
	2SK2889	600	10	100	TO-220FL/SM	0.54	0.75	10	5	45
	2SK2866	600	10	125	TO-220AB	0.54	0.75	10	5	45
	2SK2699	600	10	150	TO-3P(N)	0.5	0.65	10	6	58
	2SK2953	600	12	90	TO-3P(N)IS	0.31	0.4	10	8	80
2SK3265	700	10	45	TO-220NIS	0.72	1.0	10	5	53	
2SK3453	700	10	80	TO-3P(N)IS	0.72	1.0	10	5	53	

■ π-MOSIII Series ( $V_{DSS} = 800\text{ V to }1000\text{ V}$ )

Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ ( $\Omega$ )				Qg Typ. (nC)
	$V_{DS}$ (V)	$I_D$ (A)	$P_D$ (W)		Typ.	Max	$V_{GS}$ (V)	$I_D$ (A)	
2SK2603	800	3	100	TO-220AB	3.0	3.6	10	1.5	25
2SK2883	800	3	75	TO-220FL/SM	3.0	3.6	10	15	25
2SK2884	800	5	100	TO-220FL/SM	1.9	2.2	10	3.0	34
2SK2746	800	7	150	TO-3P(N)	1.3	1.7	10	3.5	55
2SK2606	800	8	85	TO-3P(N)IS	1.0	1.2	10	4.0	68
2SK2607	800	9	150	TO-3P(N)	1.0	1.2	10	4.0	68
2SK3301	900	1	20	PW-Mold	15	20	10	0.5	6
2SK2845	900	1	40	DP	8.0	9.0	10	0.5	15
2SK2733	900	1	60	TO-220AB	8.0	9.0	10	0.5	15
2SK2608	900	3	100	TO-220AB	3.73	4.3	10	1.5	25
2SK2719	900	3	125	TO-3P(N)	3.7	4.3	10	1.5	25
2SK2847	900	8	85	TO-3P(N)IS	1.05	1.25	10	4.0	58
2SK3017	900	8.5	90	TO-3P(N)IS	1.2	1.4	10	4.0	70
2SK2968	900	10	150	TO-3P(N)	1.05	1.25	10	4	70
2SK2613	1000	8	150	TO-3P(N)	1.4	1.7	10	8.0	65



## 7-1 Alphanumeric Index of Part Numbers

Part Number	Series	Package	Main Characteristics			Page
			V <sub>DSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
2SJ168	$\pi$ MOS-III	S-MINI	-60	-0.2	2	36
2SJ200	$\pi$ -MOSII	TO-3P (N)	-180	-10	0.83	-
2SJ201	$\pi$ -MOSII	TO-3P (L)	-200	-12	0.63	-
2SJ304	L <sup>2</sup> - $\pi$ -MOSIV	TO-220NIS	-60	-14	0.12	-
2SJ305	$\pi$ MOS-III	S-MINI	-30	-0.2	4	36
2SJ312	L <sup>2</sup> - $\pi$ -MOSIV	TO-220FL/SM	-60	-14	0.12	-
2SJ313	$\pi$ -MOSII	TO-220NIS	-180	-1	5	-
2SJ334	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	-60	-30	0.038	43
2SJ338	$\pi$ -MOSII	PW-Mold	-180	-1	5	-
2SJ343	$\pi$ MOS-III	S-MINI	-50	-0.05	50	36
2SJ344	$\pi$ MOS-III	USM	-50	-0.05	50	36
2SJ349	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	-60	-20	0.045	43
2SJ360	L <sup>2</sup> - $\pi$ -MOSV	PW-Mini	-60	-1	0.73	43
2SJ378	L <sup>2</sup> - $\pi$ -MOSV	TPS	-60	-5	0.19	43
2SJ380	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	-100	-12	0.21	43
2SJ401	L <sup>2</sup> - $\pi$ -MOSV	TO-220FL/SM	-60	-20	0.045	43
2SJ402	L <sup>2</sup> - $\pi$ -MOSV	TO-220FL/SM	-60	-30	0.038	43
2SJ407	$\pi$ -MOSV	TO-220NIS	-200	-5	1	44
2SJ412	L <sup>2</sup> - $\pi$ -MOSV	TO-220FL/SM	-100	-16	0.21	43
2SJ438	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	-60	-5	0.19	43
2SJ440	$\pi$ -MOSII	TO-3P (N)IS	-180	-9	0.8	-
2SJ464	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	-100	-18	0.09	43
2SJ507	L <sup>2</sup> - $\pi$ -MOSV	LSTM	-60	-1	0.7	43
2SJ508	L <sup>2</sup> - $\pi$ -MOSV	PW-Mini	-100	-1	1.9	43
2SJ509	L <sup>2</sup> - $\pi$ -MOSV	LSTM	-100	-1	1.9	43
2SJ512	$\pi$ -MOSV	TO-220NIS	-250	-5	1.25	44
2SJ516	$\pi$ -MOSV	TO-220NIS	-250	-6.5	0.8	44
2SJ537	L <sup>2</sup> - $\pi$ -MOSV	LSTM	-50	-5	0.19	43
2SJ567	$\pi$ -MOSV	New PW-Mold	-200	-2.5	2	44
2SJ610	$\pi$ -MOSV	PW-Mold	-250	-2	2.55	44
2SJ618	$\pi$ -MOSV	TO-3P (N)	-180	-10	0.37	44
2SJ619	L <sup>2</sup> - $\pi$ -MOSV	TFP	-100	-16	0.21	43
2SJ620	L <sup>2</sup> - $\pi$ -MOSV	TFP	-100	-18	0.09	43
2SJ668	U-MOSIII	New PW-Mold	-60	-5	0.17	38
2SJ669	U-MOSIII	TPS	-60	-5	0.17	38
2SJ676	$\pi$ -MOSV	TPS	-200	-2.5	2	44
2SJ680	$\pi$ -MOSV	New PW-Mold2	-200	-2.5	2	44
2SJ681	U-MOSIII	New PW-Mold2	-60	-5	0.17	38
2SK1062	$\pi$ MOS-III	S-MINI	60	0.2	1	36
2SK1119	$\pi$ -MOSII .5	TO-220AB	1000	4	3.8	-
2SK1359	$\pi$ -MOSII .5	TO-3P (N)	100	5	3.8	-
2SK1365	$\pi$ -MOSII .5	TO-3P (N)IS	1000	7	1.8	-
2SK1381	L <sup>2</sup> - $\pi$ -MOSIII	TO-3P (N)	100	50	0.032	-
2SK1382	L <sup>2</sup> - $\pi$ -MOSIII	TO-3P (L)	100	60	0.02	-
2SK1486	$\pi$ -MOSIII.5	TO-3P (L)	300	32	0.095	-
2SK1489	$\pi$ -MOSIII.5	TO-3P (L)	1000	12	1	-
2SK1529	$\pi$ -MOSII	TO-3P (N)	180	10	0.83	-
2SK1530	$\pi$ -MOSII	TO-3P (N)	200	12	0.63	-
2SK1544	$\pi$ -MOSIII.5	TO-3P (L)	500	25	0.2	-
2SK1930	$\pi$ -MOSII.5	TO-220FL/SM	1000	4	3.8	-
2SK2009	$\pi$ MOS-III	S-MINI	30	0.2	2	36
2SK2013	$\pi$ -MOSII	TO-220NIS	180	1	5	-

Part Number	Series	Package	Main Characteristics			Page
			V <sub>DSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
2SK2162	$\pi$ -MOSII	PW-Mold	180	1	5	-
2SK2173	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	60	50	0.017	44
2SK2200	L <sup>2</sup> - $\pi$ -MOSV	TPS	100	3	0.35	44
2SK2201	L <sup>2</sup> - $\pi$ -MOSV	New PW-Mold	100	3	0.35	44
2SK2229	L <sup>2</sup> - $\pi$ -MOSV	TPS	60	5	0.16	44
2SK2232	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	60	25	0.046	44
2SK2233	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	60	45	0.03	44
2SK2266	L <sup>2</sup> - $\pi$ -MOSV	TO-220FL/SM	60	45	0.03	44
2SK2267	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (L)	60	60	0.011	44
2SK2274	$\pi$ -MOSII.5	TO-220NIS	700	5	1.7	-
2SK2311	L <sup>2</sup> - $\pi$ -MOSV	TO-220FL/SM	60	25	0.046	44
2SK2313	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	60	60	0.011	44
2SK2314	L <sup>2</sup> - $\pi$ -MOSV	TO-220AB	100	27	0.085	44
2SK2350	$\pi$ -MOSV	TO-220NIS	200	8.5	0.4	44
2SK2376	L <sup>2</sup> - $\pi$ -MOSV	TO-220FL/SM	60	45	0.017	44
2SK2381	$\pi$ -MOSV	TO-220NIS	200	5	0.8	44
2SK2382	$\pi$ -MOSV	TO-220NIS	200	15	0.18	44
2SK2385	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	60	36	0.03	44
2SK2391	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	100	20	0.085	44
2SK2398	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	60	45	0.03	44
2SK2399	L <sup>2</sup> - $\pi$ -MOSV	New PW-Mold	100	5	0.23	44
2SK2400	L <sup>2</sup> - $\pi$ -MOSV	TPS	100	5	0.23	44
2SK2401	$\pi$ -MOSV	TO-220FL/SM	200	15	0.18	44
2SK2417	$\pi$ -MOSV	TO-220NIS	250	7.5	0.5	44
2SK2445	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	60	50	0.018	44
2SK2467	$\pi$ -MOSII	TO-3P (N)IS	180	9	0.8	-
2SK2507	L <sup>2</sup> - $\pi$ -MOSV	TO-220NIS	50	25	0.046	43
2SK2508	$\pi$ -MOSV	TO-220NIS	250	13	0.25	44
2SK2542	$\pi$ -MOSV	TO-220AB	500	8	0.85	45
2SK2550	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	50	45	0.03	43
2SK2551	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	50	50	0.011	43
2SK2598	$\pi$ -MOSV	TO-220FL/SM	250	13	0.25	44
2SK2599	$\pi$ -MOSV	TPS	500	2	3.2	45
2SK2601	$\pi$ -MOSV	TO-3P (N)	500	10	1	45
2SK2602	$\pi$ -MOSV	TO-3P (N)	600	6	1.25	45
2SK2603	$\pi$ -MOSIII	TO-220AB	800	3	3.6	45
2SK2606	$\pi$ -MOSIII	TO-3P (N)IS	800	8	1.2	45
2SK2607	$\pi$ -MOSIII	TO-3P (N)	800	9	1.2	45
2SK2608	$\pi$ -MOSIII	TO-220AB	900	3	4.3	45
2SK2613	$\pi$ -MOSIII	TO-3P (N)	1000	8	1.7	45
2SK2614	L <sup>2</sup> - $\pi$ -MOSV	DP	50	20	0.046	43
2SK2615	L <sup>2</sup> - $\pi$ -MOSV	PW-Mini	60	2	0.3	44
2SK2679	$\pi$ -MOSV	TO-220NIS	400	5.5	1.2	45
2SK2699	$\pi$ -MOSV	TO-3P (N)	600	12	0.65	45
2SK2719	$\pi$ -MOSIII	TO-3P (N)	900	3	4.3	45
2SK2733	$\pi$ -MOSIII	TO-220AB	900	1	9	45
2SK2744	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	50	45	0.02	43
2SK2745	L <sup>2</sup> - $\pi$ -MOSV	TO-3P (N)	50	50	0.0095	43
2SK2776	$\pi$ -MOSV	TO-220FL/SM	500	8	0.85	45
2SK2777	$\pi$ -MOSV	TO-220FL/SM	600	6	1.25	42,45
2SK2782	L <sup>2</sup> - $\pi$ -MOSV	DP	60	20	0.055	44
2SK2789	L <sup>2</sup> - $\pi$ -MOSV	TO-220FL/SM	100	27	0.085	44

Part Number	Series	Package	Main Characteristics			Page
			V <sub>DSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max (Ω)	
2SK2835	π-MOSV	TPS	200	5	0.8	44
2SK2838	π-MOSV	TO-220FL/SM	400	5.5	1.2	45
2SK2841	π-MOSV	TO-220AB	400	10	0.55	45
2SK2845	π-MOSIII	DP	900	1	9	45
2SK2846	π-MOSV	TPS	600	2	5	45
2SK2847	π-MOSIII	TO-3P (N)IS	900	8	1.4	45
2SK2862	π-MOSV	TO-220NIS	500	3	3.2	45
2SK2865	π-MOSV	New PW-Mold	600	2	5	45
2SK2866	π-MOSV	TO-220AB	600	10	0.75	42,45
2SK2882	π-MOSV	TO-220NIS	150	18	0.12	44
2SK2883	π-MOSIII	TO-220FL/SM	800	3	3.6	45
2SK2884	π-MOSIII	TO-220FL/SM	800	5	2.2	45
2SK2886	L <sup>2</sup> -π-MOSV	TO-220NIS	50	45	0.02	43
2SK2889	π-MOSV	TO-220FL/SM	600	10	0.75	45
2SK2914	π-MOSV	TO-220AB	250	7.5	0.5	44
2SK2916	π-MOSV	TO-3P (N)IS	500	14	0.4	45
2SK2917	π-MOSV	TO-3P (N)IS	500	18	0.27	45
2SK2920	π-MOSV	New PW-Mold	200	5	0.8	44
2SK2949	π-MOSV	TO-220FL/SM	400	10	0.55	45
2SK2952	π-MOSV	TO-220NIS	400	8.5	0.55	45
2SK2953	π-MOSV	TO-3P (N)IS	600	15	0.4	45
2SK2961	L <sup>2</sup> -π-MOSV	LSTM	60	2	0.27	44
2SK2962	L <sup>2</sup> -π-MOSV	LSTM	100	1	0.7	44
2SK2963	L <sup>2</sup> -π-MOSV	PW-Mini	100	1	0.7	44
2SK2965	π-MOSV	TO-220NIS	200	11	0.26	44
2SK2967	π-MOSV	TO-3P (N)	250	30	0.068	44
2SK2968	π-MOSIII	TO-3P (N)	900	10	1.25	45
2SK2989	L <sup>2</sup> -π-MOSV	LSTM	50	5	0.15	43
2SK2991	π-MOSV	TO-220FL/SM	500	5	1.5	42,45
2SK2992	π-MOSV	PW-Mini	200	1	3.5	44
2SK2993	π-MOSV	TO-220FL/SM	250	20	0.105	44
2SK2995	π-MOSV	TO-3P (N)IS	250	30	0.068	44
2SK2998	π-MOSV	LSTM	500	0.5	18	45
2SK3017	π-MOSIII	TO-3P (N)IS	900	8.5	1.25	45
2SK3051	L <sup>2</sup> -π-MOSV	TO-220FL/SM	50	45	0.03	43
2SK3068	π-MOSV	TO-220FL/SM	500	12	0.52	45
2SK3085	π-MOSV	TO-220AB	600	3.5	2.2	45
2SK3130	π-MOSV	TO-220NIS	600	6	1.55	45
2SK3131	π-MOSV (HSD)	TO-3P (L)	500	50	0.11	42
2SK3132	π-MOSV	TO-3P (L)	500	50	0.095	42,45
2SK3176	π-MOSV	TO-3P (N)	200	30	0.052	44
2SK3205	π-MOSV	PW-Mold	150	5	0.5	44
2SK3265	π-MOSV	TO-220NIS	700	10	1	45
2SK3301	π-MOSIII	PW-Mold	900	1	20	45
2SK3302	π-MOSV	TPS	500	0.5	18	45
2SK3309	MACH	TO-220FL/SM	450	10	0.65	42
2SK3310	MACH	TO-220NIS	450	10	0.65	42
2SK3312	π-MOSV	TO-220FL/SM	600	6	1.25	42,45
2SK3313	π-MOSV (HSD)	TO-220NIS	500	12	0.62	42
2SK3314	π-MOSV (HSD)	TO-3P (N)	500	15	0.49	42
2SK3342	π-MOSV	New PW-Mold	250	4.5	1	44
2SK3371	π-MOSV	New PW-Mold	600	1	9	45

Part Number	Series	Package	Main Characteristics			Page
			V <sub>DSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max (Ω)	
2SK3373	π-MOSV	New PW-Mold	500	2	3.2	45
2SK3374	π-MOSV	TPS	450	1	4.6	45
2SK3387	L <sup>2</sup> -π-MOSV	TFP	150	18	0.12	44
2SK3388	π-MOSV	TFP	250	20	0.105	44
2SK3398	π-MOSV	TFP	500	12	0.52	45
2SK3399	MACH	TO-220FL/SM	600	10	0.75	42
2SK3403	MACH	TO-220FL/SM	450	13	0.4	42
2SK3417	π-MOSV (HSD)	TO-220FL/SM	500	5	1.8	42
2SK3437	MACH	TO-220FL/SM	600	10	1	42
2SK3438	π-MOSV	TFP	600	10	1	45
2SK3444	π-MOSV	TFP	200	25	0.082	44
2SK3445	π-MOSV	TFP	250	20	0.105	44
2SK3453	π-MOSIV	TO-3P (N)IS	700	10	1	45
2SK3462	π-MOSV	New PW-Mold	250	3	1.7	44
2SK3466	π-MOSV	TFP	500	5	1.5	45
2SK3471	π-MOSV	PW-Mini	500	0.5	18	45
2SK3472	π-MOSV	PW-Mold	450	1	4.6	45
2SK3473	π-MOSIV	TO-3P (N)	900	9	1.6	43
2SK3497	π-MOSV	TO-3P (N)	180	10	0.15	44
2SK3498	π-MOSV	PW-Mold	400	1	5.5	45
2SK3499	π-MOSV	TFP	400	10	0.55	45
2SK3506	π-MOSVI	TO-3P (N)	30	45	0.02	43
2SK3538	π-MOSV	TFP	500	8	0.85	45
2SK3544	π-MOSV	TFP	450	13	0.4	45
2SK3561	π-MOSVI	TO-220SIS	500	8	0.85	40,42,43
2SK3562	π-MOSVI	TO-220SIS	600	6	1.25	40,42,43
2SK3563	π-MOSVI	TO-220SIS	500	5	1.5	40,42,43
2SK3564	π-MOSIV	TO-220SIS	900	3	4.3	43
2SK3565	π-MOSIV	TO-220SIS	900	5	2.5	43
2SK3566	π-MOSIV	TO-220SIS	900	2.5	6.4	43
2SK3567	π-MOSVI	TO-220SIS	600	3.5	2.2	40,43
2SK3568	π-MOSVI	TO-220SIS	500	12	0.52	40,43
2SK3569	π-MOSVI	TO-220SIS	600	10	0.75	40,42,43
2SK3625	π-MOSV	TO-220FL/SM	200	25	0.082	44
2SK3633	π-MOSIV	TO-3P (N)	800	7	1.7	43
2SK3662	U-MOSIII	TO-220NIS	60	35	0.0125	38
2SK3667	π-MOSVI	TO-220SIS	600	7.5	1	40,43
2SK3669	π-MOSVII	New PW-Mold	100	10	0.125	-
2SK3670	π-MOSV	LSTM	150	0.67	1.7	44
2SK3700	π-MOSIV	TO-3P (N)	900	5	2.5	43
2SK3742	π-MOSIV	TO-220SIS	900	5	2.5	43
2SK3743	MACH	TO-220NIS	450	13	0.6	40,42
2SK3754	U-MOSIII	TO-220NIS	30	5	0.089	38
2SK3757	π-MOSVI	TO-220SIS	450	2	2.45	43
2SK3766	π-MOSVI	TO-220SIS	450	2	2.45	43
2SK3767	π-MOSVI	TO-220SIS	600	2	4.5	43
2SK3797	π-MOSVI	TO-220SIS	600	13	0.43	40,42,43
2SK3798	π-MOSIV	TO-220SIS	900	4	3.5	43
2SK3799	π-MOSIV	TO-220SIS	900	8	1.3	43
2SK3842	U-MOSIII	TFP	60	75	0.0058	38
2SK3843	U-MOSIII	TFP	40	75	0.0035	38
2SK3844	U-MOSIII	TO-220NIS	60	45	0.0058	38

Part Number	Series	Package	Main Characteristics			Page
			V <sub>bss</sub> (V)	I <sub>b</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
2SK3845	U-MOSIII	TO-3P (N)	60	70	0.0058	38
2SK3846	U-MOSIII	TO-220NIS	40	26	0.018	38
2SK3847	U-MOSIII	TO-220SM	40	26	0.018	38
2SK3863	$\pi$ -MOSVI	DP	500	5	1.5	43
2SK3868	$\pi$ -MOSVI (HSD)	TO-220SIS	500	5	1.7	42
2SK3869	$\pi$ -MOSVI	TO-220SIS	450	10	0.68	43
2SK3878	$\pi$ -MOSIV	TO-3P (N)	900	9	1.3	43
2SK3879	$\pi$ -MOSIV	TO-220FL/SM	800	6.5	1.7	43
2SK3880	$\pi$ -MOSIV	TO-3P (N)IS	800	6.5	1.7	43
2SK3903	$\pi$ -MOSVI	TO-3P (N)	600	14	0.44	43
2SK3904	$\pi$ -MOSVI	TO-3P (N)	450	19	0.26	43
2SK3905	$\pi$ -MOSVI	TO-3P (N)	500	17	0.31	43
2SK3906	MACH (HSD)	TO-3P (N)	600	20	0.33	42
2SK3907	MACH	TO-3P (N)	500	23	0.23	42
2SK3911	MACH	TO-3P (N)	600	20	0.32	41,42
2SK3934	$\pi$ -MOSVI	TO-220SIS	500	15	0.3	40,43
2SK3935	$\pi$ -MOSVI	TO-220SIS	450	17	0.25	43
2SK3936	MACH (HSD)	TO-3P (N)	500	23	0.25	42
2SK3947	$\pi$ -MOSVI (HSD)	TO-220SIS	600	6	1.4	42
2SK3975	$\pi$ -MOSV	New PW-Mold	600	3	2.2	45
2SK3994	$\pi$ -MOSV	TO-220NIS	250	20	0.105	44
2SK4002	$\pi$ -MOSV	New PW-Mold2	600	2	5	40,45
2SK4003	$\pi$ -MOSV	New PW-Mold2	600	3	2.2	45
2SK4012	$\pi$ -MOSVI	TO-220SIS	500	13	0.4	40,43
2SK4013	$\pi$ -MOSIV	TO-220SIS	800	6	1.7	43
2SK4014	$\pi$ -MOSIV	TO-220SIS	900	6	2	43
2SK4015	$\pi$ -MOSVI (HSD)	TO-220SIS	600	10	0.86	42
2SK4016	$\pi$ -MOSVI (HSD)	TO-220SIS	600	13	0.5	42
2SK4017	U-MOSIII	New PW-Mold2	60	5	0.1	38
2SK4018	L <sup>2</sup> - $\pi$ -MOSV	New PW-Mold2	100	3	0.35	44
2SK4019	L <sup>2</sup> - $\pi$ -MOSV	New PW-Mold2	100	5	0.23	44
2SK4020	$\pi$ -MOSV	New PW-Mold2	200	5	0.8	44
2SK4021	$\pi$ -MOSV	New PW-Mold2	250	4.5	1	44
2SK4022	$\pi$ -MOSV	New PW-Mold2	250	3	1.7	44
2SK4023	$\pi$ -MOSV	New PW-Mold2	450	1	4.6	45
2SK4026	$\pi$ -MOSV	New PW-Mold2	600	1	9	45
2SK4033	U-MOSIII	New PW-Mold	60	5	0.1	38
2SK4034	U-MOSIII	TFP	60	75	0.0058	38
2SK4042	$\pi$ -MOSVI (HSD)	TO-220SIS	500	8	0.97	42
2SK4103	$\pi$ -MOSVI	New PW-Mold	500	5	1.5	43
2SK4107	$\pi$ -MOSVI	TO-3P (N)	500	15	0.4	40,43
2SK4108	$\pi$ -MOSVI	TO-3P (N)	500	20	0.27	40,43
2SK4115	$\pi$ -MOSIV	TO-3P (N)	900	7	2	43
2SK4207	$\pi$ -MOSIV	TO-3P (N)	900	13	0.95	43
S3U72	U-MOSV-H	SOP Advance	30	TBD	TBD	35
S3W16	U-MOSIV-H	SOP Advance	30	(40)	(0.0035)	-
SSM3J01T	$\pi$ -MOSVI	TSM	-20	-1.7	0.4	28
SSM3J02T	$\pi$ -MOSVI	TSM	-30	-1.5	0.5	28
SSM3J05FU	$\pi$ -MOS-VI	USM	-20	-0.2	4	36
SSM3J09FU	$\pi$ -MOS-VI	USM	-30	-0.2	4.2	36
SSM3J108TU	U-MOSIII	UFM	-20	-1.8	0.158	28
SSM3J109TU	U-MOSIII	UFM	-20	-2	0.13	28

Part Number	Series	Package	Main Characteristics			Page
			V <sub>bss</sub> (V)	I <sub>b</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
SSM3J110TU	U-MOSIII	UFM	-12	-2.3	0.094	28
SSM3J111TU	U-MOSIII	UFM	-20	-1	0.48	28
SSM3J112TU	U-MOSII	UFM	-30	-1.1	0.79	28
SSM3J113TU	U-MOSIII	UFM	-20	-1.7	0.169	28
SSM3J114TU	U-MOSIV	UFM	-20	-1.8	0.149	28
SSM3J115TU	U-MOSIV	UFM	-20	-2.2	0.098	28
SSM3J117TU	U-MOSII	UFM	-30	-2	0.225	28
SSM3J118TU	U-MOSII	UFM	-30	-1.4	0.48	28
SSM3J120TU	U-MOSIV	UFM	-20	-4	0.038	28
SSM3J129TU	U-MOSV	UFM	-20	-4.6	0.046	28
SSM3J130TU	U-MOSVI	UFM	-20	-4.4	0.0258	28
SSM3J13T	U-MOSIII	TSM	-12	-3	0.07	28
SSM3J14T	U-MOSII	TSM	-30	-2.7	0.17	28
SSM3J15CT	$\pi$ -MOS-VI	CST3	-30	-0.1	32	36
SSM3J15F	$\pi$ -MOS-VI	S-MINI	-30	-0.1	32	36
SSM3J15FS	$\pi$ -MOS-VI	SSM	-30	-0.1	32	36
SSM3J15FU	$\pi$ -MOS-VI	USM	-30	-0.1	32	36
SSM3J15FV	$\pi$ -MOS-VI	VESM	-30	-0.1	32	36
SSM3J16CT	$\pi$ -MOS-VI	CST3	-20	-0.1	45	36
SSM3J16FS	$\pi$ -MOS-VI	SSM	-20	-0.1	45	36
SSM3J16FU	$\pi$ -MOS-VI	USM	-20	-0.1	45	36
SSM3J16FV	$\pi$ -MOS-VI	VESM	-20	-0.1	45	48
SSM3J304T	U-MOSIII	TSM	-20	-2.3	0.127	28
SSM3J305T	U-MOSII	TSM	-30	-1.7	0.477	28
SSM3J306T	U-MOSII	TSM	-30	-2.4	0.225	28
SSM3J307T	U-MOSV	TSM	-20	-4.7	0.031	28
SSM3J312T	U-MOSIII	TSM	-12	-2.7	0.091	28
SSM3J313T	U-MOSIII	TSM	-30	-1.6	0.268	28
SSM3J314T	U-MOSIII-H	TSM	-30	-3.5	0.1	28
SSM3J317T	U-MOSIII	TSM	-20	-3.6	0.107	28
SSM3J321T	U-MOSV	TSM	-20	-5.2	0.046	28
SSM3J35CT	$\pi$ -MOS-VI	CST3	-20	-0.1	44	36
SSM3J35FS	$\pi$ -MOS-VI	SSM	-20	-0.1	44	36
SSM3J35FV	$\pi$ -MOS-VI	VESM	-20	-0.1	44	36
SSM3J36FS	U-MOSIII	SSM	-20	-0.33	3.6	36
SSM3J36FV	U-MOSIII	VESM	-20	-0.33	3.6	36
SSM3J36TU	U-MOSIII	UFM	-20	-0.33	3.6	36
SSM3J46CTB	U-MOSVI	CST3B	-20	-2	0.103	28
SSM3K01T	$\pi$ -MOSVI	TSM	30	3.2	0.12	29
SSM3K02T	$\pi$ -MOSVI	TSM	30	2.5	0.2	29
SSM3K03FV	$\pi$ -MOS-VI	VESM	20	0.1	12	36
SSM3K04FS	$\pi$ -MOS-VI	SSM	20	0.1	12	36
SSM3K04FU	$\pi$ -MOS-VI	USM	20	0.1	12	36
SSM3K04FV	$\pi$ -MOS-VI	VESM	20	0.1	12	36
SSM3K05FU	$\pi$ -MOS-VI	USM	20	0.4	1.2	36
SSM3K09FU	$\pi$ -MOS-VI	USM	30	0.4	1.2	36
SSM3K101TU	U-MOSIII	UFM	20	2.2	0.103	29
SSM3K102TU	U-MOSIII	UFM	20	2.6	0.071	29
SSM3K104TU	U-MOSIII	UFM	20	3	0.056	29
SSM3K105TU	$\pi$ -MOSVI	UFM	30	2.1	0.2	29
SSM3K106TU	$\pi$ -MOSVII	UFM	20	1.2	0.53	29
SSM3K107TU	$\pi$ -MOSVII	UFM	20	1.5	0.41	29

Part Number	Series	Package	Main Characteristics			Page
			V <sub>bss</sub> (V)	I <sub>b</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
SSM3K116TU	U-MOSIII	UFM	30	2.2	0.1	29
SSM3K119TU	U-MOSIII	UFM	30	2.5	0.08	29
SSM3K121TU	U-MOSIII	UFM	20	3.2	0.048	29
SSM3K122TU	U-MOSIII	UFM	20	2	0.123	29
SSM3K123TU	U-MOSIII	UFM	20	4.2	0.028	29
SSM3K124TU	$\pi$ -MOSVII	UFM	30	2.4	0.12	29
SSM3K127TU	U-MOSIII	UFM	30	2	0.123	29
SSM3K128TU	U-MOSIII	UFM	30	1.5	0.36	29
SSM3K12T	$\pi$ -MOSVII	TSM	30	3	0.175	29
SSM3K131TU	U-MOSIV	UFM	30	5.4	0.0415	29
SSM3K14T	U-MOSII	TSM	30	4	0.067	29
SSM3K15CT	$\pi$ MOS-VI	CST3	30	0.1	7	36
SSM3K15F	$\pi$ -MOS-VI	S-MINI	30	0.1	7	36
SSM3K15FS	$\pi$ -MOS-VI	SSM	30	0.1	7	36
SSM3K15FU	$\pi$ -MOS-VI	USM	30	0.1	7	36
SSM3K15FV	$\pi$ MOS-VI	VESM	30	0.1	7	36
SSM3K16CT	$\pi$ -MOS-VI	CST3	20	0.1	15	36
SSM3K16FS	$\pi$ -MOS-VI	SSM	20	0.1	15	36
SSM3K16FU	$\pi$ -MOS-VI	USM	20	0.1	15	36
SSM3K16FV	$\pi$ -MOS-VI	VESM	20	0.1	15	36
SSM3K17FU	$\pi$ -MOS-V	USM	50	0.1	40	36
SSM3K301T	U-MOSIII	TSM	20	3.5	0.056	29
SSM3K302T	U-MOSIII	TSM	30	3	0.071	29
SSM3K303T	$\pi$ -MOSVII	TSM	30	2.9	0.12	29
SSM3K309T	U-MOSIII	TSM	20	4.7	0.031	29
SSM3K310T	U-MOSIII	TSM	20	5	0.028	29
SSM3K315T	U-MOSIV	TSM	30	6	0.0415	29
SSM3K316T	U-MOSIII	TSM	30	4	0.065	29
SSM3K318T	U-MOSIV	TSM	60	2.5	0.145	29
SSM3K320T	U-MOSIV	TSM	30	4.2	0.077	29
SSM3K35CT	$\pi$ -MOS-VI	CST3	20	0.18	20	36
SSM3K35FS	$\pi$ -MOS-VI	SSM	20	0.18	20	36
SSM3K35MFV	$\pi$ -MOS-VI	VESM	20	0.18	20	36
SSM3K36FS	U-MOSIII	SSM	20	0.5	1.52	36
SSM3K36MFV	U-MOSIII	VESM	20	0.5	1.52	36
SSM3K36TU	U-MOSIII	UFM	20	0.5	1.52	36
SSM3K7002AF	$\pi$ -MOS-V	S-MINI	60	0.2	3.3	36
SSM3K7002AFU	$\pi$ -MOS-V	USM	60	0.2	3.3	36
SSM3K7002F	$\pi$ -MOS-VI	S-MINI	60	0.2	3.3	36
SSM3K7002FU	$\pi$ -MOS-VI	USM	60	0.2	3.3	36
SSM4K27CT	U-MOSIII	CST4	20	0.5	0.205	29
SSM5G01TU	U-MOSII	UFV	-30	-1	0.8	30
SSM5G02TU	U-MOSII	UFV	-12	-1	0.16	30
SSM5G04TU	U-MOSII	UFV	-12	-1	0.24	30
SSM5G09TU	U-MOSII	UFV	-12	-1.5	0.13	30
SSM5G10TU	U-MOSIII	UFV	-20	-1.5	0.213	30
SSM5G11TU	U-MOSIII-H	UFV	-30	-1.4	0.403	30
SSM5H01TU	U-MOSII	UFV	30	1.4	0.45	30
SSM5H03TU	U-MOSIII	UFV	12	1.4	0.3	30
SSM5H05TU	U-MOSIII	UFV	20	1.5	0.16	30
SSM5H07TU	$\pi$ -MOSVII	UFV	20	1.2	0.54	30
SSM5H08TU	U-MOSIII	UFV	20	1.5	0.16	30

Part Number	Series	Package	Main Characteristics			Page
			V <sub>bss</sub> (V)	I <sub>b</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
SSM5H10TU	U-MOSIII	UFV	20	1.6	0.119	30
SSM5H11TU	U-MOSIII	UFV	30	1.6	0.182	30
SSM5H12TU	U-MOSIII	UFV	30	1.9	0.133	30
SSM5H14F	U-MOSIII	SMV	30	3	0.078	31
SSM5N03FE	$\pi$ -MOSVI	ES6	20	0.1	12	36
SSM5N05FU	$\pi$ -MOSVI	US6	20	0.4	1.2	36
SSM5N15FE	$\pi$ -MOSVI	ES6	30	0.1	7	36
SSM5N15FU	$\pi$ -MOSVI	US6	30	0.1	7	36
SSM5N16FE	$\pi$ -MOSVI	ES6	20	0.1	15	36
SSM5N16FU	$\pi$ -MOSVI	US6	20	0.1	15	36
SSM5P05FU	$\pi$ -MOSVI	US6	-20	-0.2	4	36
SSM5P15FE	$\pi$ -MOSVI	ES6	-30	-0.1	32	36
SSM5P15FU	$\pi$ -MOSVI	US6	-30	-0.1	32	36
SSM5P16FE	$\pi$ -MOSVI	ES6	-20	-0.1	45	36
SSM5P16FU	$\pi$ -MOSVI	US6	-20	-0.1	45	36
SSM6E01TU	U-MOSIII	UF6	-12	-1	0.16	30
SSM6E02TU	U-MOSIV	UF6	-20	-1.8	0.136	30
SSM6E03TU	U-MOSIII	UF6	-12	-1.8	0.144	30
SSM6J06FU	$\pi$ -MOSVI	US6	-20	-0.65	0.5	28
SSM6J07FU	$\pi$ -MOSVI	US6	-30	-0.8	0.8	28
SSM6J08FU	U-MOSII	US6	-20	-1.3	0.18	28
SSM6J205FE	U-MOSIII	ES6	-20	-0.8	0.234	28
SSM6J206FE	U-MOSIII	ES6	-20	-2	0.13	28
SSM6J207FE	U-MOSII	ES6	-30	-1.3	0.491	28
SSM6J21TU	U-MOSIII	UF6	-12	-3	0.05	28
SSM6J23FE	U-MOSIII	ES6	-12	-1.2	0.16	28
SSM6J25FE	U-MOSIII	ES6	-20	-0.5	0.26	28
SSM6J26FE	U-MOSIII	ES6	-20	-0.5	0.23	28
SSM6J401TU	U-MOSIII	UF6	-30	-2.5	0.145	28
SSM6J402TU	U-MOSIII	UF6	-30	-2	0.225	28
SSM6J409TU	U-MOSV	UF6	-20	-6.7	0.0221	28
SSM6J50TU	U-MOSIV	UF6	-20	-2.5	0.064	28
SSM6J51TU	U-MOSIV	UF6	-12	-4	0.054	28
SSM6J53FE	U-MOSIV	ES6	-20	-1.8	0.136	28
SSM6K06FU	$\pi$ -MOSVI	US6	20	1.1	0.16	29
SSM6K07FU	$\pi$ -MOSVI	US6	30	1.5	0.22	29
SSM6K08FU	U-MOSII	US6	20	1.6	0.105	29
SSM6K18TU	U-MOSIII	UF6	20	4	0.04	29
SSM6K202FE	U-MOSIII	ES6	30	2.3	0.085	29
SSM6K203FE	U-MOSIII	ES6	20	2.8	0.061	29
SSM6K204FE	U-MOSIII	ES6	20	2	0.126	29
SSM6K208FE	U-MOSIII	ES6	30	1.9	0.133	29
SSM6K210FE	U-MOSIII	ES6	30	1.4	0.371	29
SSM6K211FE	U-MOSIII	ES6	20	3.2	0.047	29
SSM6K22FE	U-MOSIII	ES6	20	1.4	0.17	29
SSM6K24FE	U-MOSIII	ES6	30	0.5	0.145	29
SSM6K25FE	U-MOSIII	ES6	20	0.5	0.145	29
SSM6K30FE	$\pi$ -MOSVII	ES6	20	1.2	0.42	29
SSM6K31FE	$\pi$ -MOSVII	ES6	20	1.2	0.54	29
SSM6K32TU	$\pi$ -MOSV	UF6	60	2	0.44	29
SSM6K34TU	U-MOSIII	UF6	30	3	0.077	29
SSM6K403TU	U-MOSIII	UF6	20	4.2	0.028	29



Part Number	Series	Package	Main Characteristics			Page
			V <sub>bss</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
SSM6K404TU	U-MOSIII	UF6	20	3	0.055	29
SSM6K405TU	U-MOSIII	UF6	20	2	0.123	29
SSM6K406TU	U-MOSIV	UF6	30	4.4	0.0385	29
SSM6K407TU	$\pi$ -MOSV	UF6	60	2	0.44	29
SSM6L05FU	$\pi$ -MOSVI	US6	20	0.4	1.2	36
SSM6L09FU	$\pi$ -MOSVI	US6	30	0.4	1.2	36
SSM6L10TU	U-MOSIII	UF6	20	0.5	0.145	30
SSM6L11TU	U-MOSIII	UF6	20	0.5	0.145	30
SSM6L12TU	U-MOSIII	UF6	30	0.5	0.145	30
SSM6L13TU	U-MOSIII	UF6	20	0.8	0.143	30
SSM6L16FE	$\pi$ -MOSVI	ES6	20	0.1	15	36
SSM6L35FE	$\pi$ -MOSVI	ES6	20	0.18	20	36
SSM6L35FU	$\pi$ -MOSVI	US6	20	0.18	20	36
SSM6L36FE	U-MOSIII	ES6	20	0.5	1.52	36
SSM6L36TU	U-MOSIII	UF6	20	0.5	1.52	36
SSM6L39TU	U-MOSIII	UF6	20	1.6	0.119	30
SSM6L40TU	U-MOSIII	UF6	30	1.6	0.182	30
SSM6N03FE	$\pi$ -MOSVI	ES6	20	0.1	12	36
SSM6N04FU	$\pi$ -MOSVI	US6	20	0.1	12	36
SSM6N05FU	$\pi$ -MOSVI	US6	20	0.4	1.2	36
SSM6N09FU	$\pi$ -MOSVI	US6	30	0.4	1.2	36
SSM6N15FE	$\pi$ -MOSVI	ES6	30	0.1	7	36
SSM6N15FU	$\pi$ -MOSVI	US6	30	0.1	7	36
SSM6N16FE	$\pi$ -MOSVI	ES6	20	0.1	15	36
SSM6N16FU	$\pi$ -MOSVI	US6	20	0.1	15	36
SSM6N17FU	$\pi$ -MOSV	US6	50	0.1	40	36
SSM6N24TU	U-MOSIII	UF6	30	0.5	0.145	30
SSM6N25TU	U-MOSIII	UF6	20	0.5	0.145	30
SSM6N29TU	U-MOSIII	UF6	20	0.8	0.143	30
SSM6N35FE	$\pi$ -MOSVI	ES6	20	0.18	20	36
SSM6N35FU	$\pi$ -MOSVI	US6	20	0.18	20	36
SSM6N36FE	U-MOSIII	ES6	20	0.5	1.52	36
SSM6N36TU	U-MOSIII	UF6	20	0.5	1.52	36
SSM6N37CTD	U-MOSIII	CST6D	20	0.25	5.6	36
SSM6N39TU	U-MOSIII	UF6	20	1.6	0.119	30
SSM6N40TU	U-MOSIII	UF6	30	1.6	0.182	30
SSM6N7002AFU	$\pi$ -MOSV	US6	60	0.2	3.3	36
SSM6N7002FU	$\pi$ -MOSVI	US6	60	0.2	3.3	36
SSM6P05FU	$\pi$ -MOSVI	US6	-20	-0.2	4	36
SSM6P09FU	$\pi$ -MOSVI	US6	-30	-0.2	4.2	36
SSM6P15FE	$\pi$ -MOSVI	ES6	-30	-0.1	32	36
SSM6P15FU	$\pi$ -MOSVI	US6	-30	-0.1	32	36
SSM6P16FE	$\pi$ -MOSVI	ES6	-20	-0.1	45	36
SSM6P16FU	$\pi$ -MOSVI	US6	-20	-0.1	45	36
SSM6P25TU	U-MOSIII	UF6	-20	-0.5	0.26	30
SSM6P26TU	U-MOSIII	UF6	-20	-0.5	0.23	30
SSM6P28TU	U-MOSIII	UF6	-20	-0.8	0.234	30
SSM6P35FE	$\pi$ -MOSVI	ES6	-20	-0.1	44	36
SSM6P35FU	$\pi$ -MOSVI	US6	-20	-0.1	44	36
SSM6P36FE	U-MOSIII	ES6	-20	-0.33	3.6	-
SSM6P36TU	U-MOSIII	UF6	-20	-0.33	3.6	36
SSM6P39TU	U-MOSIII	UF6	-20	-1.5	0.213	30
SSM6P40TU	U-MOSIII	UF6	-30	-1.4	0.403	30
SSM6P41FE	U-MOSV	ES6	-20	-0.72	0.3	30
SSM6P54TU	U-MOSIV	UF6	-20	-1.2	0.228	30
TJ20A10M3	U-MOSVI	TO-220SIS	-100	-20	0.09	38

Part Number	Series	Package	Main Characteristics			Page
			V <sub>bss</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
TK100F04K3	U-MOSIV	TO-220SM(W)	40	100	0.003	37
TK100F06K3	U-MOSIV	TO-220SM(W)	60	100	0.005	37
TK10A50D	$\pi$ -MOSVII	TO-220SIS	500	10	0.72	40
TK10A60D	$\pi$ -MOSVII	TO-220SIS	600	10	0.75	40
TK11A55D	$\pi$ -MOSVII	TO-220SIS	550	11	0.63	40
TK11A60D	$\pi$ -MOSVII	TO-220SIS	600	11	0.65	40
TK12A50D	$\pi$ -MOSVII	TO-220SIS	500	12	0.52	40
TK12A53D	$\pi$ -MOSVII	TO-220SIS	525	12	0.58	40
TK12A60D	$\pi$ -MOSVII	TO-220SIS	600	12	0.55	40
TK12A60U	DTMOSII	TO-220SIS	600	12	0.4	41
TK12D60U	DTMOSII	TO-220(W)	600	12	0.4	41
TK12J55D	$\pi$ -MOSVII	TO-3P(N)	550	12	0.57	40
TK12J60U	DTMOSII	TO-3P(N)	600	12	0.4	41
TK12X53D	$\pi$ -MOSVII	TFP	550	12	0.58	40
TK130F06K3	U-MOSIV	TO-220SM(W)	60	130	0.0034	37
TK13A45D	$\pi$ -MOSVII	TO-220SIS	450	13	0.46	40
TK13A50D	$\pi$ -MOSVII	TO-220SIS	500	13	0.4	40
TK13A50DA	$\pi$ -MOSVII	TO-220SIS	500	12.5	0.47	40
TK13A60D	$\pi$ -MOSVII	TO-220SIS	600	13	0.43	40
TK13A65U	DTMOSII	TO-220SIS	650	13	0.38	41
TK14A55D	$\pi$ -MOSVII	TO-220SIS	550	14	0.37	40
TK150F04K3	U-MOSIV	TO-220SM(W)	40	150	0.0021	37
TK15A50D	$\pi$ -MOSVII	TO-220SIS	500	15	0.3	40
TK15A60D	$\pi$ -MOSVII	TO-220SIS	600	15	0.37	40
TK15A60U	DTMOSII	TO-220SIS	600	15	0.3	41
TK15D60U	DTMOSII	TO-220(W)	600	15	0.3	41
TK15J50D	$\pi$ -MOSVII	TO-3P(N)	500	15	0.4	40
TK15J60T	DTMOSI	TO-3P(N)	600	15	0.28	41
TK15J60U	DTMOSII	TO-3P(N)	600	15	0.3	41
TK16J55D	$\pi$ -MOSVII	TO-3P(N)	550	16	0.37	40
TK18A50D	$\pi$ -MOSVII	TO-220SIS	500	18	0.27	40
TK20A60T	DTMOSI	TO-220SIS	600	20	0.19	41
TK20A60U	DTMOSII	TO-220SIS	600	20	0.19	41
TK20D60T	DTMOSI	TO-220(W)	600	20	0.19	41
TK20D60U	DTMOSII	TO-220(W)	600	20	0.19	41
TK20J50D	$\pi$ -MOSVII	TO-3P(N)	500	20	0.27	40
TK20J60T	DTMOSI	TO-3P(N)	600	20	0.19	41
TK20J60U	DTMOSII	TO-3P(N)	600	20	0.19	41
TK25A10K3	U-MOSIV	TO-220SIS	100	25	0.04	38
TK2Q60D	$\pi$ -MOSVII	NewPW-Mold2	600	2	5	40
TK30A06J3A	U-MOSIII	TO-220SIS	60	30	0.026	38
TK3A60DA	$\pi$ -MOSVII	TO-220SIS	600	2.5	2.8	40
TK40A08K3	U-MOSIV	TO-220SIS	75	40	0.009	39
TK40A10J1	U-MOSIII-H	TO-220SIS	100	40	0.015	39
TK40A10K3	U-MOSIV	TO-220SIS	100	40	0.015	39
TK40D10J1	U-MOSIII-H	TO-220(W)	100	40	0.015	39
TK40J60T	DTMOSI	TO-3P(N)	600	40	0.08	41
TK40P03M1	U-MOSVI-H	D-PAK	30	40	0.0108	35
TK40P04M1	U-MOSVI-H	D-PAK	40	40	0.0103	35
TK40X10J1	U-MOSIII-H	TFP	100	40	0.02	39
TK4A50D	$\pi$ -MOSVII	TO-220SIS	500	4	2	40
TK4A55D	$\pi$ -MOSVII	TO-220SIS	550	4	1.9	40
TK4A55DA	$\pi$ -MOSVII	TO-220SIS	550	3.5	2.45	40
TK4A60D	$\pi$ -MOSVII	TO-220SIS	600	4	1.7	40
TK4A60DA	$\pi$ -MOSVII	TO-220SIS	600	3.5	2.2	40

Part Number	Series	Package	Main Characteristics			Page
			V <sub>DS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max (Ω)	
TK50F15J1	U-MOSIII	TO-220SM(W)	150	50	0.03	37
TK50P03M1	U-MOSVI-H	D-PAK	30	50	0.0075	35
TK50P04M1	U-MOSVI-H	D-PAK	40	50	0.0087	35
TK50X15J1	U-MOSIII-H	TFP	150	50	0.03	39
TK55A10J1	U-MOSIII-H	TO-220SIS	100	55	0.0105	39
TK55D10J1	U-MOSIII-H	TO-220(W)	100	55	0.0105	39
TK5A50D	π-MOSVII	TO-220SIS	500	5	1.5	40
TK5A55D	π-MOSVII	TO-220SIS	550	5	1.88	40
TK5A65D	π-MOSVII	TO-220SIS	650	5	1.45	40
TK60A08J1	U-MOSIII-H	TO-220SIS	75	60	0.0078	39
TK60D08J1	U-MOSIII-H	TO-220(W)	75	60	0.0078	39
TK6A50D	π-MOSVII	TO-220(W)	500	6	1.4	40
TK6A53D	π-MOSVII	TO-220SIS	525	6	1.3	40
TK6A55DA	π-MOSVII	TO-220SIS	550	5.5	1.48	40
TK6A60D	π-MOSVII	TO-220SIS	600	6	1.25	40
TK6A65D	π-MOSVII	TO-220SIS	650	6	1.11	40
TK70A06J1	U-MOSIII-H	TO-220SIS	60	70	0.0064	39
TK70D06J1	U-MOSIII-H	TO-220(W)	60	70	0.0064	39
TK70J04J3	U-MOSIII	TO-3P(N)	40	70	0.0038	38
TK7A50D	π-MOSVII	TO-220SIS	500	7	1.22	40
TK80A08K3	U-MOSIV	TO-220SIS	75	80	0.0045	39
TK80D08K3	U-MOSIV	TO-220(W)	75	80	0.0045	39
TK8A50D	π-MOSVII	TO-220SIS	500	8	0.85	40
TK8A55DA	π-MOSVII	TO-220SIS	550	7.5	1.07	40
TK8A60DA	π-MOSVII	TO-220SIS	600	7.5	1	40
TK8A65D	π-MOSVII	TO-220SIS	650	8	0.84	40
TK9A55DA	π-MOSVII	TO-220SIS	550	8.5	0.86	40
TPC6004	U-MOSIII	VS-6	20	6	0.024	31
TPC6005	U-MOSIII	VS-6	30	6	0.028	31
TPC6006-H	U-MOSIII-H	VS-6	40	3.9	0.075	24,31
TPC6007-H	U-MOSIII-H	VS-6	30	5	0.054	24,31
TPC6011	U-MOSIV	VS-6	30	6	0.024	31
TPC6103	U-MOSIII	VS-6	-12	-5.5	0.035	31
TPC6105	U-MOSIII	VS-6	-20	-2.7	0.11	31
TPC6107	U-MOSIV	VS-6	-20	-4.5	0.055	31
TPC6108	U-MOSIV	VS-6	-30	-4.5	0.06	31
TPC6109-H	U-MOSIII-H	VS-6	-30	-5	0.059	24,31
TPC6111	U-MOSV	VS-6	-20	-5.5	0.04	31
TPC6201	U-MOSII	VS-6	30	2.5	0.095	-
TPC8012-H	π-MOSV	SOP-8	200	1.8	0.4	34
TPC8014	U-MOSIII	SOP-8	30	11	0.014	27
TPC8017-H	U-MOSIII-H	SOP-8	30	15	0.0066	-
TPC8018-H	U-MOSIII-H	SOP-8	30	18	0.0046	-
TPC8020-H	U-MOSIII-H	SOP-8	30	13	0.009	-
TPC8021-H	U-MOSIII-H	SOP-8	30	11	0.017	24,33
TPC8022-H	U-MOSIII-H	SOP-8	40	7.5	0.027	24,34
TPC8025	U-MOSIV	SOP-8	30	11	0.009	27,33
TPC8026	U-MOSIV	SOP-8	30	13	0.0066	27,33
TPC8027	U-MOSIV	SOP-8	30	18	0.0027	27,34
TPC8028	U-MOSIV	SOP-8	30	18	0.0043	27,34
TPC8029	U-MOSIV	SOP-8	30	18	0.0038	27,34
TPC8030	U-MOSIV	SOP-8	30	11	0.0095	27,33
TPC8031-H	U-MOSV-H	SOP-8	30	11	0.0133	24
TPC8032-H	U-MOSIV-H	SOP-8	30	15	0.0065	24,33
TPC8033-H	U-MOSIV-H	SOP-8	30	17	0.0053	24,33

Part Number	Series	Package	Main Characteristics			Page
			V <sub>DS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max (Ω)	
TPC8034-H	U-MOSIV-H	SOP-8	30	18	0.0035	24,34
TPC8045-H	U-MOSVI-H	SOP-8	40	18	0.0039	24,34
TPC8046-H	U-MOSVI-H	SOP-8	40	18	0.0057	24,34
TPC8047-H	U-MOSVI-H	SOP-8	40	16	0.0076	24
TPC8048-H	U-MOSVI-H	SOP-8	60	16	0.0069	25,34
TPC8049-H	U-MOSVI-H	SOP-8	60	13	0.0107	25,34
TPC8050-H	U-MOSVI-H	SOP-8	60	11	0.0145	25,34
TPC8051-H	U-MOSVI-H	SOP-8	80	13	0.0097	25,34
TPC8052-H	U-MOSVI-H	SOP-8	40	12	0.0121	24,34
TPC8053-H	U-MOSVI-H	SOP-8	60	9	0.0232	25,34
TPC8107	U-MOSIII	SOP-8	-30	-13	0.007	27,34
TPC8109	U-MOSIII	SOP-8	-30	-10	0.02	27,34
TPC8110	U-MOSIII	SOP-8	-40	-8	0.025	34
TPC8111	U-MOSIV	SOP-8	-30	-11	0.012	27,34
TPC8112	U-MOSIII	SOP-8	-30	-13	0.006	27,34
TPC8113	U-MOSIV	SOP-8	-30	-11	0.01	27,34
TPC8114	U-MOSIV	SOP-8	-30	-18	0.0045	27,34
TPC8115	U-MOSIV	SOP-8	-20	-10	0.01	27,34
TPC8116-H	U-MOSIII-H	SOP-8	-40	-7.5	0.03	25,34
TPC8117	U-MOSV	SOP-8	-30	-18	0.0039	27,34
TPC8118	U-MOSV	SOP-8	30	13	0.007	27,34
TPC8120	U-MOSVI	SOP-8	-30	-18	0.0095	27,34
TPC8123	U-MOSVI	SOP-8	-30	-11	0.0032	27,34
TPC8207	U-MOSIII	SOP-8	20	6	0.02	27,34
TPC8208	U-MOSIII	SOP-8	20	5	0.05	27,34
TPC8210	U-MOSIII	SOP-8	30	8	0.015	27,34
TPC8211	U-MOSIII	SOP-8	30	5.5	0.036	27,34
TPC8212-H	U-MOSIII-H	SOP-8	30	6	0.021	34
TPC8213-H	U-MOSIII-H	SOP-8	60	5	0.05	25,34
TPC8214-H	U-MOSIII-H	SOP-8	100	2.2	0.18	25,34
TPC8404	π-MOSV/π-MOSV	SOP-8	-250/250	1.1/-0.9	1.7/2.55	34
TPC8405	U-MOSIV/U-MOSIII	SOP-8	-30/30	-4.5/6	0.027	27,34
TPC8406-H	U-MOSIII-H	SOP-8	40	6.5	0.03	25,34
TPC8406-H	U-MOSIII-H	SOP-8	-40	-6.5	0.025	25,34
TPC8A01	High-speed U-MOSIII	SOP-8	30	6	0.018	34
TPC8A01	U-MOSIII	SOP-8	30	8.5/1	0.0056	34
TPC8A02-H	U-MOSIII-H	SOP-8	30	16/1	0.0056	-
TPC8A03-H	U-MOSV-H	SOP-8	30	17/1	0.0036	25,34
TPC8A04-H	U-MOSV-H	SOP-8	30	18/1	0.0133	25,34
TPC8A05-H	U-MOSV-H	SOP-8	30	10/1	0.0066	25,34
TPCA8003-H	U-MOSIII-H	SOP Advance	30	35	0.0046	-
TPCA8004-H	U-MOSIII-H	SOP Advance	30	40	0.009	-
TPCA8005-H	U-MOSIII-H	SOP Advance	30	27	0.067	-
TPCA8006-H	π-MOSVII	SOP Advance	100	18	0.58	35
TPCA8008-H	π-MOSV	SOP Advance	250	4	0.35	25,35
TPCA8009-H	π-MOSV	SOP Advance	150	7	0.45	25,35
TPCA8010-H	π-MOSV	SOP Advance	200	5.5	0.0035	25,35
TPCA8011-H	U-MOSIII-H	SOP Advance	20	40	0.0049	24,35
TPCA8012-H	U-MOSV-H	SOP Advance	30	35	0.009	24,35
TPCA8014-H	U-MOSIII-H	SOP Advance	40	30	0.0054	24,35
TPCA8015-H	U-MOSIII-H	SOP Advance	40	35	0.021	24,35
TPCA8016-H	U-MOSIII-H	SOP Advance	60	25	0.0062	25,35
TPCA8018-H	U-MOSV-H	SOP Advance	30	27	0.0031	24,35
TPCA8019-H	U-MOSV-H	SOP Advance	30	40	0.027	24,35



Part Number	Series	Package	Main Characteristics			Page
			V <sub>bss</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
TPCA8020-H	U-MOSIII-H	SOP Advance	40	7.5	0.027	24,35
TPCA8022-H	U-MOSIII-H	SOP Advance	100	22	0.026	25,35
TPCA8023-H	U-MOSV-H	SOP Advance	30	21	0.0129	24
TPCA8024	U-MOSIV	SOP Advance	30	35	0.0043	27,35
TPCA8025	U-MOSIV	SOP Advance	30	40	0.0036	27,35
TPCA8026	U-MOSIV	SOP Advance	30	45	0.0022	27,35
TPCA8027-H	U-MOSIII	SOP Advance	40	30	0.01	24,35
TPCA8028-H	U-MOSVI-H	SOP Advance	30	50	0.0028	24,35
TPCA8045-H	U-MOSVI-H	SOP Advance	40	46	0.0036	24,35
TPCA8046-H	U-MOSVI-H	SOP Advance	40	38	0.0054	24,35
TPCA8047-H	U-MOSVI-H	SOP Advance	40	32	0.0073	24,35
TPCA8048-H	U-MOSVI-H	SOP Advance	60	35	0.0066	25,35
TPCA8049-H	U-MOSVI-H	SOP Advance	60	28	0.0104	25,35
TPCA8050-H	U-MOSVI-H	SOP Advance	60	24	0.0142	25,35
TPCA8051-H	U-MOSVI-H	SOP Advance	80	28	0.0094	25,35
TPCA8052-H	U-MOSVI-H	SOP Advance	40	20	0.0118	24,35
TPCA8053-H	U-MOSVI-H	SOP Advance	60	15	0.0229	25,35
TPCA8060-H	U-MOSVI-H	SOP Advance	30	45	0.0034	24,35
TPCA8101	U-MOSIII	SOP Advance	-30	-40	0.007	-
TPCA8102	U-MOSIII	SOP Advance	-30	-40	0.006	27,35
TPCA8103	U-MOSIV	SOP Advance	-30	-40	0.0042	27,35
TPCA8104	U-MOSIII	SOP Advance	-60	-40	0.016	35,38
TPCA8105	U-MOSIII	SOP Advance	-12	-6	0.0033	27,35
TPCA8106	U-MOSV	SOP Advance	-30	-40	0.0037	27,35
TPCA8107-H	U-MOSIII-H	SOP Advance	-40	-7.5	0.03	25,35
TPCA8108	U-MOSIII	SOP Advance	-40	-40	0.0095	35
TPCA8A01-H	U-MOSIII-H	SOP Advance	30	36	0.0056	-
TPCA8A02-H	U-MOSV-H	SOP Advance	30	34	0.0053	25,35
TPCA8A04-H	U-MOSV-H	SOP Advance	30	42	(0.0032)	25,35
TPCA8A05-H	U-MOSV-H	SOP Advance	30	10	0.0129	25,35
TPCA8A08-H	U-MOSV-H	SOP Advance	30	38	0.0039	25
TPCC8001-H	U-MOSV-H	TSON Advance	30	(20)	(0.0122)	24,32
TPCC8002-H	U-MOSV-H	TSON Advance	30	(20)	(0.0122)	24,32
TPCC8003-H	U-MOSIV-H	TSON Advance	30	(17)	(0.0169)	24,32
TPCC8005-H	U-MOSV-H	TSON Advance	30	(26)	(0.006)	24,32
TPCC8006-H	U-MOSIV-H	TSON Advance	30	(24)	(0.0069)	24,32
TPCC8007	U-MOSIV	TSON Advance	20	(27)	(0.0055)	27,32
TPCC8008	U-MOSIV	TSON Advance	30	(24)	(0.007)	27,32
TPCC8102	U-MOSV	TSON Advance	-30	(-15)	(0.0185)	27,32
TPCC8103	U-MOSV	TSON Advance	-30	(-18)	(0.013)	27,32
TPCC8A01-H	U-MOSV-H	TSON Advance	30	(21)	(0.0083)	25,32
TPCF8002	U-MOSIV	VS-8	30	7	0.023	31
TPCF8101	U-MOSIII	VS-8	-12	-6	0.028	31
TPCF8102	U-MOSIII	VS-8	-20	-6	0.03	31
TPCF8103	U-MOSIII	VS-8	-20	-2.7	0.11	31
TPCF8104	U-MOSIII	VS-8	-30	-6	0.028	31
TPCF8201	U-MOSIII	VS-8	20	3	0.049	31
TPCF8301	U-MOSIII	VS-8	-20	-2.7	0.11	31
TPCF8302	U-MOSIII	VS-8	-20	-3	0.059	31
TPCF8303	U-MOSIII	VS-8	-20	-3	0.058	31

Part Number	Series	Package	Main Characteristics			Page
			V <sub>bss</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max ( $\Omega$ )	
TPCF8304	U-MOSIV	VS-8	-30	-3.2	0.072	31
TPCF8402	U-MOSIII	VS-8	-30/30	-3.2/4	0.072/0.05	31
TPCF8A01	U-MOSIII	VS-8	20	3	0.049	31
TPCF8B01	U-MOSIII	VS-8	-20	-2.7	0.11	31
TPCL4201	U-MOSV	Chip LGA	20	6	0.031	27,32
TPCL4202	U-MOSV	Chip LGA	30	6	0.04	27,32
TPCL4203	U-MOSV	Chip LGA	24	6	0.036	27,32
TPCM8001-H	U-MOSIII-H	TSSOP Advance	30	20	0.0095	33
TPCM8002-H	U-MOSV-H	TSSOP Advance	30	30	0.0062	24,33
TPCM8003-H	U-MOSV-H	TSSOP Advance	30	21	0.0129	24,33
TPCS8004	$\pi$ -MOSV	TSSOP-8	200	1.3	0.8	33
TPCS8007-H	$\pi$ -MOSV	TSSOP-8	200	1.9	0.45	25,33
TPCS8008-H	$\pi$ -MOSV	TSSOP-8	250	1.7	0.58	25,33
TPCS8009-H	$\pi$ -MOSV	TSSOP-8	150	2.1	0.35	25,33
TPCS8104	U-MOSIV	TSSOP-8	-30	-11	0.012	33
TPCS8105	U-MOSIV	TSSOP-8	-30	-11	0.0135	33
TPCS8204	U-MOSIII	TSSOP-8	20	6	0.017	33
TPCS8208	U-MOSIII	TSSOP-8	20	6	0.017	33
TPCS8209	U-MOSIII	TSSOP-8	20	5	0.03	33
TPCS8210	U-MOSIII	TSSOP-8	20	5	0.03	33
TPCS8211	U-MOSIII	TSSOP-8	20	6	0.024	33
TPCS8212	U-MOSIII	TSSOP-8	20	6	0.024	33
TPCS8213	U-MOSIV	TSSOP-8	20	6	0.013	33
TPCS8214	U-MOSIV	TSSOP-8	30	6	0.0135	33
TPCS8302	U-MOSIII	TSSOP-8	-20	-5	0.0035	33
TPCS8303	U-MOSIV	TSSOP-8	-20	-5	0.021	33
TPCP8001-H	U-MOSIII-H	PS-8	30	7.2	0.016	32
TPCP8003-H	U-MOSIII-H	PS-8	100	2.2	0.19	25,32
TPCP8004	U-MOSIV	PS-8	30	8.3	0.009	27,32
TPCP8005-H	U-MOSV-H	PS-8	30	11	0.0133	24,32
TPCP8006	U-MOSIV	PS-8	20	9.1	0.01	27,32
TPCP8101	U-MOSIII	PS-8	-20	-5.6	0.03	32
TPCP8102	U-MOSIV	PS-8	-20	-7.6	0.018	32
TPCP8103-H	U-MOSIII-H	PS-8	-40	-4.8	0.04	25,32
TPCP8201	U-MOSIII	PS-8	30	4.2	0.05	32
TPCP8202	U-MOSIV	PS-8	30	5.5	0.023	27,32
TPCP8203	U-MOSIII	PS-8	40	4.7	0.04	32
TPCP8301	U-MOSIV	PS-8	-20	-5	0.031	32
TPCP8302	U-MOSIV	PS-8	-20	-5	0.033	32
TPCP8303	U-MOSV	PS-8	-20	-3.8	0.04	32
TPCP8401	U-MOSIII	PS-8	-12/20	-5.5/0.1	0.038/3	32
TPCP8402	U-MOSIII	PS-8	-30/30	-3.4/4.2	0.048/0.072	32
TPCP8403	U-MOSIV/U-MOSIII	PS-8	-40/40	-3.4/4.7	0.170/0.040	32
TPCP8404	U-MOSV/U-MOSIV	PS-8	-30/30	-4/4	0.05/0.05	32
TPCP8A05-H	U-MOSV-H	PS-8	30	TBD	(0.0164)	32
TPCP8AA1	U-MOSII	PS-8	20	1.6	0.105	32
TPCP8BA1	U-MOSII	PS-8	-20	-1.3	0.18	32
TPCP8J01	U-MOSIV	PS-8	-32/50	-6/0.1	0.035	32
TPCT4203	U-MOSIV	STP2	20	6	0.031	27,32
TPCT4204	U-MOSIV	STP2	30	6	0.038	27,32

## 8-1 End-of-Life Products

The part numbers in the left-hand column below are end-of-life or obsolete products. When ordering, please choose from the replacement products in the right-hand column.

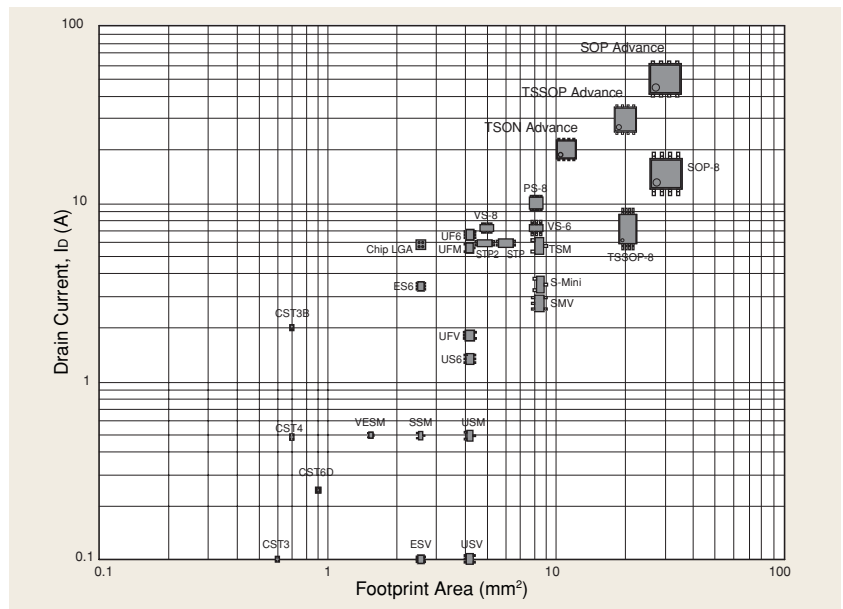
End-of-Life Products					Replacement Products				
Part Number	Electrical Characteristics			Package	Part Number	Electrical Characteristics			Package
	V <sub>DSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max(Ω)			V <sub>DSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max(Ω)	
2SJ148	-60	-0.2	2	TO-92	2SJ168	-60	-0.2	2	S-MINI
2SJ167	-60	-0.2	2	N-MINI	2SJ168	-60	-0.2	2	S-MINI
2SJ200	-16	-2	0.71	PW-Mini	TPC6105	-20	-2.7	0.11	VS-6
2SJ342	-50	-0.05	50	N-MINI	2SJ343	-50	-0.05	50	S-MINI
2SJ345	-20	-0.05	40	S-MINI	SSM3J16FU	-20	-0.1	45	USM
2SJ346	-20	-0.05	40	USM	SSM3J16FU	-20	-0.1	45	USM
2SJ347	-20	-0.05	40	SSM	SSM3J16FS	-20	-0.1	45	SSM
2SJ511	-30	-2	0.76	PW-Mini	TPC6108	-30	-4.5	0.006	VS-6
2SJ525	-30	-5	0.12	TPS	TPCF8104	-30	-6	0.028	VS-8
2SK1061	60	0.2	1	N-MINI	SSM3K7002FU	60	0.2	3	USM
2SK1120	1000	8	1.8	TO-3P(N)	2SK2613	1000	8	1.7	TO-3P(N)
2SK1825	50	0.05	50	N-MINI	SSM3K7002F	60	0.2	3	S-MINI
2SK1826	50	0.05	50	S-MINI	SSM3K7002F	60	0.2	3	S-MINI
2SK1827	50	0.05	50	USM	SSM3K7002FU	60	0.2	3	USM
2SK1828	20	0.05	40	S-MINI	SSM3K15F	30	0.1	7	S-MINI
2SK1829	20	0.05	40	USM	SSM3K15FU	30	0.1	7	USM
2SK1830	20	0.05	40	SSM	SSM3K15FS	30	0.1	7	SSM
2SK2033	20	0.1	12	S-MINI	SSM3K15F	30	0.1	7	S-MINI
2SK2034	20	0.1	12	USM	SSM3K15FU	30	0.1	7	USM
2SK2035	20	0.1	12	SSM	SSM3K15FS	30	0.1	7	SSM
2SK2036	20	0.1	6	S-MINI	SSM3K15F	30	0.1	7	S-MINI
2SK2037	20	0.1	6	USM	SSM3K15FU	30	0.1	7	USM
2SK2312	60	45	0.017	TO-220NIS	2SK3844	60	45	0.0058	TO-220NIS
2SK2466	100	30	0.046	TO-220NIS	TK40A10K3	100	40	0.015	TO-220SIS
2SK2543	500	8	0.85	TO-220NIS	TK8A50D	500	8	0.85	TO-220SIS
2SK2544	600	6	1.25	TO-220AB	2SK3761	600	6	1.25	TO-220AB
2SK2545	600	6	1.25	TO-220NIS	TK6A60D	600	6	1.25	TO-220SIS
2SK2549	16	2	0.29	PW-Mini	TPC6004	20	6	0.024	VS-6
2SK2604	800	5	2.2	TO-3P(N)	2SK3633	800	7	1.7	TO-3P(N)
2SK2605	800	5	2.2	TO-220NIS	2SK4013	800	6	1.7	TO-220SIS
2SK2610	900	5	2.5	TO-3P(N)	2SK3700	900	5	2.5	TO-3P(N)
2SK2611	900	9	1.4	TO-3P(N)	2SK3878	900	9	1.3	TO-3P(N)
2SK2661	500	5	1.5	TO-220AB	2SK3758	500	5	1.5	TO-220AB
2SK2662	500	5	1.5	TO-220NIS	TK5A50D	500	5	1.5	TO-220SIS
2SK2698	500	15	0.4	TO-3P(N)	TK15J50D	500	15	0.4	TO-3P(N)
2SK2700	900	3	4.3	TO-220NIS	2SK3564	900	3	4.3	TO-220SIS
2SK2717	900	5	2.5	TO-220NIS	2SK3565	900	5	2.5	TO-220SIS
2SK2718	900	2.5	6.4	TO-220NIS	2SK3566	900	2.5	6.4	TO-220SIS
2SK2746	800	7	1.7	TO-3P(N)	2SK3633	800	7	1.7	TO-3P(N)
2SK2749	900	7	2	TO-3P(N)	2SK4115	900	7	2	TO-3P(N)
2SK2750	600	3.5	2.2	TO-220NIS	TK4A60DA	600	3.5	2.2	TO-220SIS
2SK2823	20	0.1	40	S-MINI	SSM3K35FU	20	0.1	20	USM
2SK2824	20	0.1	40	USM	SSM3K35FU	20	0.1	20	USM
2SK2825	20	0.1	40	SSM	SSM3K35FS	20	0.1	20	SSM
2SK2837	500	20	0.27	TO-3P(N)	TK20J50D	500	20	0.27	TO-3P(N)
2SK2842	500	12	0.52	TO-220NIS	TK12A50D	500	12	0.52	TO-220SIS
2SK2843	600	10	0.75	TO-220NIS	TK10A60D	600	10	0.75	TO-220SIS
2SK2844	30	35	0.02	TO-220AB	TK70D06J1	60	70	0.0064	TO-220(W)
2SK2915	600	16	0.4	TO-3P(N)	2SK3903	600	14	0.44	TO-3P(N)
2SK2996	600	10	1	TO-220NIS	2SK4112	600	10	1	TO-220HIS

End-of-Life Products					Replacement Products				
Part Number	Electrical Characteristics			Package	Part Number	Electrical Characteristics			Package
	V <sub>DSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max(Ω)			V <sub>DSS</sub> (V)	I <sub>D</sub> (A)	R <sub>DS(ON)</sub> Max(Ω)	
2SK2964	30	2	0.18	PW-Mini	TPC6003	30	6	0.024	VS-6
2SK3067	600	2	5	TO-220NIS	2SK3767	600	2	4.5	TO-220SIS
2SK3084	100	30	0.046	TO-220FL/SM	—	—	—	—	—
2SK3089	30	40	0.03	TO-220FL/SM	2SK3847	40	32	0.018	TO-220SM
2SK3090	30	45	0.02	TO-220FL/SM	2SK3847	40	32	0.018	TO-220SM
2SK3125	30	70	0.007	TO-3PSM	2SK3843	40	75	0.0035	TFP
2SK3126	450	10	0.65	TO-220NIS	2SK3869	450	10	0.68	TO-220SIS
2SK3127	30	45	0.012	TO-220FL/SM	2SK3847	40	32	0.018	TO-220SM
2SK3128	30	60	0.012	TO-3P(N)	2SK3843	40	75	0.0035	TFP
2SK3129	50	60	0.007	TO-3P(N)	2SK3845	60	70	0.0058	TO-3P(N)
2SK3130	600	6	1.55	TO-220NIS	2SK3947	600	6	1.4	TO-220SIS
2SK3236	60	35	0.02	TO-220NIS	2SK3662	60	35	0.0125	TO-220NIS
2SK3316	500	5	1.8	TO-220NIS	2SK3868	500	5	1.7	TO-220NIS
2SK3389	30	75	0.005	TFP	2SK3843	40	75	0.008	TFP
2SK3397	30	75	0.006	TFP	2SK3843	40	75	0.0035	TFP
2SK3407	450	10	0.65	TO-220NIS	2SK3869	450	10	0.68	TO-220SIS
2SK3439	30	75	0.005	TFP	2SK3843	40	75	0.0035	TFP
2SK3440	60	50	0.008	TFP	2SK3842	60	75	0.0058	TFP
2SK3441	60	75	0.0058	TFP	2SK4034	60	75	0.0058	TFP
2SK3442	100	45	0.02	TFP	TK40D10J1	100	40	0.015	TO-220(W)
2SK3443	150	30	0.055	TFP	TK50X15J1	150	50	0.03	TFP
2SK3499	400	10	0.55	TFP	TK10X40D *	400	10	0.55	TFP
2SK3543	450	2	2.45	TO-220NIS	2SK3757	450	2	2.45	TO-220SIS
2SK982	60	0.2	1	TO-92	SSM3K7002F	60	0.2	3	S-MINI
HN1J02FU	-20	-0.05	40	US6	SSM6P16FU	-20	-0.1	45	US6
HN1K02FU	20	0.05	40	US6	SSM6N16FU	20	0.1	15	US6
HN1K03FU	20	0.1	12	US6	SSM6N16FU	20	0.1	15	US6
HN1K04FU	50	0.05	50	US6	SSM6N7002FU	60	0.2	3	US6
HN1K05FU	20	0.1	40	US6	SSM6N35FU	20	0.1	20	US6
HN1K06FU	20	0.1	6	US6	SSM6N15FU	30	0.1	7	US6
HN1L02FU	20	0.05	40	US6	SSM6L35FU	20	0.1	20	US6
HN1L03FU	50	0.05	50	US6	—	—	—	—	—
HN4K03JU	20	0.1	12	US6	SSM5N15FU	30	0.1	7	USV
SSM3J01F	-30	-0.7	0.6	S-MINI	SSM3J01T	-30	-1.7	0.6	TSM
SSM3J02F	-30	-0.6	0.7	S-MINI	SSM3J02T	-30	-1.6	0.7	TSM
SSM3J15TE	-30	-0.1	32	TESM	SSM3J15FV	-30	-0.1	32	VESM
SSM3J16TE	-20	-0.1	45	TESM	SSM3J16FV	-20	-0.1	45	VESM
SSM3K01F	30	1.3	0.15	S-MINI	SSM3K01T	30	3.2	0.15	TSM
SSM3K02F	30	1	0.25	S-MINI	SSM3K02T	30	2.5	0.25	TSM
SSM3K03C	20	0.1	12	SS-CSP	SSM3K16CT	20	0.1	15	CST3
SSM3K03FE	20	0.1	12	ESM	SSM3K16FS	20	0.1	15	SSM
SSM3K03TE	20	0.1	12	TESM	SSM3K16FV	20	0.1	15	VESM
SSM3K04FE	20	0.1	12	ESM	SSM3K04FS	20	0.1	12	SSM
SSM3K126TU	30	3.9	0.043	UFM	SSM3K131TU	30	6	0.0415	UFM
SSM3K15TE	30	0.1	7	TESM	SSM3K15FV	30	0.1	7	VESM
SSM3K16TE	20	0.1	15	TESM	SSM3K16FV	20	0.1	15	VESM
SSM3K311T	30	4.6	0.043	TSM	SSM3K315T	30	6	0.0415	TSM
SSM6G06FE	-20	-0.1	45	ES6	—	—	—	—	—
SSM6H06FE	20	0.1	15	ES6	—	—	—	—	—
TPC6106	-40	-3.9	0.08	VS-6	—	—	—	—	—
TPCT4201	20	6	0.031	STP	TPCT4203	20	6	0.031	STP2
TPCT4202	30	6	0.038	STP	TPCT4204	30	6	0.038	STP2
TPC6201	30	2.5	0.095	VS-6	TPCP8202	30	5.5	0.023	PS-8
TPC8301	-30	-3.5	0.12	SOP-8	TPCF8304	-30	3.2	0.105	SOP-8
TPC8303	-30	-4.5	0.035	SOP-8	—	—	—	—	—

\*: Under development


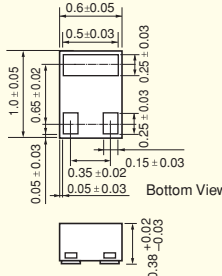
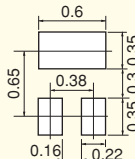
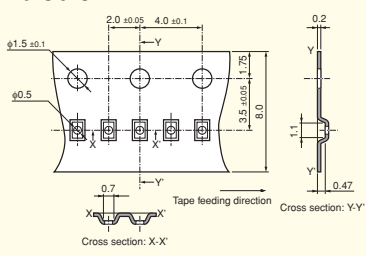
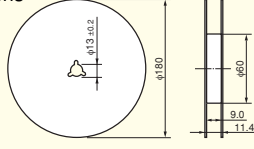
## 9-1 Compact Surface-Mount Packages

Toshiba offers a broad range of packaging options suitable for various mobile applications, including ultra-small, thin packages; those specifically designed for lithium-ion battery protection circuits; high-current packages with a thermal fin on the bottom.




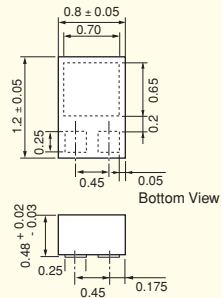

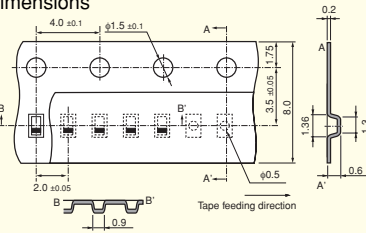
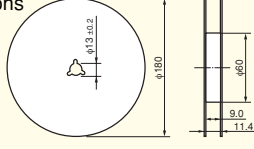
### ■ CST3

Unit: mm

	<p>Package dimensions</p> 	<p>Typical PCB land pad dimensions</p> 	<p>Tape dimensions</p> 
	<p>Reel dimensions</p> 		<p>Packing quantity</p> <p>10000 pcs/reel</p>

### ■ CST3B

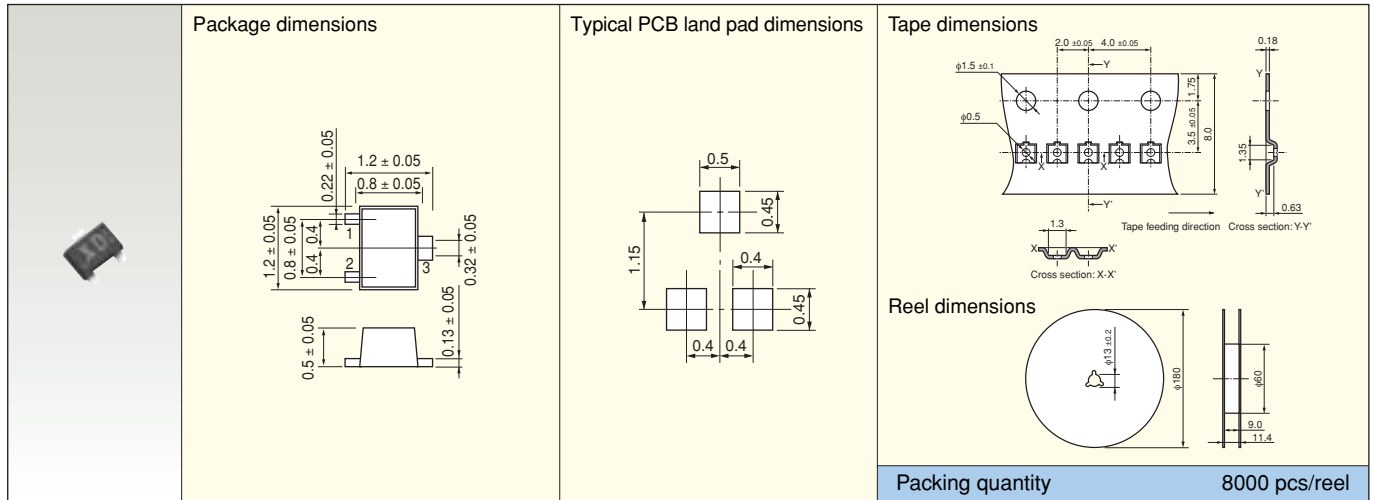
Unit: mm

	<p>Package dimensions <span style="border: 1px solid black; padding: 2px;">Preliminary</span></p> 	<p>Typical PCB land pad dimensions</p> 	<p>Tape dimensions</p> 
	<p>Reel dimensions</p> 		<p>Packing quantity</p> <p>10000 pcs/reel</p>

## 9-1 Compact Surface-Mount Packages

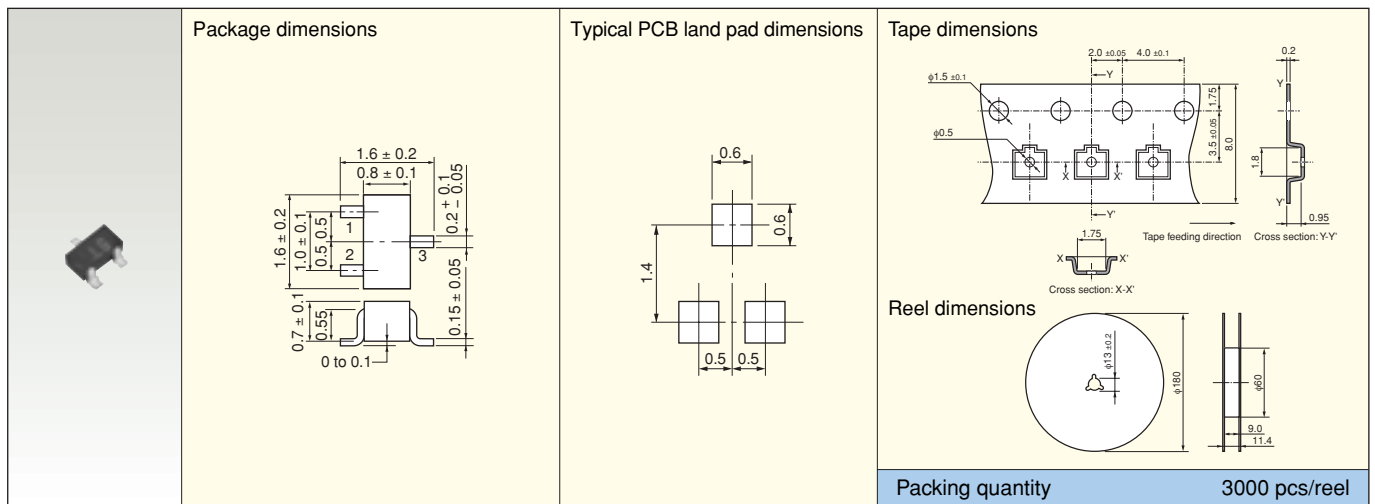
### ■ VESM (SOT-723)

Unit: mm



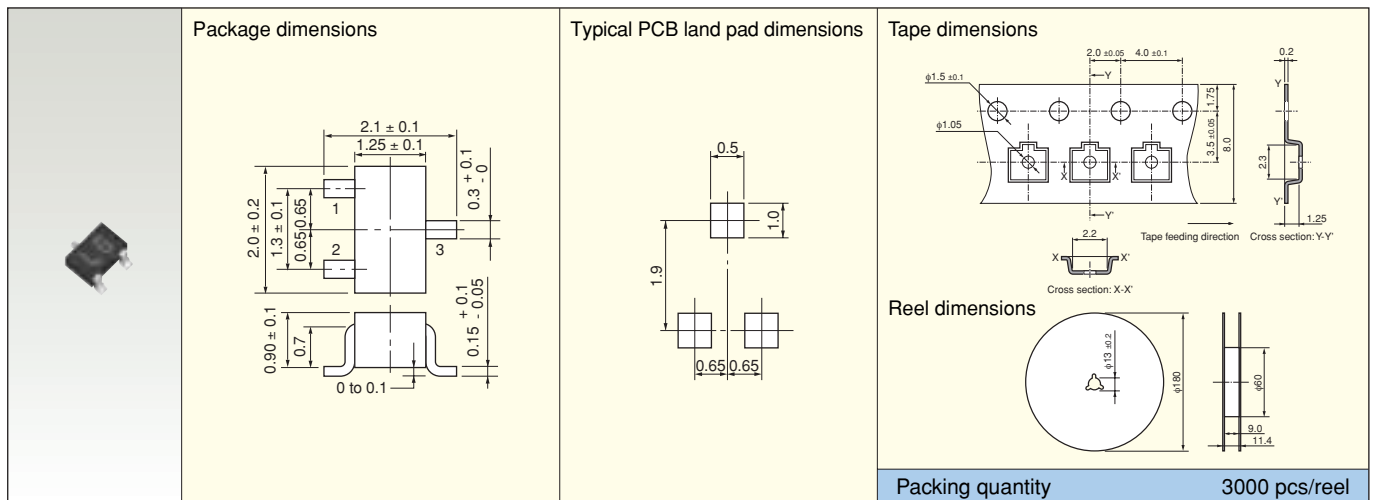
### ■ SSM (SOT-416)(SC-75)

Unit: mm



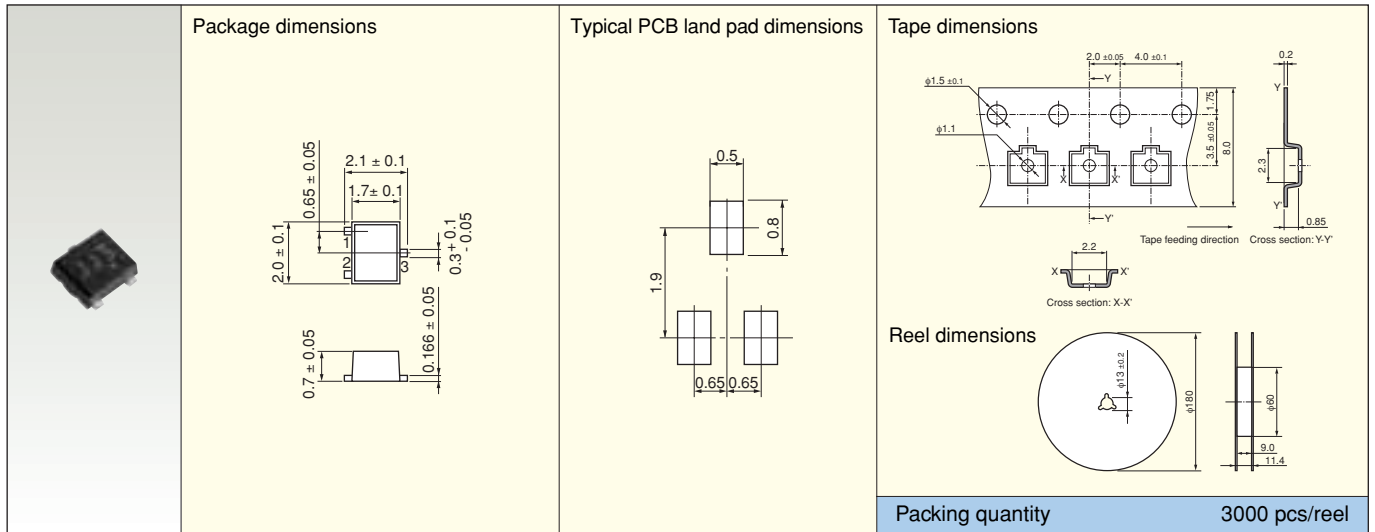
### ■ USM (SOT-323)(SC-70)

Unit: mm



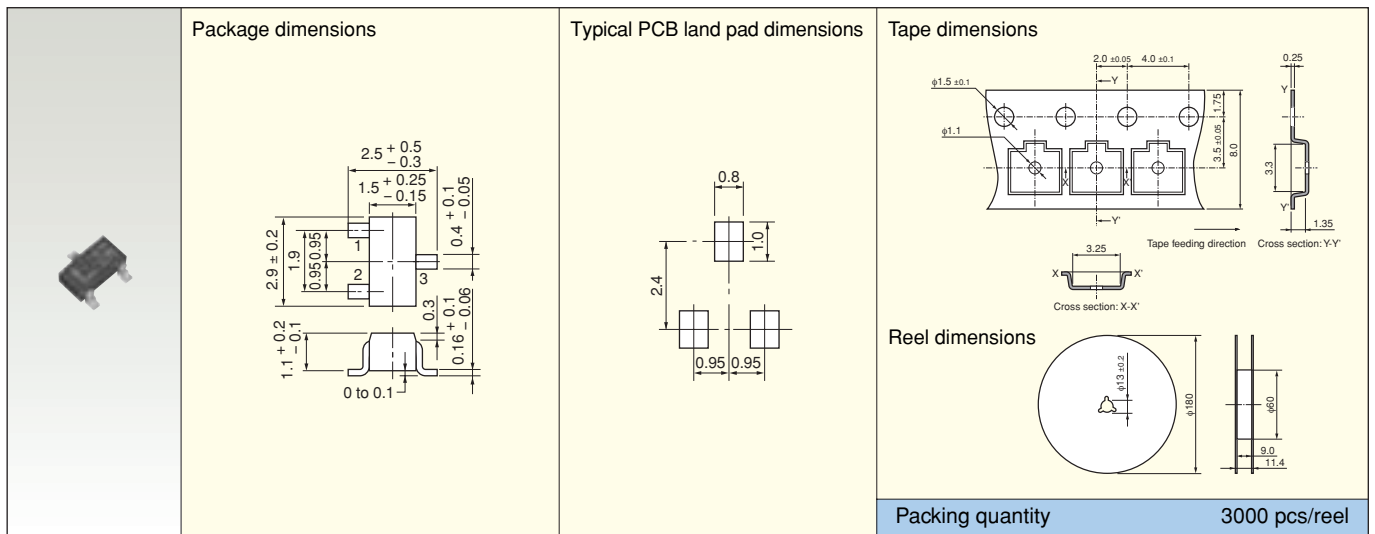
■ UFM

Unit: mm



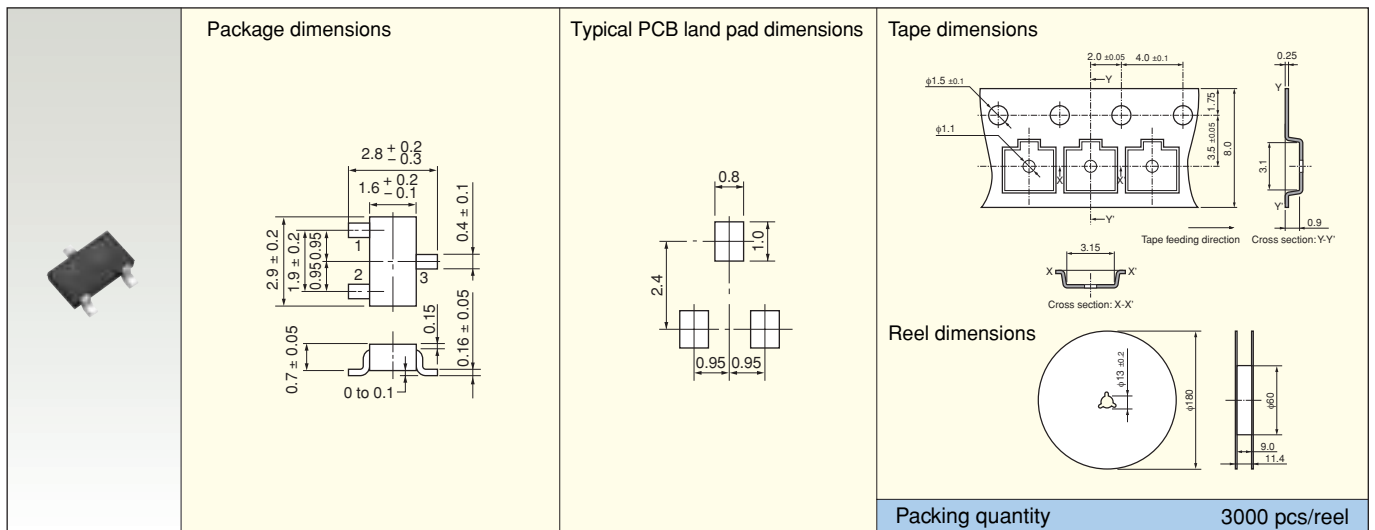
■ S-Mini (SOT-346)(SC-59)

Unit: mm



■ TSM

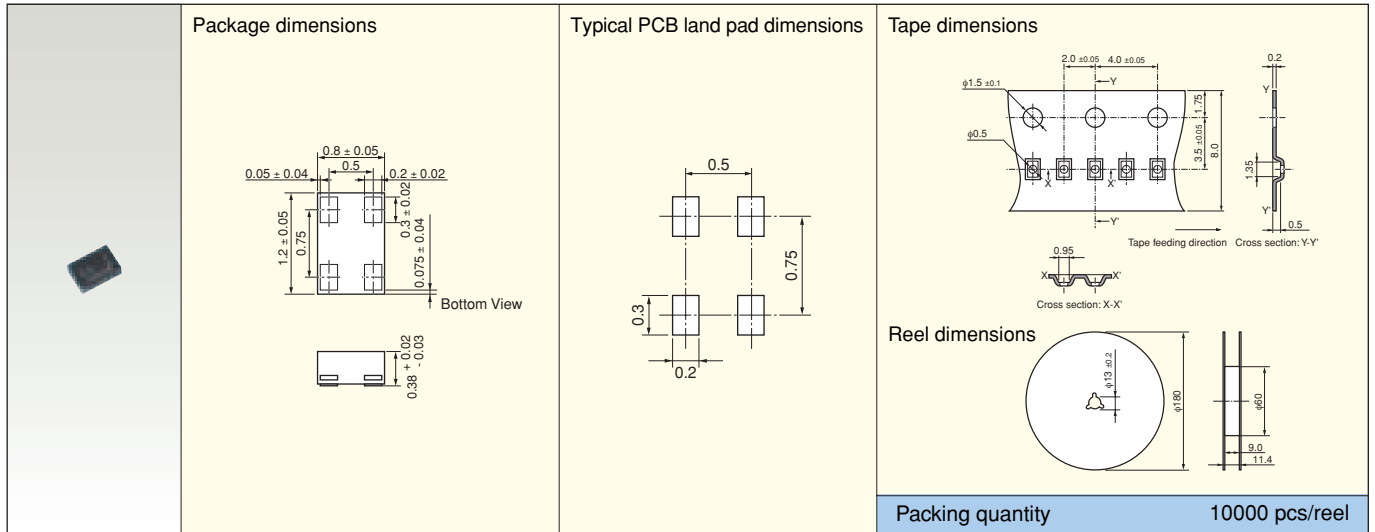
Unit: mm





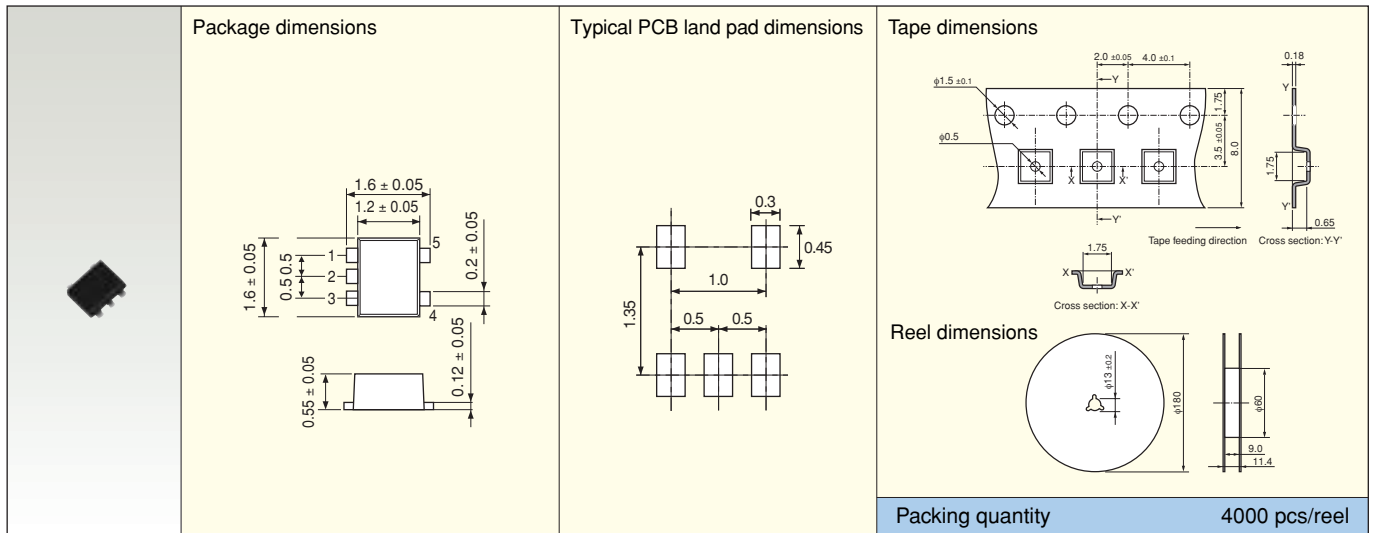
## ■ CST4

Unit: mm



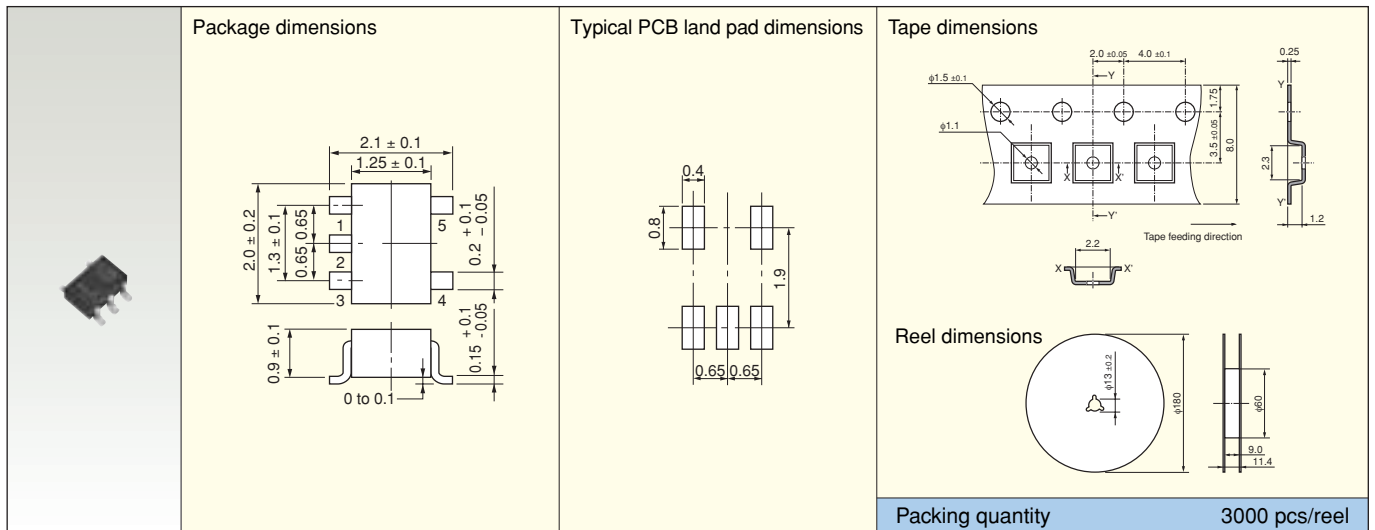
## ■ ESV (SOT-553)

Unit: mm



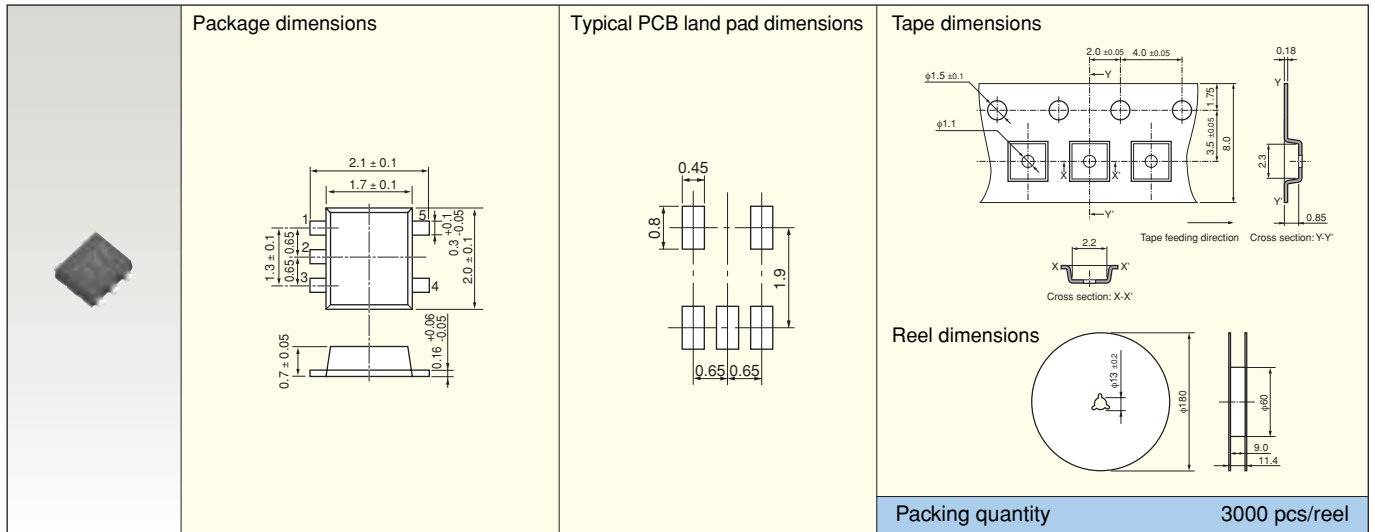
## ■ USV (SOT-353)(SC-88A)

Unit: mm



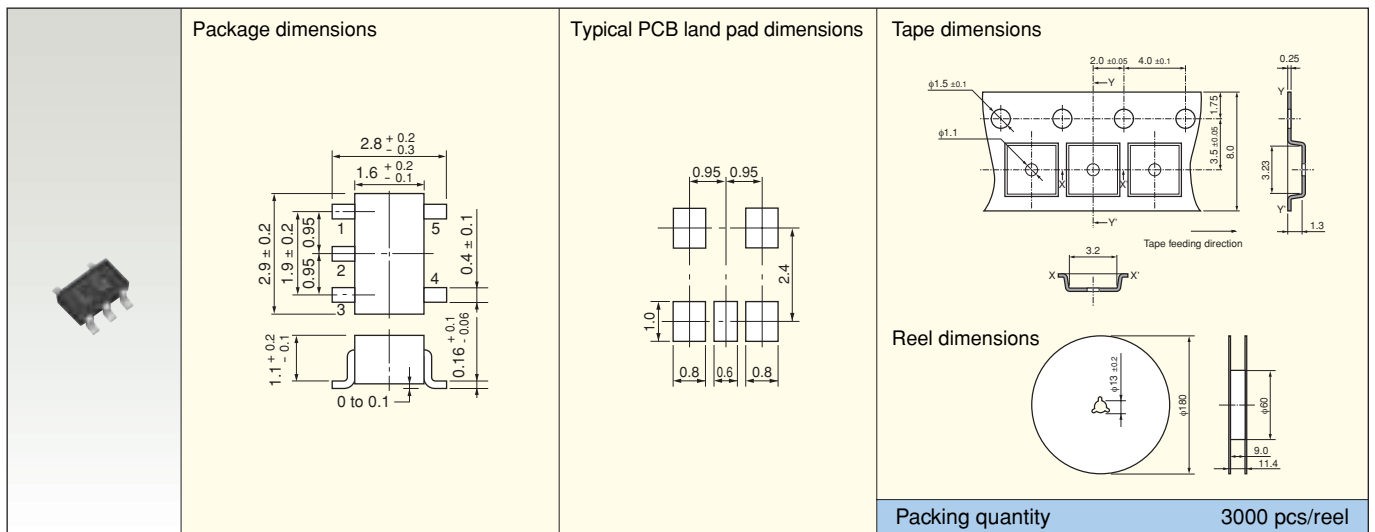
■ UFV

Unit: mm



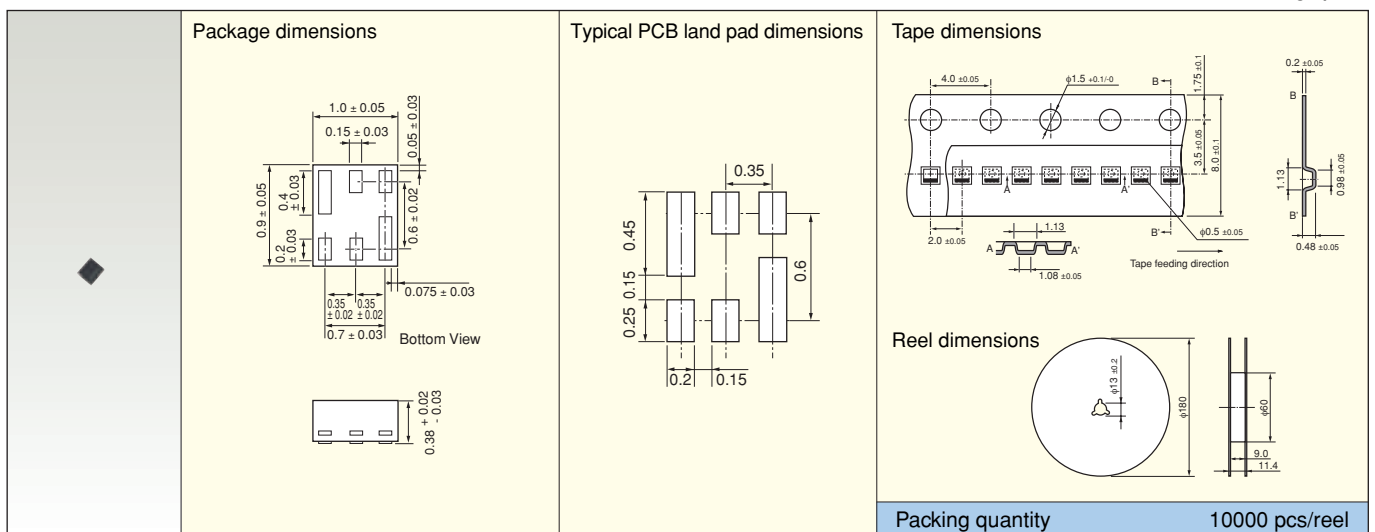
■ SMV (SOT-25)(SC-74A)

Unit: mm



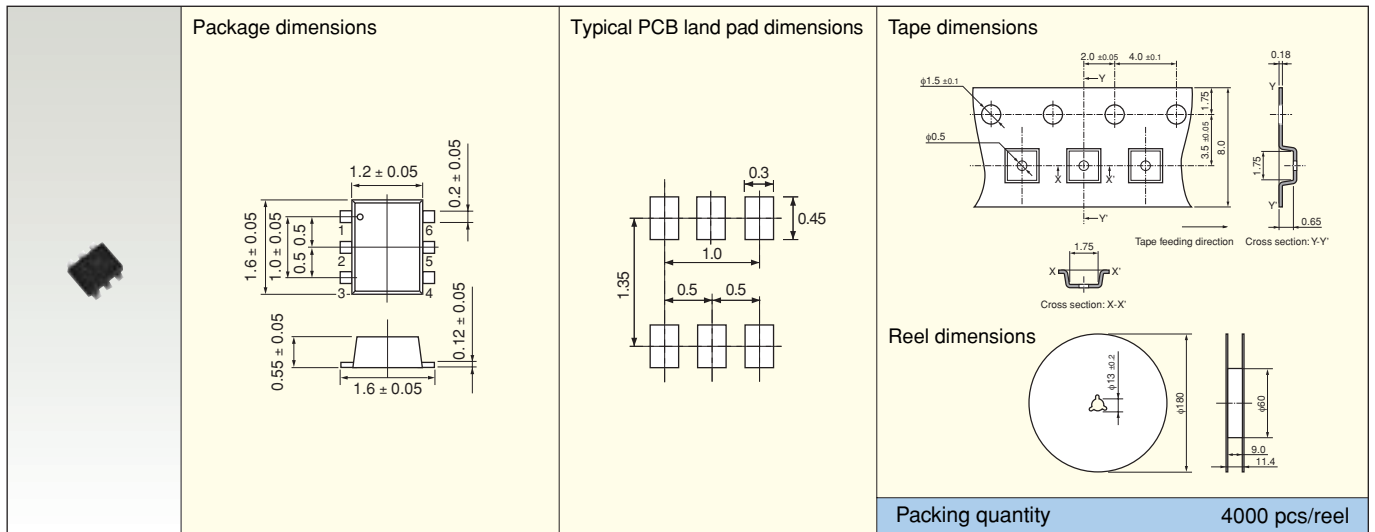
■ CST6D

Unit: mm



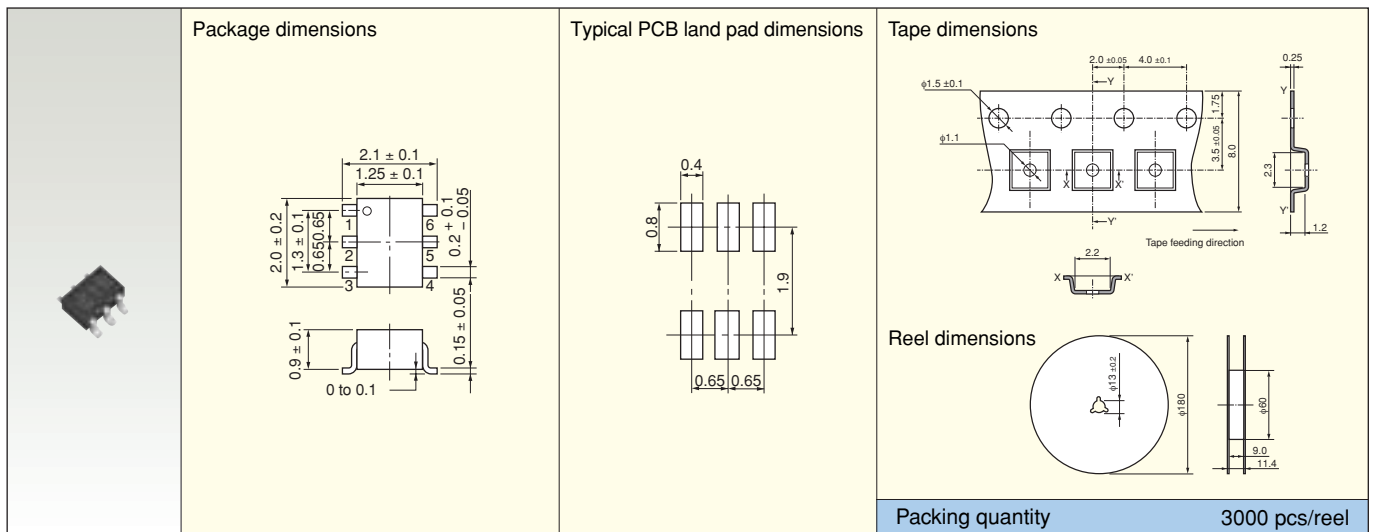
## ■ ES6 (SOT-563)

Unit: mm



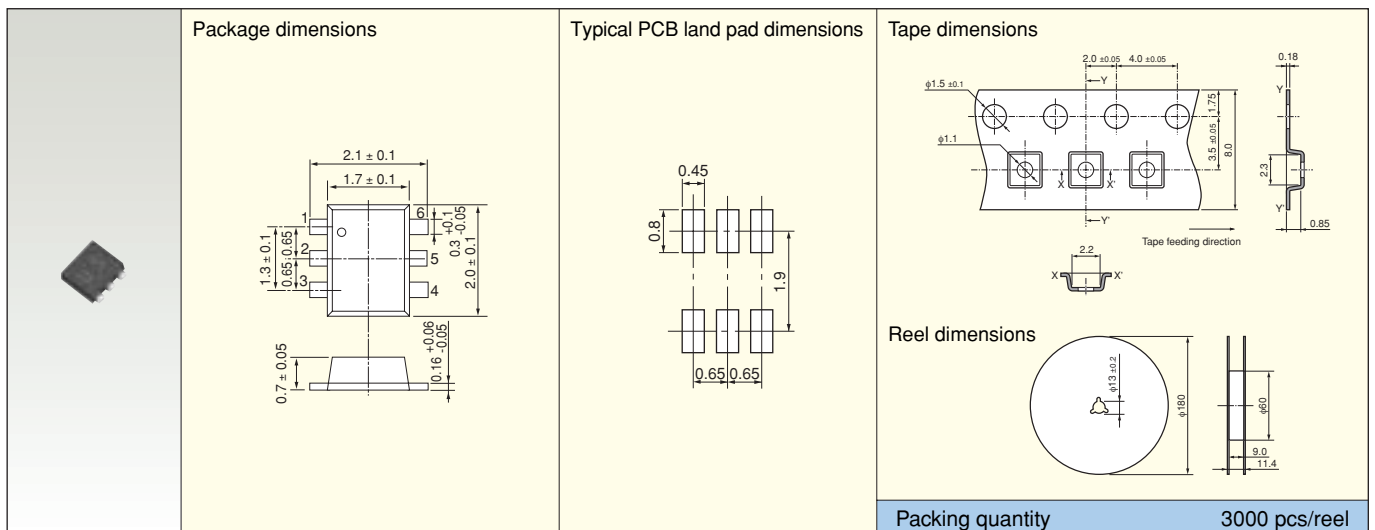
## ■ US6 (SOT-363)(SC-88)

Unit: mm



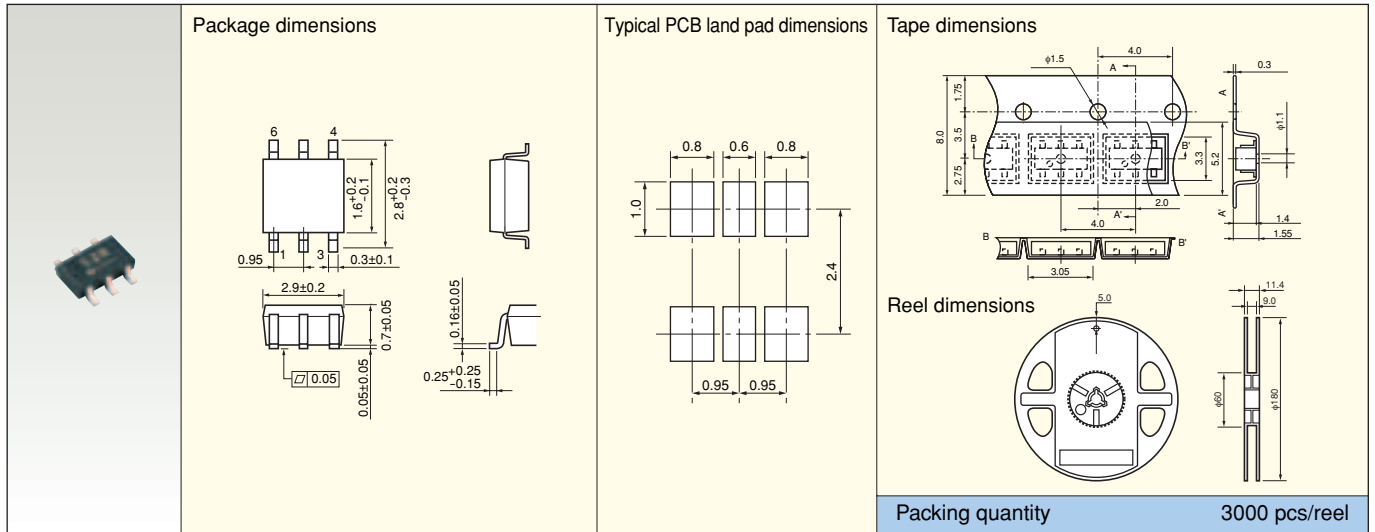
## ■ UF6

Unit: mm



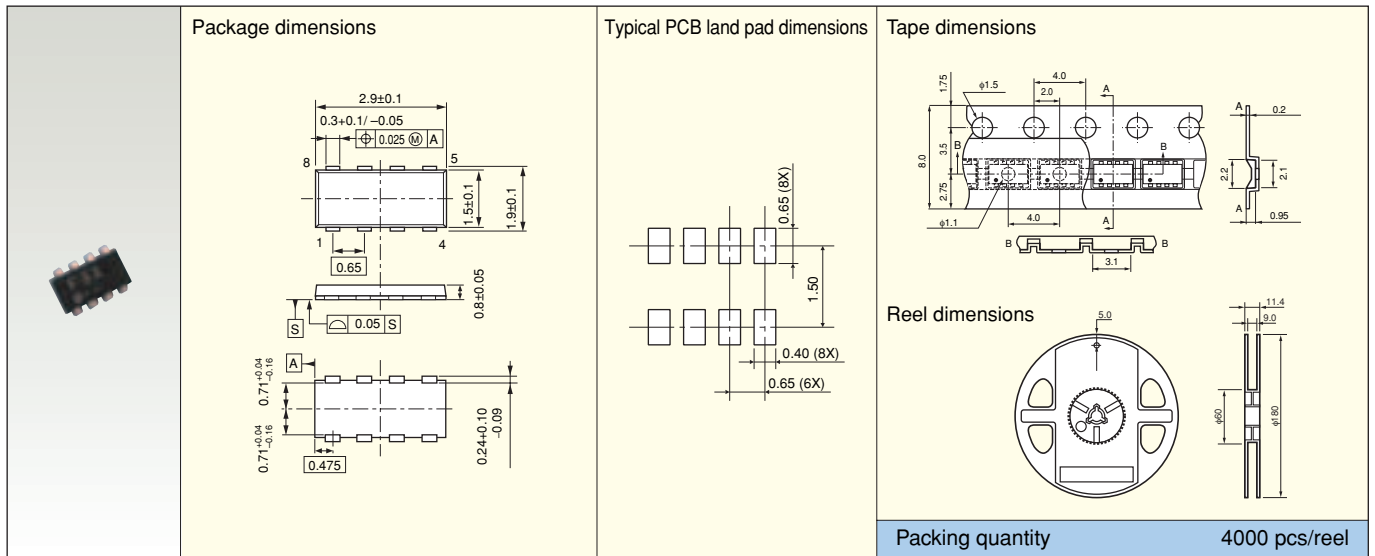
■ VS-6

Unit: mm



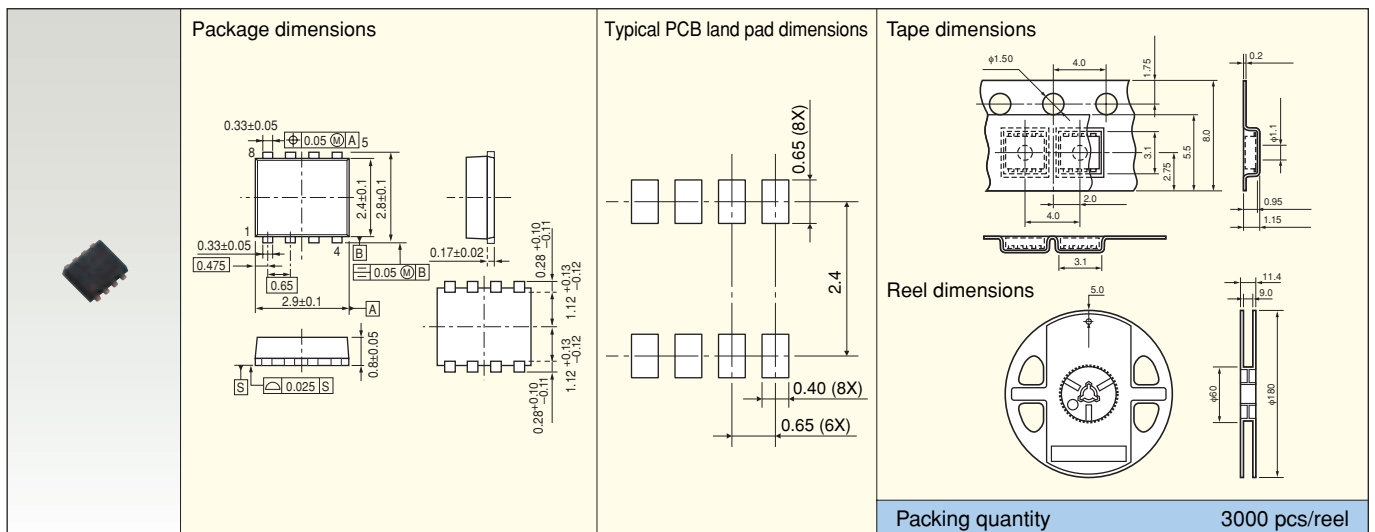
■ VS-8

Unit: mm



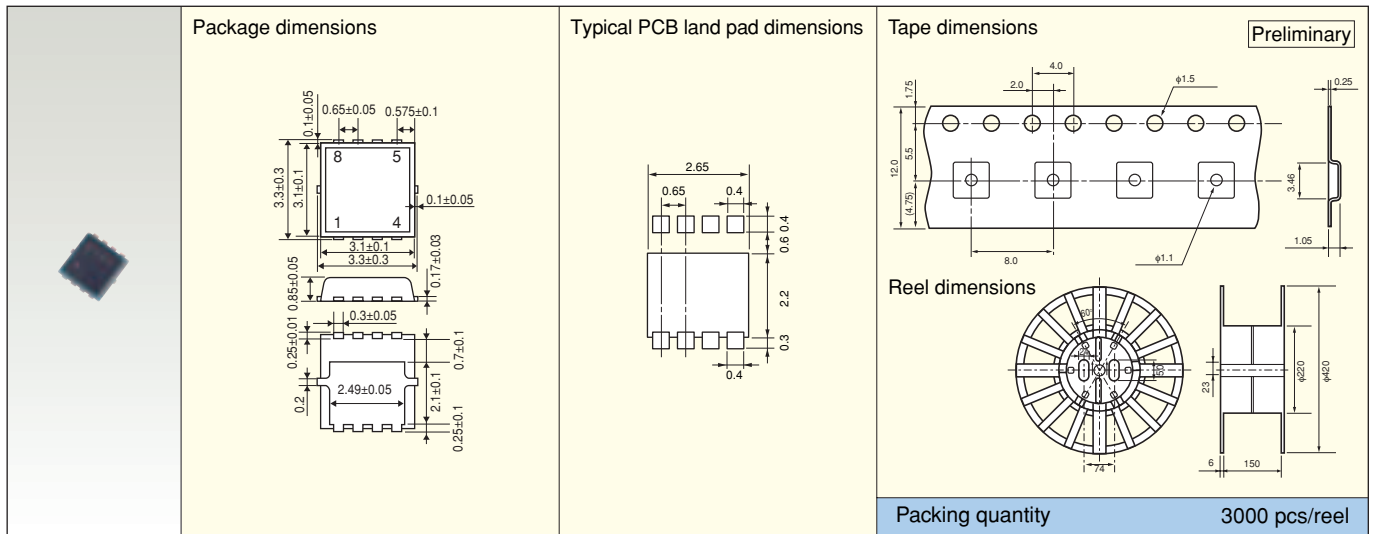
■ PS-8

Unit: mm



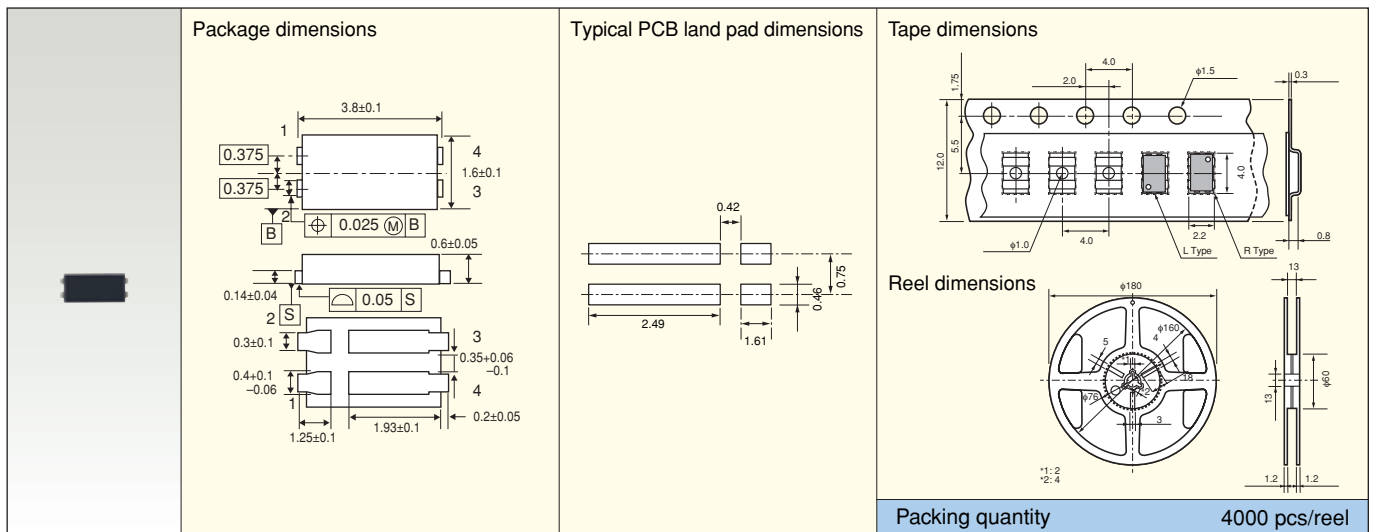
## ■ TSON

Unit: mm



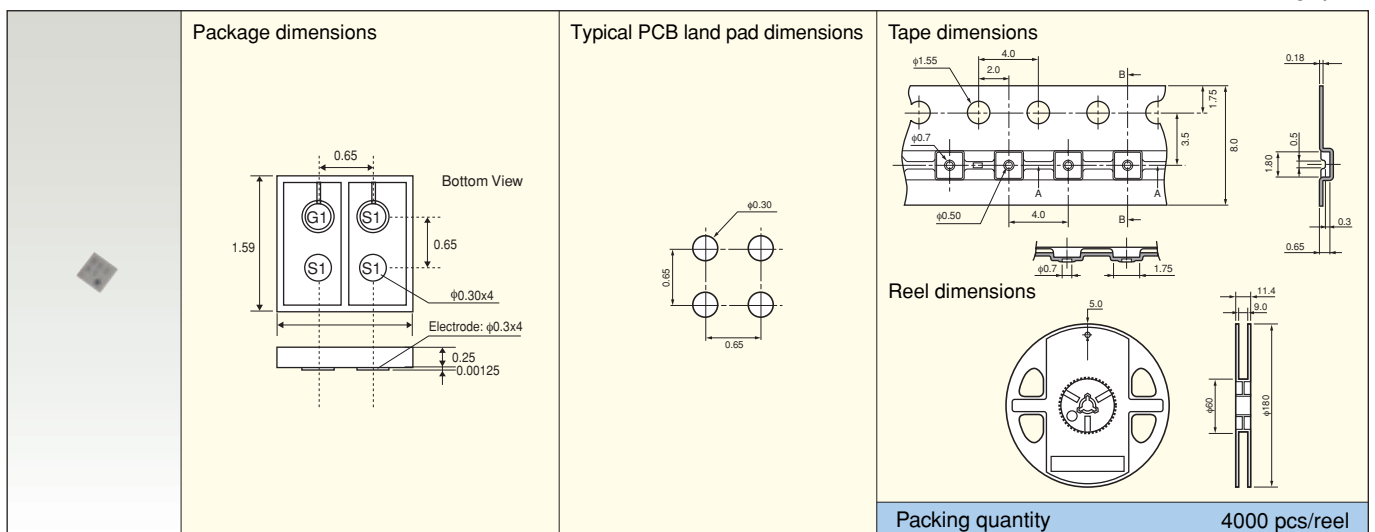
## ■ STP2

Unit: mm



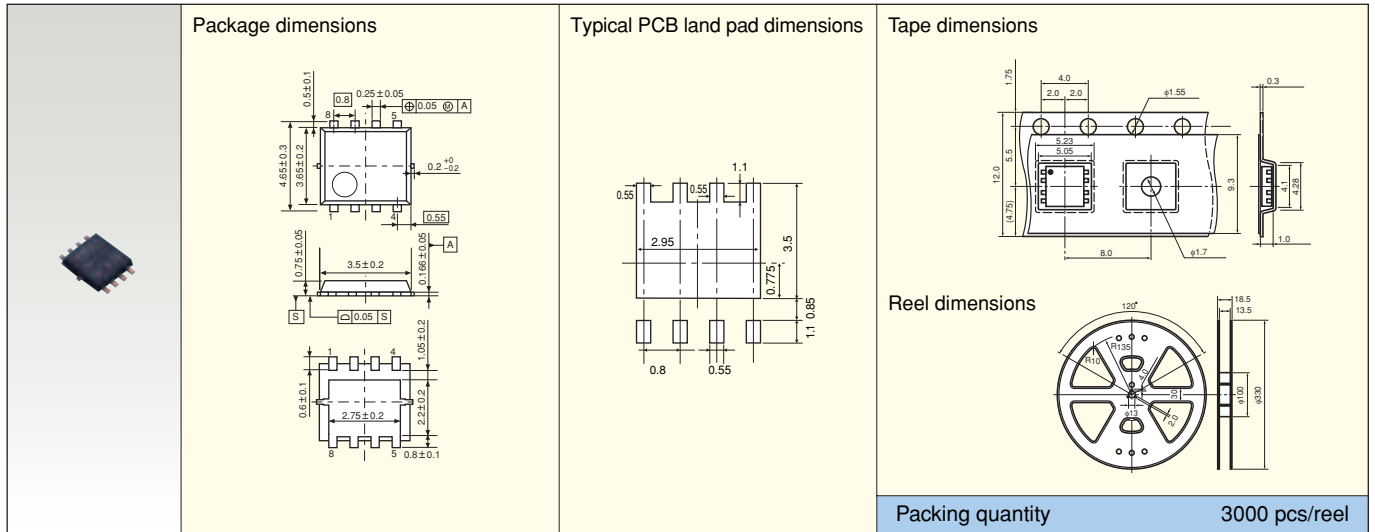
## ■ LGA

Unit: mm



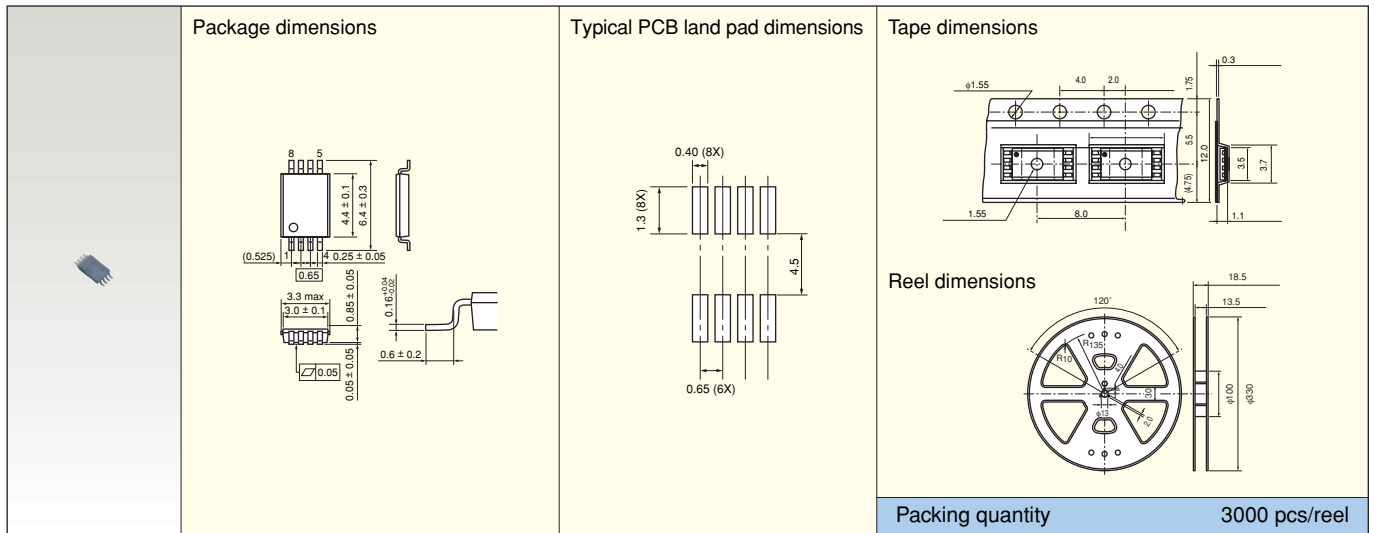
### TSSOP Advance

Unit: mm



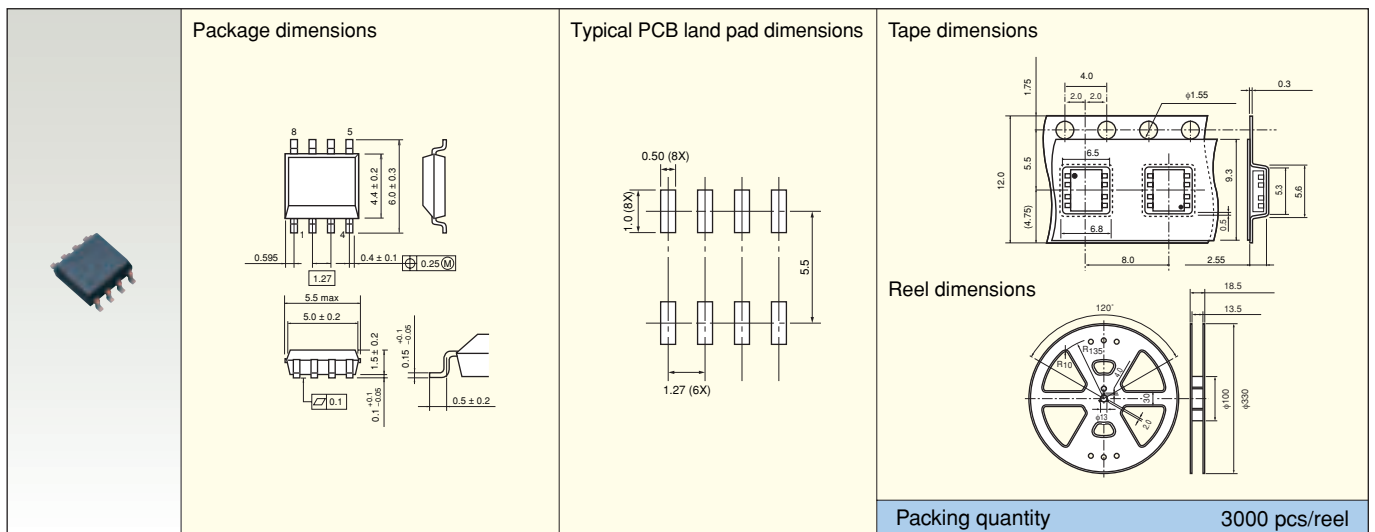
### TSSOP-8

Unit: mm



### SOP-8

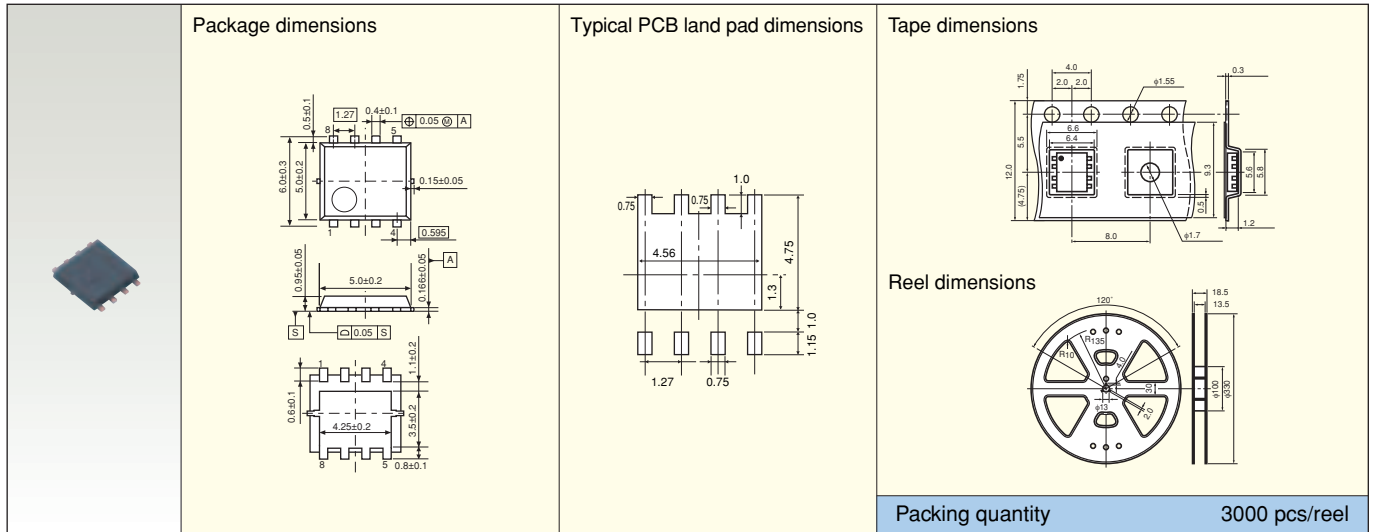
Unit: mm





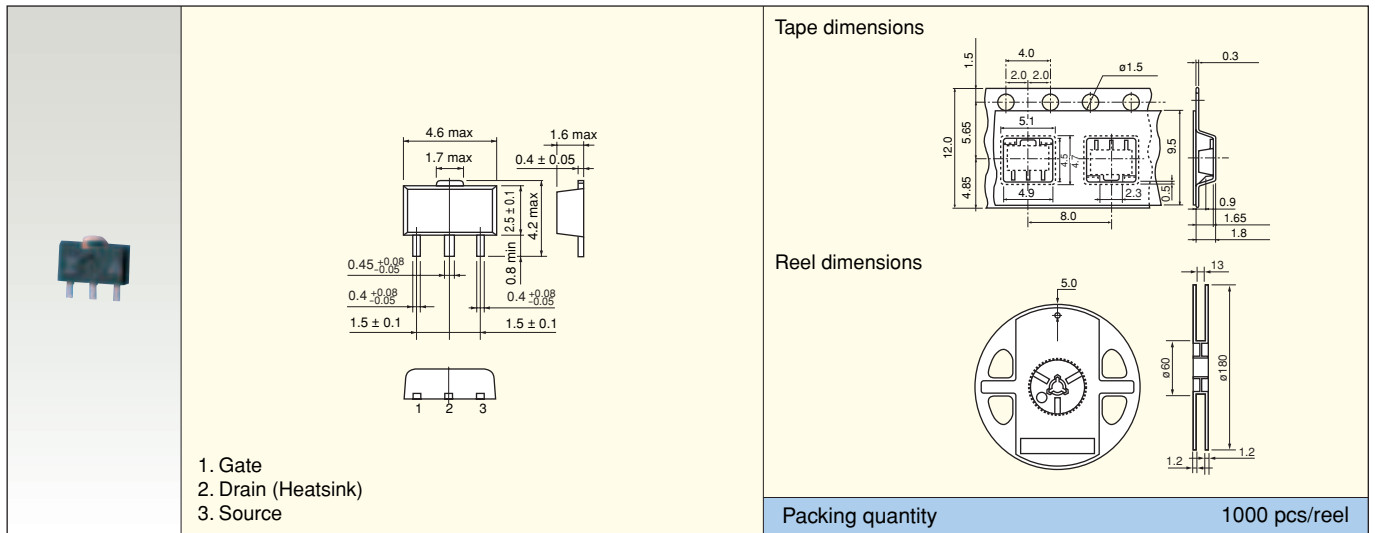
## ■ SOP Advance

Unit: mm



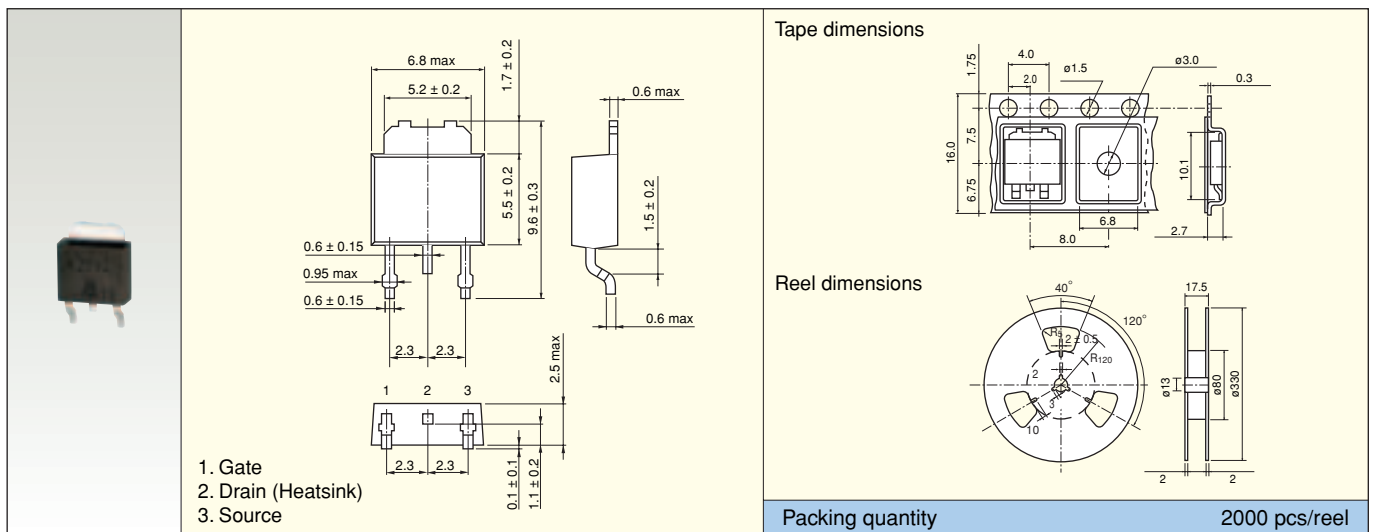
## ■ PW-Mini

Unit: mm



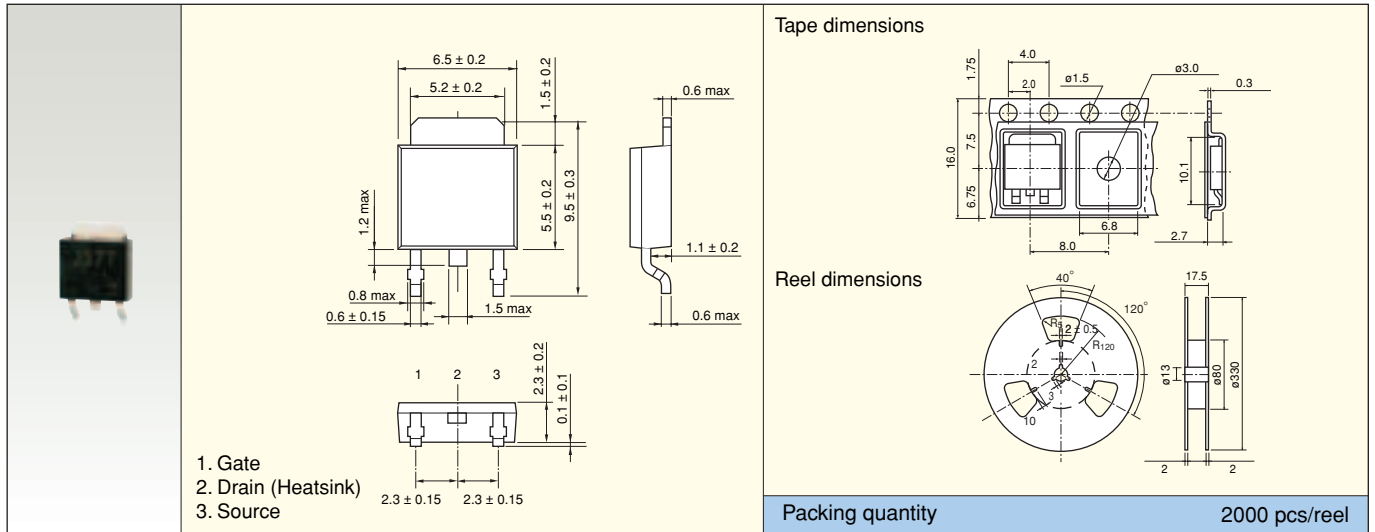
## ■ DP

Unit: mm



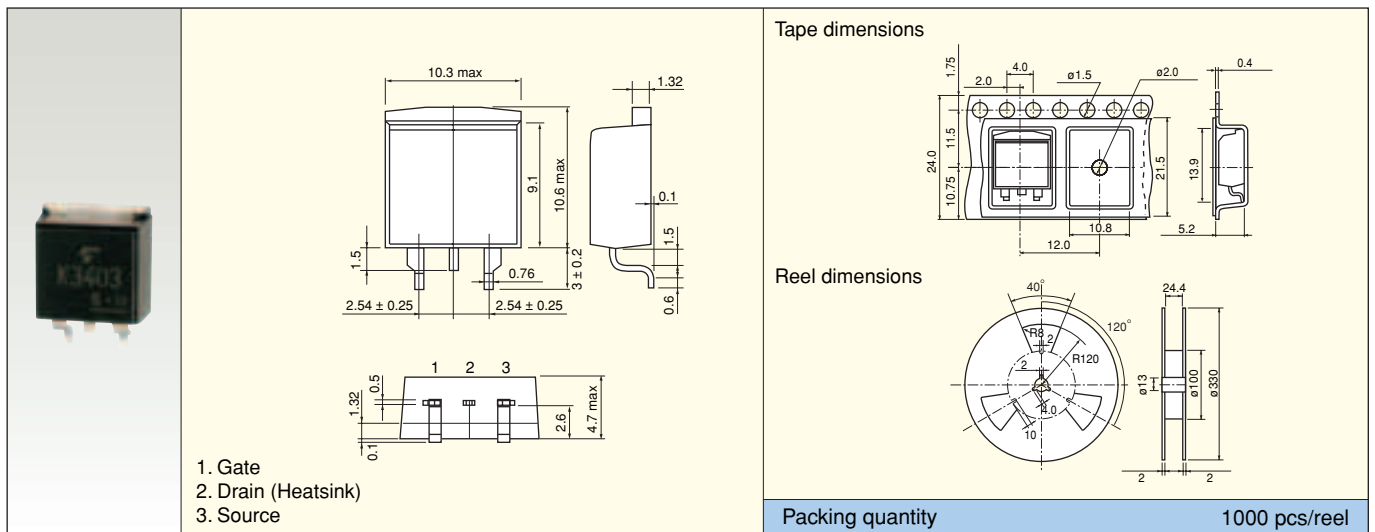
### ■ New PW-Mold

Unit: mm



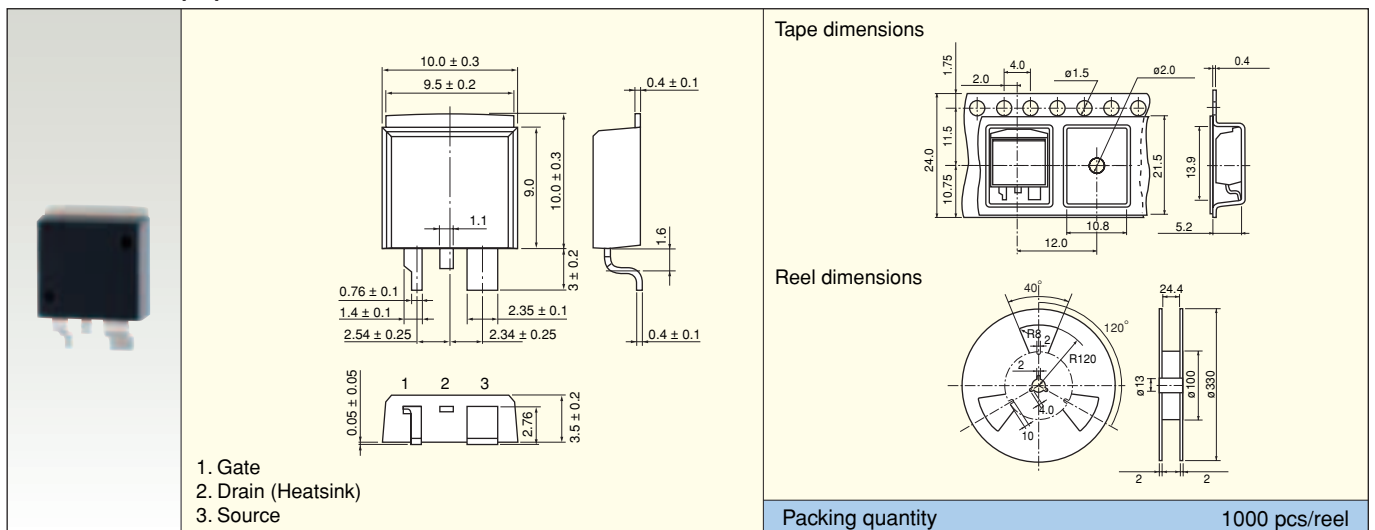
### ■ TO-220SM

Unit: mm




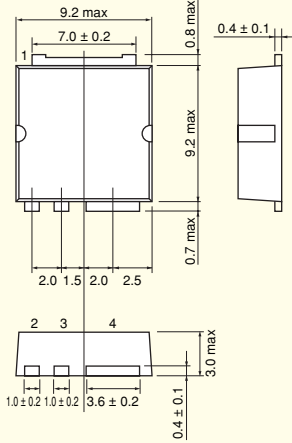
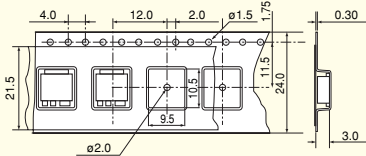
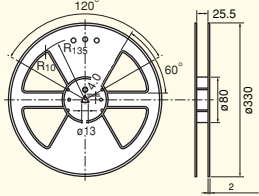
### ■ TO-220SM(W)

Unit: mm




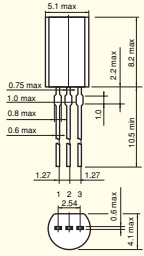
## TFP

Unit: mm

		<p><b>Tape dimensions</b></p> 
	<ol style="list-style-type: none"> <li>1. Drain (Heatsink)</li> <li>2. Gate</li> <li>3. Source 1</li> <li>4. Source 2</li> </ol>	<p><b>Reel dimensions</b></p> 
<p>Packing quantity</p>		<p>1500 pcs/reel</p>


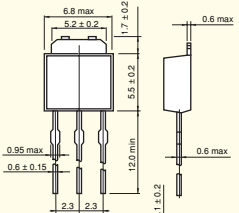
## 9-2 Through-Hole Packages

### LSTM


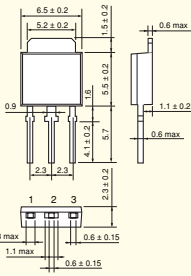
	
<ol style="list-style-type: none"> <li>1. Source</li> <li>2. Drain</li> <li>3. Gate</li> </ol>	

### PW-Mold (Straight)


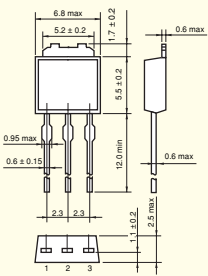
Unit: mm

	
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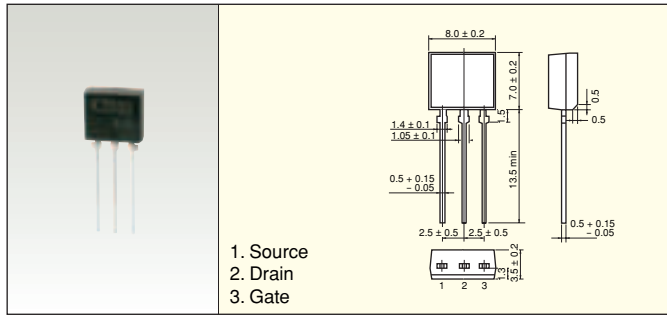
### New PW-Mold2

	
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### DP (Straight)

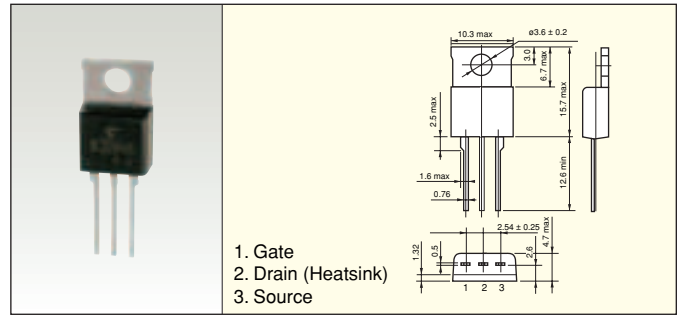
	
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■ TPS

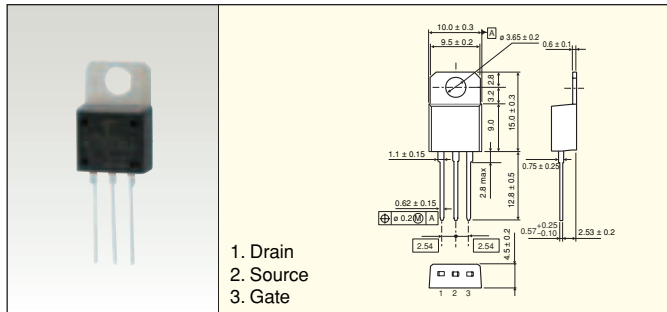


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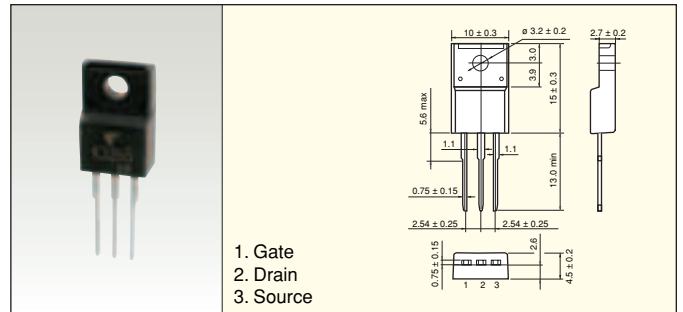
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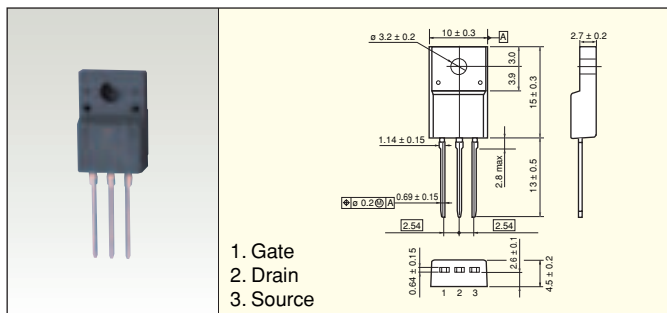
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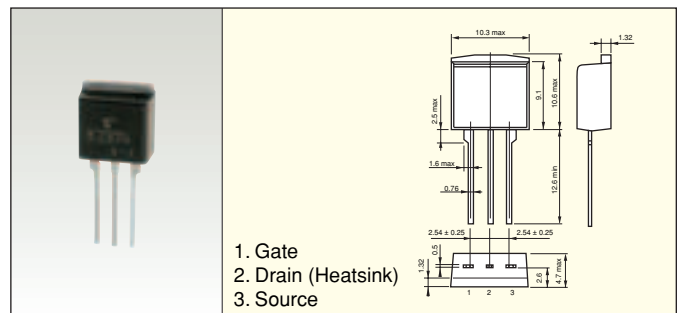
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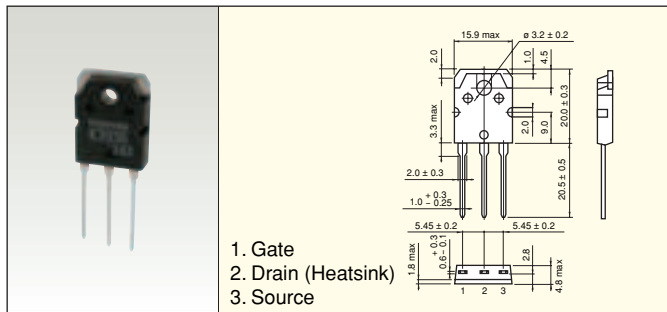
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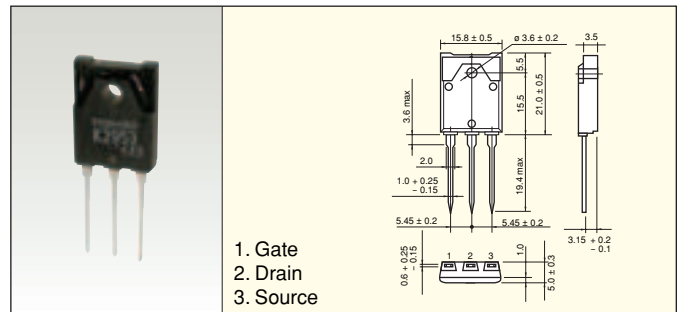
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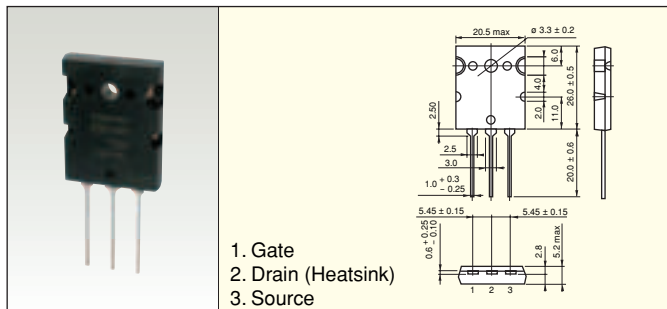
■ TO-3P(N)



■ TO-3P(N)IS



■ TO-3P(L)



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